

1997

Data Handbook SC16

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PHILIPS

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Our quality system focuses on the continuing high quality of our components and the best possible service for our customers. We have a three-sided quality strategy: we apply a system of total quality control and assurance; we operate customer-oriented dynamic improvement programmes; and we promote a partnering relationship with our customers and suppliers.

PRODUCT SAFETY

In striving for state-of-the-art perfection, we continuously improve components and processes with respect to environmental demands. Our components offer no hazard to the environment in normal use when operated or stored within the limits specified in the data sheet.

Some components unavoidably contain substances that, if exposed by accident or misuse, are potentially hazardous to health. Users of these components are informed of the danger by warning notices in the data sheets supporting the components. Where necessary the warning notices also indicate safety precautions to be taken and disposal instructions to be followed. Obviously users of these components, in general the set-making industry, assume responsibility towards the consumer with respect to safety matters and environmental demands.

All used or obsolete components should be disposed of according to the regulations applying at the disposal location. Depending on the location, electronic components are considered to be 'chemical', 'special' or sometimes 'industrial' waste. Disposal as domestic waste is usually not permitted.

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Application information	
Where application informat	ion is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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Selection guide

CATV AMPLIFIER MODULES

TYPE NUMBER	FREQUENCY RANGE	POWER GAIN AT f = 50 MHz (Gp) (dB)	SLOPE CABLE EQUIVALENT (SL) (dB)	APPLICATION	PAGE
BGD102	40 to 450	18 to 19	0.5 to 2.5	power doubler	34
BGD104	40 to 450	19.5 to 20.5	0.5 to 2.5	power doubler	34
BGD106	40 to 450	21.5 to 22.5	0 to 2	power doubler	36
BGD108	40 to 450	35 to 37	0.2 to 2.2	power doubler	38
BGD502 ⁽¹⁾	40 to 550	18 to 19	0.2 to 2.2	power doubler	40
BGD504 ⁽¹⁾	40 to 550	19.5 to 20.5	0.2 to 2.2	power doubler	40
BGD506	40 to 550	21.5 to 22.5	0 to 2	power doubler	43
BGD508 ⁽¹⁾	40 to 550	35 to 37	0.2 to 2.2	power doubler	45
BGD601 ⁽²⁾	40 to 600	12 to 13	0.2 to 2.2	power doubler	49
BGD602 ⁽²⁾	40 to 600	18 to 19	0.2 to 2.2	power doubler	53
BGD602D ⁽²⁾	40 to 600	17.5 to 18.5	0.2 to 2.2	power doubler, darlington	57
BGD702 ⁽³⁾	40 to 750	18 to 19	0.2 to 2	power doubler	61
BGD702D ⁽⁴⁾	40 to 750	18 to 19	0.2 to 4	amplifier	66
BGD702MI ⁽³⁾	40 to 750	18 to 19	0.2 to 2	amplifier	70
BGD704 ⁽³⁾	40 to 750	19.5 to 20.5	0 to 2	power doubler	75
BGD802 ⁽⁵⁾	40 to 860	18 to 19	0.2 to 2	amplifier	80
BGD802MI ⁽⁵⁾	40 to 860	18 to 19	0.2 to 2	amplifier	85
BGD804 ⁽⁵⁾	40 to 860	19.5 to 20.5	0.2 to 2	amplifier	88
BGD885	40 to 860	16.5 to 17.5	0.2 to 1.6	power doubler	94
BGE884	40 to 860	16.5 to 17.5	0.2 to 1.4	amplifier	97
BGE885	40 to 860	16.5 to 17.5	0.2 to 1.2	amplifier	99
BGE887	470 to 860	22.5 to 25 ⁽⁸⁾	-0.2 to +1	amplifier	102
BGX881	40 to 860	12 to 13	0.2 to 1.2	amplifier	104
BGX885N	40 to 860	16.5 to 17.5	0.2 to 1.4	amplifier	107
BGY61	5 to 200	12.5 to 13.5 ⁽⁹⁾	-0.2 to +0.5	reverse amplifier	110
BGY65	5 to 200	18 to 19 ⁽⁹⁾	-0.2 to +0.5	reverse amplifier	112
BGY66B	5 to 120	24.5 to 25.5	-0.2 to +0.5	reverse amplifier	114
BGY67	5 to 200	21.5 to 22.5 ⁽⁹⁾	-0.2 to +0.5	reverse amplifier	116
BGY67A	5 to 200	23.5 to 24.5 ⁽⁹⁾	-0.2 to +0.5	reverse amplifier	118
BGY67BO	5 to 300	-	_	optical receiver	120
BGY68	5 to 75	29.2 to 30.8	-0.2 to +0.5	reverse amplifier	122
BGY80	40 to 450	12 to 13	0.2 to 1.5	pre-amplifier	124
BGY81	40 to 450	12 to 13	0.2 to 1.5	final amplifier	124
BGY82	40 to 450	13.5 to 14.5	0.2 to 1.5	amplifier	126
BGY83	40 to 450	13.5 to 14.5	0.2 to 1.5	amplifier	126
BGY84	40 to 450	16.5 to 17.5	0.5 to 1.5	pre-amplifier	128

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TYPE NUMBER	FREQUENCY RANGE	POWER GAIN AT f = 50 MHz (Gp) (dB)	SLOPE CABLE EQUIVALENT (SL) (dB)	APPLICATION	PAGE
BGY84A	40 to 450	18 to 18.8	0.3 to 1.5	pre-amplifier	130
BGY85	40 to 450	16.5 to 17.5	0.5 to 1.5	final amplifier	128
BGY85A	40 to 450	18 to 18.8	0.3 to 1.5	final amplifier	130
BGY86	40 to 450	21.5 to 22.5	0 to 1.5	pre-amplifier	132
BGY87	40 to 450	21.5 to 22.5	0 to 1.5	final amplifier	132
BGY87B	40 to 450	26.2 to 27.8	0.5 to 2.5	amplifier	134
BGY88	40 to 450	33.5 to 35.5	0.5 to 2.5	line extender	136
BGY89	40 to 450	37 to 39	0 to 2.5	line extender	138
BGY580	40 to 550	12 to 13	0.5 to 2	pre-amplifier	140
BGY581	40 to 550	12 to 13	0.5 to 2	final amplifier	140
BGY582	40 to 550	13.5 to 14.5	0.2 to 1.5	amplifier	142
BGY583	40 to 550	13.5 to 14.5	0.2 to 1.5	amplifier	142
BGY584 ⁽¹⁾	40 to 550	16.5 to 17.5	0.5 to 2	pre-amplifier	144
BGY584A ⁽¹⁾	40 to 550	17.7 to 18.7	0.5 to 2	pre-amplifier	147
BGY585 ⁽¹⁾	40 to 550	16.5 to 17.5	0.5 to 2	final amplifier	144
BGY585A ⁽¹⁾	40 to 550	17.7 to 18.7	0.5 to 2	final amplifier	147
BGY586	40 to 550	21.5 to 22.5	0.2 to 1.5	pre-amplifier	150
BGY587	40 to 550	21.5 to 22.5	0.2 to 1.5	final amplifier	150
BGY587B	40 to 550	26.2 to 27.8	0.5 to 2.5	amplifier	152
BGY588 ⁽¹⁾	40 to 550	33.5 to 35.5	0 to 2.5	line extender	154
BGY681 ⁽²⁾	40 to 600	12 to 13	0.7 to 2.2	amplifier	157
BGY683 ⁽²⁾	40 to 600	13.5 to 14.5	0.2 to 1.7	amplifier	161
BGY685 ⁽²⁾	40 to 600	16.5 to 17.5	0.5 to 2.2	amplifier	165
BGY685A ⁽²⁾	40 to 600	17.7 to 18.7	0.5 to 2.2	amplifier	169
BGY685AD ⁽²⁾	40 to 600	18 to 19	0.2 to 2.2	darlington amplifier	173
BGY685AL ⁽²⁾	40 to 600	18 to 19	0.5 to 2	amplifier	177
BGY687	40 to 600	21 to 22	0.8 to 2.2	amplifier	181
BGY687B	40 to 600	26.2 to 27.8	0.8 to 2.8	amplifier	183
BGY785A ⁽³⁾	40 to 750	18 to 19	0 to 2	amplifier	187
BGY785AD ⁽³⁾	40 to 750	18 to 19	0.2 to 2	amplifier	192
BGY785AD/8M ⁽⁵⁾	40 to 870	18 to 19	0.2 to 2	amplifier	197
BGY787 ⁽³⁾	40 to 750	21 to 22	0 to 1.5	amplifier	201
BGY883	40 to 860	14.5 to 15.5	0 to 2	amplifier	206
BGY885A ⁽⁶⁾	40 to 860	18 to 19	0 to 2	amplifier	208
BGY885B	40 to 860	19.5 to 20.5	0 to 2	amplifier	214
BGY887 ⁽⁷⁾	40 to 860	21 to 22	0.2 to 2	amplifier	216
BGY887B ⁽⁷⁾	40 to 860	28.5 to 29.5	0.5 to 2.5	amplifier	221
BGY887BO	40 to 860		-	optical receiver	226

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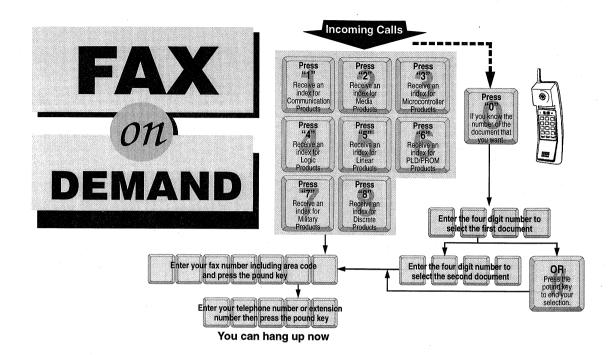
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TYPE NUMBER	FREQUENCY RANGE	POWER GAIN AT f = 50 MHz (Gp) (dB)	SLOPE CABLE EQUIVALENT (SL) (dB)	APPLICATION	PAGE
BGY887BO/FC	40 to 860	= 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	-	optical receiver	228
BGY887BO/SC	40 to 860	=	_	optical receiver	231
BGY888 ⁽⁷⁾	40 to 860	33.5 to 34.5	0.5 to 2.5	amplifier	233
BGY1085A	40 to 1000	18 to 19	0 to 2	amplifier	238

Notes

- 1. Specifications also supplied for 450 MHz bandwidth operation.
- 2. Specifications also supplied for 450 and 550 MHz bandwidth operation.
- 3. Specifications also supplied for 450, 550 and 600 MHz bandwidth operation.
- 4. Specifications also supplied for 550 and 600 MHz bandwidth operation.
- 5. Specifications also supplied for 550, 650 and 750 MHz bandwidth operation.
- 6. Specifications also supplied for 450, 550, 600 and 750 MHz bandwidth operation.
- 7. Specifications also supplied for 600 and 750 MHz bandwidth operation.
- 8. Power gain measured at f = 470 MHz.
- 9. Power gain measured at f = 10 MHz.

FAX-on-DEMAND System



What is it?

The FAX-on-DEMAND system is a computer facsimile system that allows customers to receive selected documents by fax automatically.

How does it work?

To order a document, you simply enter the document number. This number can be obtained by asking for an index of available documents to be faxed to you the first time you call the system.

Our system has a selection of the latest product data sheets from Philips with varying page counts. As you know, it takes approximately one minute to FAX one page. This isn't bad if the number of pages is less than 10. But if the document is 37 pages long, be ready for a long transmission!

Philips Semiconductors also maintains product information on the World-Wide Web. Our home page can be located at:

http://www.semiconductors.philips.com

Who do I contact if I have a question about FAX-on-DEMAND?

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FAX-on-DEMAND phone numbers:

England 44-181-730-5020

(United Kingdom, Ireland)

France 33-1-40-99-60-60

Italy 39-167-295502

North America 1-800-282-2000

Locations soon to be in operation:

Hong Kong Japan

The Netherlands

Internet World Wide Web Home Page

WHAT IS IT?

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http://www.semiconductors.philips.com/

You can find us in the Product category of Discretes.

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General

QUALITY

Total Quality Management

Philips Semiconductors is a Quality Company, renowned for the high quality of our products and service. We keep alive this tradition by constantly aiming towards one ultimate standard, that of zero defects. This aim is guided by our Total Quality Management (TQM) system which is described in our Quality manuals. The basis is outlined in the following paragraphs.

QUALITY ASSURANCE

Based on ISO 9000 standards, customer standards such as FDC, QS9000 and IBM MDQ. Our factories are certified to ISO 9000 by external inspectorates.

PARTNERSHIPS WITH CUSTOMERS

PPM co-operations, design-in agreements, ship-to-stock, just-in-time, self-qualification programmes and application support.

PARTNERSHIPS WITH SUPPLIERS

Ship-to-stock, statistical process control and ISO 9000 audits.

QUALITY IMPROVEMENT PROGRAMME

Continuous process and system improvement, design improvement, complete use of statistical process control, realization of our final objective of zero defects, and logistics improvement by ship-to-stock and just-in-time agreements.

Advanced quality planning

During the design and development of new products and processes, quality is built-in by advanced quality planning. Through failure-mode-and-effect analysis the critical parameters are detected and measures taken to ensure good performance on these parameters. The capability of process steps is also planned in this phase in preparation for production under statistical process control.

Product conformance

The assurance of product conformance is an integral part of our quality assurance (QA) practice. This is achieved by:

- Incoming material management through partnerships with suppliers
- In-line quality assurance to monitor process reproducibility during manufacture and initiate any

- necessary corrective action. Process steps are under statistical process control
- Acceptance tests on finished products to verify conformance with the device specification. The test results are used for quality feedback and corrective actions. The inspection and test requirements are detailed in the general quality specifications SNW-EQ-611 part A
- Periodic inspections to monitor and measure the conformance of products
- Qualification tests (see SNW-EQ-611 part A).

Product reliability

With the increasing complexity of Original Equipment Manufacturer (OEM) equipment, component reliability must be extremely high. Our research laboratories and development departments study the failure mechanisms of semiconductors. Their studies result in design rules and process optimization for the highest built-in product reliability. Highly accelerated tests are applied to the products reliability evaluation. Rejects from reliability tests and from customer complaints are submitted to failure analysis, to result in corrective action.

Customer response

Our quality improvement depends on joint action with our customer. We need our customer's inputs and we invite constructive comments on all aspects of our performance. Please contact our local sales representative.

Recognition

The high quality of our products and services is demonstrated by many Quality Awards granted by major customers and international organizations.

PRO ELECTRON TYPE NUMBERING SYSTEM

Basic type number

This type designation code applies to discrete semiconductor devices (not integrated circuits), multiples of such devices, semiconductor chips and Darlington transistors.

FIRST LETTER

The first letter gives information about the material for the active part of the device.

A Germanium or other material with a band gap of 0.6 to 1 eV

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- B Silicon or other material with a band gap of 1 to 1.3 eV
- Gallium arsenide (GaAs) or other material with a band gap of 1.3 eV or more
- R Compound materials, e.g. cadmium sulphide.

SECOND LETTER

The second letter indicates the function for which the device is primarily designed. The same letter can be used for multi-chip devices with similar elements.

In the following list low power types are defined by $R_{th\ i-mb} > 15$ K/W and power types by $R_{th\ i-mb} \le 15$ K/W.

- A Diode; signal, low power
- B Diode; variable capacitance
- C Transistor; low power, audio frequency
- D Transistor; power, audio frequency
- E Diode; tunnel
- F Transistor; low power, high frequency
- G Multiple of dissimilar devices/miscellaneous devices; e.g. oscillators. Also with special third letter; see under Section "Serial number".
- H Diode; magnetic sensitive
- L Transistor; power, high frequency
- N Photocoupler
- P Radiation detector; e.g. high sensitivity photo-transistor; with special third letter
- Q Radiation generator; e.g. LED, laser; with special third letter
- R Control or switching device; e.g. thyristor, low power; with special third letter
- S Transistor; low power, switching
- Control or switching device; e.g. thyristor, power; with special third letter
- U Transistor; power, switching
- W Surface acoustic wave device
- X Diode; multiplier, e.g. varactor, step recovery
- Y Diode; rectifying, booster
- Z Diode; voltage reference or regulator, transient suppressor diode; with special third letter.

THIRD LETTER

The third letter indicates a common feature of a group of devices:

D For power-doubler modules

- E For economical modules
- X For cascade push-pull modules
- Y For cascode push-pull modules.

SERIAL NUMBER

The number comprises two to four digits:

- 6x For reverse amplifiers
- 8x For 40 to 450 MHz forward amplifiers
- 1xx For 40 to 450 MHz power doublers
- 5xx For 40 to 550 MHz amplifiers
- 6xx For 40 to 600 MHz amplifiers
- 7xx For 40 to 750 MHz amplifiers
- 8xx For 40 to 860 MHz amplifiers
- 10xx For 40 to 1000 MHz amplifiers.

Suffix letter(s)

One or two letters may be added to the basic type number to indicate a specific feature of the device:

- D For Darlington modules
- BO For optical modules

RATING SYSTEMS

The rating systems described are those recommended by the International Electrotechnical Commission (IEC) in its publication number 134.

Definitions of terms used

ELECTRONIC DEVICE

An electronic tube or valve, transistor or other semiconductor device. This definition excludes inductors, capacitors, resistors and similar components.

CHARACTERISTIC

A characteristic is an inherent and measurable property of a device. Such a property may be electrical, mechanical, thermal, hydraulic, electro-magnetic or nuclear, and can be expressed as a value for stated or recognized conditions. A characteristic may also be a set of related values, usually shown in graphical form.

BOGEY ELECTRONIC DEVICE

An electronic device whose characteristics have the published nominal values for the type. A bogey electronic device for any particular application can be obtained by

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Wideband Hybrid IC Modules

considering only those characteristics that are directly related to the application.

RATING

A value that establishes either a limiting capability or a limiting condition for an electronic device. It is determined for specified values of environment and operation, and may be stated in any suitable terms. Limiting conditions may be either maxima or minima.

RATING SYSTEM

The set of principles upon which ratings are established and which determine their interpretation. The rating system indicates the division of responsibility between the device manufacturer and the circuit designer, with the object of ensuring that the working conditions do not exceed the ratings.

Absolute maximum rating system

Absolute maximum ratings are limiting values of operating and environmental conditions applicable to any electronic device of a specified type, as defined by its published data, which should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking no responsibility for equipment variations, environmental variations, and the effects of changes in operating conditions due to variations in the characteristics of the device under consideration and of all other electronic devices in the equipment.

The equipment manufacturer should design so that, initially and throughout the life of the device, no absolute maximum value for the intended service is exceeded with any device, under the worst probable operating conditions with respect to supply voltage variation, equipment component variation, equipment control adjustment, load variations, signal variation, environmental conditions, and variations in characteristics of the device under consideration and of all other electronic devices in the equipment.

Design maximum rating system

Design maximum ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking responsibility for the effects of changes in operating conditions due to variations in the characteristics of the electronic device under consideration.

The equipment manufacturer should design so that, initially and throughout the life of the device, no design maximum value for the intended service is exceeded with a bogey electronic device, under the worst probable operating conditions with respect to supply voltage variation, equipment component variation, variation in characteristics of all other devices in the equipment, equipment control adjustment, load variation, signal variation and environmental conditions.

Design centre rating system

Design centre ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device of a specified type as defined by its published data, and should not be exceeded under normal conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device in average applications, taking responsibility for normal changes in operating conditions due to rated supply voltage variation, equipment component variation, equipment control adjustment, load variation, signal variation, environmental conditions, and variations in the characteristics of all electronic devices.

The equipment manufacturer should design so that, initially, no design centre value for the intended service is exceeded with a bogey electronic device in equipment operating at the stated normal supply voltage.

LETTER SYMBOLS

The letter symbols for transistors and signal diodes detailed in this section are based on IEC publication number 148.

Letter symbols for currents, voltages and powers

BASIC LETTERS

I, i current

V, v voltage

P. p power.

Upper-case letter symbols are used to represent all values except instantaneous values that vary with time, these are represented by lower-case letters.

General

SUBSCRIPTS

A, a	anode terminal
(AV), (av)	average value
B, b	base terminal
C, c	collector terminal
D, d	drain terminal
E, e	emitter terminal
F, f	forward
G, g	gate terminal
K, k	cathode terminal
M, m	peak value
О, о	as third subscript: the terminal not mentioned is open-circuit
R, r	as first subscript: reverse. As second subscript: repetitive. As third subscript: with a specified resistance between the terminal not mentioned and the reference terminal
(RMS), (rms)	root-mean-square value
S, s	as first or second subscript: source terminal (FETs only). As second subscript: non-repetitive (not FETs). As third subscript: short circuit between the terminal not mentioned and the reference terminal
X, x	specified circuit
Z, z	replaces R to indicate the actual working voltage, current or power of voltage

No additional subscript is used for DC values.

Upper-case subscripts are used for the indication of:

reference and voltage reference diodes.

- Continuous (DC) values (without signal), e.g. IB
- Instantaneous total values, e.g. i_B
- Average total values, e.g. I_{B(AV)}
- Peak total values, e.g. I_{BM}
- Root-mean-square total values, e.g. I_{B(BMS)}.

Lower-case subscripts are used for the indication of values applying to the varying component alone:

- Instantaneous values, e.g. ib
- Root-mean-square values, e.g. Ib(rms)
- · Peak values, e.g. Ibm
- Average values, e.g. I_{b(av)}.

If more than one subscript is used, the subscript for which both styles exist are either all upper-case or all lower-case. ADDITIONAL RULES FOR SUBSCRIPTS

Transistor currents

If it is necessary to indicate the terminal carrying the current, this should be done by the first subscript (conventional current flow from the external circuit into the terminal is positive).

Examples: IB, iB, ib, Ibm.

Diode currents

To indicate a forward current (conventional current flow into the anode terminal), the subscript F or f should be used. For a reverse current (conventional current flow out of the anode terminal), the subscript R or r should be used.

Examples: I_F, I_R, i_F, I_{f(rms)}.

Transistor voltages

If it is necessary to indicate the points between which a voltage is measured, this should be done by the first two subscripts. The first subscript indicates the terminal at which the voltage is measured and the second the reference terminal or the circuit node. Where there is no possibility of confusion, the second subscript may be omitted.

Examples: V_{BF}, v_{BF}, v_{be}, V_{bem}.

Diode voltages

To indicate a forward voltage (anode positive with respect to cathode), the subscript F or f should be used. For a reverse voltage (anode negative with respect to cathode), the subscript R or r should be used.

Examples: V_F, V_R, v_F, V_{rm}.

Supply voltages or currents

Supply voltages or supply currents are indicated by repeating the appropriate terminal subscript.

Examples: V_{CC}, I_{FF}.

If it is necessary to indicate a reference terminal, this should be done by a third subscript.

Example: V_{CCE}.

Subscripts for devices with more than one terminal of the same kind

If a device has more than one terminal of the same kind, the subscript is formed by the appropriate letter for the

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terminal, followed by a number. In the case of multiple subscripts, hyphens may be necessary to avoid confusion.

Examples:

I_{B2} continuous (DC) current flowing into the second base terminal

base terminal

 $V_{\mbox{\footnotesize{B2-E}}}$ continuous (DC) voltage between the terminals of

second base and emitter terminals.

Subscripts for multiple devices

For multiple unit devices, the subscripts are modified by a number preceding the letter subscript. In the case of multiple subscripts, hyphens may be necessary to avoid confusion.

Examples:

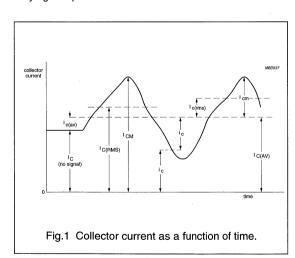
 I_{2C} continuous (DC) current flowing into the collector

terminal of the second unit

V_{1C-2C} continuous (DC) voltage between the collector terminals of the first and second units.

Application of the rules

Fig.1 represents a transistor collector current as a function of time. It comprises a continuous (DC) current and a varying component.



Letter symbols for electrical parameters

DEFINITION

For the purpose of this publication, the term 'electrical parameter' applies to four-pole matrix parameters, elements of electrical equivalent circuits, electrical

impedances and admittances, inductances and capacitances.

BASIC LETTERS

The following list comprises the most important basic letters used for electrical parameters of semiconductor devices.

B, b susceptance (imaginary part of an admittance)

C capacitance

G, g conductance (real part of an admittance)

H, h hybrid parameter

L inductance

R, r resistance (real part of an impedance)

X, x reactance (imaginary part of an impedance)

Y, y admittance

Z. z impedance.

Upper-case letters are used for the representation of:

- Electrical parameters of external circuits and of circuits in which the device forms only a part
- All inductances and capacitances.

Lower-case letters are used for the representation of electrical parameters inherent in the device, with the exception of inductances and capacitances.

SUBSCRIPTS

General subscripts

The following list comprises the most important general subscripts used for electrical parameters of semiconductor devices.

F, f forward (forward transfer)

I, i (or 1) input
L, I load
O, o (or 2) output

R, r reverse (reverse transfer)

S, s source.

Examples: Z_s , h_f , h_F .

The upper-case variant of a subscript is used for the designation of static (DC) values.

Examples:

h_{FE} static value of forward current transfer ratio in common-emitter configuration (DC current gain)

R_E DC value of the external emitter resistance.

General

The static value is the slope of the line from the origin to the operating point on the appropriate characteristic curve, i.e. the quotient of the appropriate electrical quantities at the operating point.

The lower-case variant of a subscript is used for the designation of small-signal values.

Examples:

 h_{fe}

small-signal value of the short-circuit forward current transfer ratio in common-emitter configuration

 $Z_e = R_e + jX_e$

small-signal value of the external

impedance.

If more than one subscript is used, subscripts for which both styles exist are either all upper-case or all lower-case.

Examples: h_{FE}, y_{RE}, h_{fe}.

Subscripts for four-pole matrix parameters

The first letter subscript (or double numeric subscript) indicates input, output, forward transfer or reverse transfer.

Examples: h_i (or h_{11}), h_o (or h_{22}), h_f (or h_{21}), h_r (or h_{12}).

A further subscript is used for the identification of the circuit configuration. When no confusion is possible, this further subscript may be omitted.

Examples: h_{fe} (or h_{21e}), h_{FE} (or h_{21E}).

DISTINCTION BETWEEN REAL AND IMAGINARY PARTS

If it is necessary to distinguish between real and imaginary parts of electrical parameters, no additional subscripts should be used. If basic symbols for the real and imaginary parts exist, these may be used.

Examples: $Z_i = R_i + jX_i$, $y_{fe} = g_{fe} + jb_{fe}$.

If such symbols do not exist, or if they are not suitable, the following notation is used:

Examples:

Re (hib) etc. for the real part of hib

Im (hib) etc. for the imaginary part of hib.

CATV PARAMETERS

Gain (Gp)

DEFINITION

The power gain, expressed in dB, is the ratio of output and input power of a module, operating in a 75 Ω (Z_0) system.

MEASUREMENT

The power gain is measured at several frequencies throughout the band, although the gain performances are mostly given only at the start and stop frequencies. The gain is measured by applying a single tone signal to the module and measuring the output power. The input power is measured before connecting the module using a thru-line and feeding the system with exactly the same signals.

EQUIPMENT

Input and output power levels are measured with a power meter.

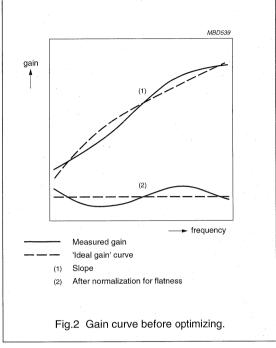
Flatness of frequency response (FL)

DEFINITION

The flatness of gain of a CATV amplifier module is defined as the maximum deviation from an absolute flat gain over a given frequency range, after the slope of the amplifier over this frequency range has been optimized and equalized by means of a certain cable length to give the best result for flatness (see Fig.2 and Fig.3). This means that an 'ideal gain curve' for the module is calculated and the flatness is the maximum deviation of this 'ideal gain' curve.

General

Wideband Hybrid IC Modules





To determine the flatness, the measured gain values are compared with an 'ideal gain' curve derived from a mathematical model. The formula used is as follows:

$$Gain = G + C \sqrt{\frac{f_x}{f_1}}$$

where

G = constant gain (frequency independent)

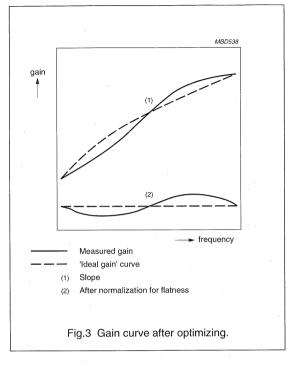
C = cable constant

f_x = desired frequency

f₁ = start frequency.

The cable constant (C) must be optimized during the flatness determination so that the gain curve best fits the measured gain figures. The start value for C is calculated using the formula:

$$C_{start} = \frac{G_n - G_1}{\sqrt{\frac{f_n}{f_1} - 1}}$$



where

G_n = the measured gain at stop frequency

G₁ = the measured gain at start frequency

 $f_n = \text{stop frequency}.$

The value of G is chosen so that the maximum positive deviation of the measured gain from the 'ideal gain' curve is the same as the maximum negative deviation. The value of C is adapted by ± 0.001 until the 'ideal gain' curve best fits the measured curve.

The flatness of the module gain is the maximum deviation in measured gain from the optimized gain formula.

Slope (SL)

DEFINITION

The slope of a module is the difference between the 'ideal gain' at the start frequency and the 'ideal gain' at the stop frequency (see 'Flatness').

General

Flatness (S-curve method)

DEFINITION

For some high-slope modules the flatness is calculated according to the 'S-curve' method. The ideal S-curve is defined as:

$$G_f = G_{f_1} + \delta G \cdot a \cdot (f - f_1) + \delta G \cdot b \cdot (f - f_1)^2 +$$

+ $\delta G \cdot c \cdot (f - f_1)^3$

where

$$\delta G = G_{f_n} - G_{f_1}$$

f₁ = start frequency

f_n = stop frequency

 $a = 3.1224 \times 10^{-3}$

 $b = 1.9932 \times 10^{-6}$

 $c = -8.934 \times 10^{-9}$

The flatness is the maximum deviation between the measured gain and the 'ideal gain' curve.

Delta gain

DEFINITION

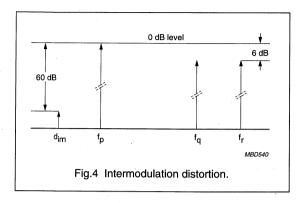
Delta gain is the difference in gain between two given frequencies (mostly the start and stop frequencies).

Intermodulation distortion (dim)

In accordance with DIN 45004B 6.3, 3-tone.

DEFINITION

The intermodulation distortion product is the difference in dB between the peak of the RF signal in the measuring channel and the peak of the distortion signal caused by the influence of a signal in a neighbouring channel (see Fig.4).



To measure 3-tone d_{im}, three CW signals are applied to the module:

 $f_p = f$ level = 0 dB $f_q = f + 7$ MHz level = -6 dB $f_r = f + 9$ MHz level = -6 dB.

The distortion product is measured at f-2 MHz. This distortion product consists of the $(f_p+f_q-f_r)$ beats and is expressed in dB referenced to the 0 dB level (the f_p signal level).

This 0 dB level should be chosen so that the distortion product (d_{im}) is -60 dB. For practical reasons the given output level (V_o) for 3-tone distortion is defined as the 0 dB level and the modules are rejected if the distortion level is worse than -60 dB.

EQUIPMENT

Spectrum analyzer with settings:

Internal attenuator 40 dB
Resolution bandwidth 3 kHz
Video bandwidth 100 Hz
Span 50 kHz.

The three signals are obtained from three different generators (see Appendix A).

Composite third order distortion: composite triple beat (CTB) in CW carriers

In accordance with National Cable Television Association recommendations.

DEFINITION

Composite third order modulation is the amplitude distortion of desired signals, caused by third order curvature of non-linear transfer characteristics in system equipment. It is the ratio, expressed in dB, of the peak level of the RF signal to the peak level of the cluster of distortion components centered around the carrier.

MEASUREMENT

To measure the CTB, a signal at the measuring frequency is set to the specified V_o level. This output level is defined as the 0 dB level. During the measurement⁽¹⁾ all channels in the band are set to the specified V_o level, see Appendix E. Now, at the measuring frequency, the distortion product is measured with a spectrum analyzer or distortion analyzer.

The CTB distortion is measured high in the band because here the distortion products have most amplitude (although the greatest number of beats $(f_1 \pm f_2 \pm f_3)$ and $2 \times f_1 \pm f_2$) are found in the centre of the band).

EQUIPMENT

Spectrum analyzer with settings:

Resolution bandwidth

30 kHz

Video bandwidth

100 kHz

Span

500 kHz.

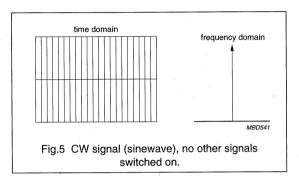
A bandpass filter is used to eliminate the distortion products caused by the spectrum analyzer itself. If desired, a distortion analyzer can be used instead of the spectrum analyzer.

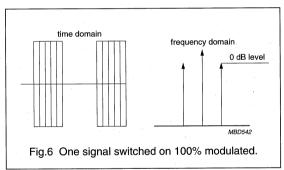
The carrier signals are obtained from a multi-channel generator. The frequency deviation of each channel must be less than 5 kHz.

Composite third order distortion: cross modulation (X_{mod}) in modulated carriers

DEFINITION

Cross modulation distortion is a form of distortion where modulation of interfering stations appears as a modulation of the desired station, caused by third order curvature of non-linear transfer characteristics in system equipment. It is the ratio, expressed in dB, of the peak level of the modulated RF signal to the peak level of the distortion components centered around the carrier (Figs. 5, 6 and 7).





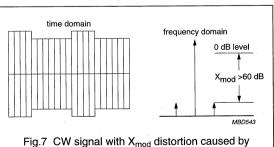


Fig.7 CW signal with X_{mod} distortion caused by other modulated signals.

⁽¹⁾ In the USA, an equally spaced frequency raster is used with a space of 6 MHz between the channels. In Germany frequency distribution of the space between the channels is 7 MHz up to 300 MHz, and 8 MHz above 300 MHz. In general, the Philips measurements are made in accordance with the American frequency raster. For the German market, measurements can be made with a set-up which appoximates as closely as possible to the German raster. A list of both rasters is given in Appendix D.

General

MEASUREMENT

To measure X_{mod} , the carrier of the desired channel is set to the specified V_o level. This channel is then 100% modulated with a 15.75 kHz square wave⁽¹⁾. The peak level of this modulation signal (15.75 kHz on the carrier) is defined as the 0 dB level. The distortion product is now measured by setting each individual CW channel to the specified V_o level and switching them on in modulated mode, see Appendix E. Only the carrier in the channel where the X_{mod} distortion is to be measured, is not modulated. The X_{mod} distortion peak now appears as 15.75 kHz on the carrier.

The X_{mod} distortion is most easily measured at the low end of the frequency band.

EQUIPMENT

Bandpass filter:

Tuned to the channel in which the distortion product is to be measured.

Spectrum analyzer with settings (for most types):

Resolution bandwidth

300 kHz

Video bandwidth

30 Hz

Span

5 kHz.

A multi-channel generator is required for the test signals.

A distortion analyzer will be required if the X_{mod} is to be measured at a high frequency in the band. This is because phase noise will make spectrum analyzer measurements inaccurate.

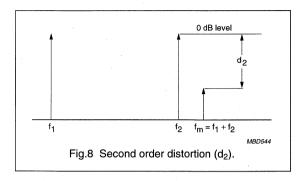
Second order distortion (d₂)

In accordance with DIN 45004-A1.

DEFINITION

The second order distortion product is the difference in dB between the peak level of an RF signal at the measuring frequency, and the peak level of the signal at the measuring frequency caused by two CW signals with their

second order modulation product $(f_1 \pm f_2)$ at the measuring frequency (see Fig.8).



MEASUREMENT

Second order modulation is measured at the frequency in the band where the distortion product is found to be worst. In general this will be at the high end of the band.

In most cases the measuring procedure will be as follows:

Signals f_1 and f_2 are chosen so that f_1 is the lowest channel in the band and f_2 is the highest. This means that $f_1 + f_2$ lays within the band.

The peak levels of f_1 and f_2 are equal and are defined as the 0 dB level. For frequency sets, see Appendix B.

EQUIPMENT

Spectrum analyzer with settings:

Resolution bandwidth

3 kHz

Video bandwidth

100 Hz

Span

50 kHz.

A tunable bandpass filter is used to eliminate the distortion caused by the spectrum analyzer.

Composite second order (CSO) distortion

DEFINITION

Composite second order distortion is the ratio, expressed in dB, of the peak level of the RF signal to the peak level of the cluster of distortion components centered around the desired signal. This distortion is caused by a compilation of components of second order intermodulation products of interfering signals with frequencies f_1 and f_2 , so that

 $f_m = f_1 \pm f_2$ or

 $f_m = 2 \times f_1$ or

 $f_m = 2 \times f_2$.

⁽¹⁾ The 15.75 kHz square wave modulation signal, used with X_{mod} measurements, found its origin in the American broadcasting method. Using the NTSC system, the 15.75 kHz is defined by the 60 Hz mains frequency and the number of 525 TV lines, i.e. (NTSC) = 60 × 525 + 2 = 15.75 kHz. The modulation frequency for PAL (one of the European methods) is 15.625 kHz. This is because in Europe the mains frequency is 50 Hz and the number of TV lines using PAL is 625.

General

MEASUREMENT

Measurement is made by setting a signal with the desired frequency to the specified level for V_o . This V_o level is defined as the 0 dB level.

During the measurement, all channels in the band are levelled to the specified V_o. Now at the measurement frequency, the distortion product is measured by use of a spectrum analyzer.

The CSO distortion is measured high in the band because it is here that this distortion product has most influence, see Appendix E.

EQUIPMENT

Spectrum analyzer with settings:

Resolution bandwidth

30 kHz

Video bandwidth

100 Hz

Span

400 kHz.

A bandpass filter is used at the input of the spectrum analyzer.

S-parameters S₁₁ and S₂₂ (return losses)

In accordance with IEC 747-7.

DEFINITION

The return losses or reflection coefficients of a module can be defined as the S_{11} and the S_{22} of a two-port network (see Fig.9).

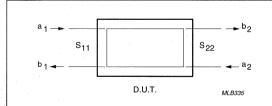


Fig.9 Two-port network with reflection coefficients S_{11} and S_{22} .

$$b_1 = S_{11} \cdot a_1 + S_{12} \cdot a_2 \tag{1}$$

$$b_2 = S_{21} \cdot a_1 + S_{22} \cdot a_2 \tag{2}$$

where

$$a_1 = \frac{1}{2 \cdot \sqrt{Z_0}} \cdot (V_1 + Z_0 \cdot i_1) = \text{signal into port 1}$$
 (3)

$$a_2 = \frac{1}{2 \cdot \sqrt{Z_0}} \cdot (V_2 + Z_0 \cdot i_2) = \text{signal into port 2}$$
 (4)

$$b_1 = \frac{1}{2 \cdot \sqrt{Z_0}} \cdot (V_1 + Z_0 \cdot i_1) = \text{signal out of port 1}$$

$$b_2 = \frac{1}{2 \cdot \sqrt{Z_0}} \cdot (V_2 + Z_0 \cdot i_2) = \text{signal out of port 2}$$

From (1) and (2) formulae for the return losses can be derived:

$$S_{11} = \frac{b_1}{a_1} \Big| a_2 = 0 \tag{5}$$

$$S_{22} = \frac{b_2}{a_2} \Big| a_1 = 0 \tag{6}$$

In (5), $a_2 = 0$ means output port terminated with Z_0 (derived from formula (4)).

In (6), $a_1 = 0$ means input port terminated with Z_0 (derived from formula (3)).

MEASUREMENT

The return losses are measured with a network analyzer after calibration, where the influence of the test jig is eliminated. The necessary termination of the other port with Z_0 is done automatically by the network analyzer.

The network analyser must have a directivity of at least 40 dB to obtain an accuracy of 0.5 dB when measuring return loss figures of 20 dB. A full two-port correction method can be used to improve the accuracy.

Noise figure (F)

In accordance with IEC 747-7.

DEFINITION

The noise figure is defined as the ratio of the total available noise power output from the module when connected to a noise source to that which is generated solely by the noise source.

MEASUREMENT

Noise figure is measured with a noise figure meter at the output of the module, while a noise is connected to the input of the module. Measurements should be done in an electrically-shielded room to prevent pick-up of unwanted signals.

General

APPENDIX A - COMMON FREQUENCY SETS FOR d_{dim} MEASUREMENTS

f _m (MHz)	f _p (MHz)	f _q (MHz)	f _r (MHz)
33.25	35.25	42.25	44.25
163.25	165.25	172.25	174.25
185.25	187.25	194.25	196.25
285.25	287.25	294.25	296.25
335.25	337.25	344.25	346.25
339.25	341.25	348.25	350.25
385.25	387.25	394.25	396.25
438.25	440.25	447.25	449.25
481.25	483.25	490.25	492.25
538.25	540.25	547.25	549.25
849.25	851.25	858.25	860.25

APPENDIX B - COMMON FREQUENCY SETS FOR d2 MEASUREMENTS

f _p (MHz)	f _q (MHz)	f _m (MHz)
83.25	109.25	192.50
66.00	144.00	210.00
55.25	211.25	266.50
55.25	343.25	398.50
55.25	391.25	446.50
55.25	493.25	548.50
300.00	450.00	750.00

General

APPENDIX C - DISTORTION RESULTS USING THE CENELEC FREQUENCY RASTER

The CENELEC Frequency Raster is increasingly being used in Europe. This raster has less channels and these are no longer equally spaced as with the USA Frequency Raster. This results generally in much better distortion readings.

The distortion figures of the CATV hybrids are measured using the standard USA Frequency Raster. A different number of channels is used, however, depending on the frequency range.

The following table based on calculations and correlation measurements using several different hybrid types provides a means of converting the standard measured distortion figures (USA Frequency Raster) into CENELEC Frequency Raster readings.

FREQUENCY	СНА	NNELS	NELS CTB		cso
RANGE (MHz)	USA	CENELEC	(dB)	(dB)	(dB)
40 - 600	85	29	-11.00	-8.00	-6.00
40 - 750	110	35	-12.00	-9.00	-9.00
40 - 860	49	42	+2.00	-1.00	+1.00

General

APPENDIX D - LIST OF FREQUENCY RASTERS FOR USA AND GERMANY

USA		
CHANNEL	FREQUENCY (MHz)	
2	55.25	
3	61.25	
4	67.25	
5	77.25	
6	83.25	
A2	109.25	
A1	115.25	
Α	121.25	
В	127.25	
С	133.25	
D	139.25	
E3	145.25	
F	151.25	
G	157.25	
Н	163.25	
. I	169.25	
7	175.25	
8	181.25	
9	187.25	
10	193.25	
11	199.25	
12	205.25	
13	211.25	
J	217.25	
K	223.25	
L	229.25	
М	235.25	
N	241.25	
0	247.25	
Р	253.25	
Q	259.25	
R	265.25	
S	271.25	
Т	277.25	
U	283.25	
V	289.25	
W	295.25	

USA	USA (CONTINUED)		
CHANNEL FREQUENCY (MHz)			
X	301.25		
Υ	307.25		
Z	313.25		
H1	319.25		
H2	325.25		
Н3	331.25		
H4	337.25		
H5	343.25		
H6	349.25		
H7	355.25		
H8	361.25		
H9	367.25		
H10	373.25		
H11	379.25		
H12	385.25		
H13	391.25		
H14	397.25		
H15	403.25		
H16	409.25		
H17	415.25		
H18	421.25		
H19	427.25		
H20	433.25		
H21	439.25		
H22	445.25		
H23	451.25		
H24	457.25		
H25	463.25		
14	469.25		
15	475.25		
16	481.25		
17	487.25		
18	493.25		
19	499.25		
20	505.25		
21	511.25		
22	517.25		
23	523.25		
24	529.25		

USA (CONTINUED)		
CHANNEL	FREQUENCY (MHz)	
25	535.25	
26	541.25	
27	547.25	
28	553.25	
29	559.25	
30	565.25	
31	571.25	
32	577.25	
33	583.25	
34	589.25	
35	595.25	
36	601.25	
37	607.25	
38	613.25	
39	619.25	
40	625.25	
41	631.25	
42	637.25	
43	643.25	
44	649.25	
45	655.25	
46	661.25	
47	667.25	
48	673.25	
49	679.25	
50	685.25	
51	691.25	
52	697.25	
53	703.25	
54	709.25	
55	715.25	
56	721.25	
57	727.25	
58	733.25	
59	739.25	
60	745.25	
61	751.25	
62	757.25	
63	763.25	

USA (CONTINUED)		
CHANNEL	FREQUENCY (MHz)	
64	769.25	
65	775.25	
66	781.25	
67	787.25	
68	793.25	
69	799.25	
70	805.25	
71	811.25	
72	817.25	
73	823.25	
74	829.25	
75	835.25	
76	841.25	
77	847.25	
78	853.25	
79	859.25	
80	865.25	
81	871.25	
82	877.25	
83	883.25	
84	889.25	
85	895.25	

GERMANY					
CHANNEL	CHANNEL FREQUENCY (MHz)				
K2	48.25				
K3	55.25				
K4	62.25				
<u> </u>	69.25				
_	76.25				
S2	112.25				
S3	119.25				
S4	126.25				
S5	133.25				
S6	140.25				
S7	147.25				
S8	154.25				
S10	168.25				

General

GERMANY (CONTINUED)			
CHANNEL	FREQUENCY (MHz)		
K5	175.25		
K6	182.25		
K7	189.25		
K8	196.25		
K9	203.25		
K10	210.25		
K11	217.25		
K12	224.25		
S11	231.25		
S12	238.25		
S13	245.25		
S14	252.25		
S15	259.25		
S16	266.25		
S17	273.25		
S18	280.25		
S19	287.25		
S20	294.25		
S21	303.25		

GERMANY (CONTINUED)		
CHANNEL	FREQUENCY (MHz)	
S22	311.25	
S23	319.25	
S24	327.25	
S25	335.25	
S26	343.25	
S27	351.25	
S28	359.25	
S29	367.25	
S30	375.25	
S31	383.25	
S32	391.25	
S33	399.25	
S34	407.25	
S35	415.25	
S36	423.25	
S37	431.25	
S38	439.25	
S39	445.25	

APPENDIX E - TEST CHANNELS

Channels used during CTB, X_{mod} and CSO measurements

RANGE	NAMES	FREQUENCIES (MHz)	CHANNELS
5 - 200 MHz	T7 - T13	7.00 - 43.00	7
22 channels	2 - 4	55.25 - 67.25	3
	5 - 6	77.25 - 83.25	2
	A - 7	121.25 - 175.25	10
40 - 300 MHz	2 - 4	55.25 - 67.25	3
32 channels	5 - 6	77.25 - 83.25	2
	A2	109.25	1
	A-F	121.25 - 151.25	6
	H-S	163.25 - 271.25	19
	W	295.25	. 1
40 - 450 MHz	2 - 4	55.25 - 67.25	3
52 channels	5 - 6	77.25 - 83.25	2
	A2	109.25	1
	A - F	121.25 - 151.25	6
	H - H14	163.25 - 397.25	40
40 - 450 MHz	2 - 4	55.25 - 67.25	3
60 channels	5 - 6	77.25 - 83.25	2
	A - H22	121.25 - 445.25	55
40 - 550 MHz	2 - 4	55.25 - 67.25	3
77 channels	5 - 6	77.25 - 83.25	2
	A - 27	121.25 - 547.25	72
40 - 600 MHz	2 - 4	55.25 - 67.25	3
85 channels	5 - 6	77.25 - 83.25	2
	A - 35	121.25 - 595.25	80
40 - 750 MHz	2 - 4	55.25 - 67.25	3
110 channels	5 - 6	77.25 - 83.25	2
	A - 60	121.25 - 745.25	105
			Continued on next pag

General

APPENDIX E - TEST CHANNELS (CONTINUED)

Channels used during CTB, X_{mod} and CSO measurements

RANGE	NAMES	FREQUENCIES (MHz)	CHANNELS
40 - 860 MHz	2	55.25	. 1
49 channels	4	67.25	i .
+5 Chamileis	6		
	9	83.25	1
	7	175.25	1
	9	187.25	1
	12	205.25	1
	J	217.25	1
	М	235.25	1
	0 .	247.25	1
	R	265.25	1
	T T	277.25	1
	w		
		295.25	1
	Y	307.25	1
	H2	325.25	1
	H4	337.25	. 1
	H7	355.25	1
	H9	367.25	1
	H12	385.25	1
	H14		•
		397.25	1
	H17	415.25	1
	H19	427.25	1 ,
	H22	445.25	1
	H24	457.25	1
	15	475.25	1
	17	487.25	1
	20	505.25	i .
	22	517.25	1
	25	535.25	1
	27	547.25	. 1
	30	565.25	1
	32	577.25	1
	35	595.25	1
	37	607.25	1
	40	625.25	1
	42	637.25	
		057.25	1
	45	655.25	1
	47	667.25	1
	50	685.25	1
	52	697.25	1
	55	715.25	1
	57	727.25	1
	60	745.25	1
	62	757.25	1
			l 4
	65	775.25	1
	67	787.25	1
	70	805.25	1 -
	73	823.25	1
	76	841.25	1
	79	859.25	i
	. 0	555.25	1

General

APPENDIX E - TEST CHANNELS (CONTINUED)

Channels used during CTB, X_{mod} and CSO measurements

RANGE	NAMES	FREQUENCIES (MHz)	CHANNELS
40 - 860 MHz	2 - 4	55.25 - 67.25	3
129 channels	5 - 6	77.25 - 83.25	2
	A - 79	121.25 - 859.25	124
40 - 450 MHz	2 - 3	55.25 - 61.25	2
36 channels	C-F	133.25 - 151.25	4
German raster	H	163.25	1
	7	175.25	1
(For test purposes, USA	9	187.25	1
frequency rasters are used	12	205.25	. 1
to emulate the German	J	217.25	1
raster)	L - M	229.25 - 235.25	2
	O-S	247.25 - 271.25	5
	U - X	283.25 - 301.25	4
	Z - H2	313.25 - 325.25	3
	H4	337.25	1
	H6	349.25	1
	H8 - H10	361.25 - 373.25	3
	H12 - H13	385.25 - 391.25	2
	H16 - H18	409.25 - 421.25	3
	H20	433.25	1

DEVICE DATA

in alphanumeric sequence

CATV power doubler amplifier modules

BGD102; BGD104

FEATURES

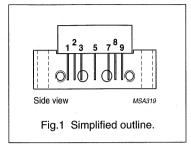
- Excellent linearity
- · High output level
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Power doubler amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION			
1	input			
2	common			
3	common			
5	+V _B			
7	common			
8	common			
9	output			



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz			
•	BGD102		18	19	dB
	BGD104		19.5	20.5	dB
	power gain	f = 450 MHz			
	BGD102		19.2	21.2	dB
	BGD104		20.5	22.5	dB
I _{tot}	total current consumption (DC)	V _B = 24 V		435	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD102; BGD104

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz			
	BGD102		18	19	dB
	BGD104		19.5	20.5	dB
	power gain	f = 450 MHz			
	BGD102		19.2	21.2	dB
	BGD104		20.5	22.5	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	_	20	dB
		f = 80 to 160 MHz	_	19	dB
		f = 160 to 450 MHz	_	18	dB
S ₂₂	output return losses	f = 40 to 80 MHz	_	20	dB
		f = 80 to 160 MHz	-	19	dB
		f = 160 to 450 MHz	_	18	dB
S ₂₁	phase response	f = 50 MHz	+135	+225	deg-
СТВ	composite triple beat	60 channels flat;			
	BGD102	$V_0 = 46 \text{ dBmV};$	-	-65	dB
	BGD104	measured at 445.25 MHz	_	-64	dB
X_{mod}	cross modulation	60 channels flat;	-		
	BGD102	$V_o = 46 \text{ dBmV};$	- "	67	dB
	BGD104	measured at 55.25 MHz	-	-66	dB
d ₂	second order distortion	note 1	-	-73	dB
Vo	output voltage	d _{im} = -60 dB; note 2			
	BGD102		65	_	dBmV
	BGD104		64.5	_	dBmV
F	noise figure	f = 40 to 450 MHz	-	7	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_o = 46$ dBmV; $f_q = 343.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 398.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$

 $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGD106

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TIPtAu metallized crystals ensure optimal reliability.

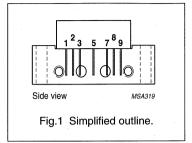
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN DESCRIPTION	
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	22.5	dB
		f = 450 MHz	22.1	-	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	435	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGD106

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; $T_{case} = 35$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	21.5	22.5	dB
		f = 450 MHz	22.1		dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz		±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	-	20	dB
		f = 80 to 160 MHz	- 1 1 1	19	dB
		f = 160 to 450 MHz	-	18	dB
S ₂₂	output return losses	f = 40 to 80 MHz	-	20	dB
		f = 80 to 160 MHz		19	dB
		f = 160 to 450 MHz		18	dB
СТВ	composite triple beat	60 channels flat;	- " "	-63	dB
		$V_0 = 46 \text{ dBmV};$			
		measured at 446.5 MHz			
X_{mod}	cross modulation	60 channels flat;	-	-63	dB
		V _o = 46 dBmV; measured at 55.25 MHz			
CSO	composite second order	60 channels flat:		-59	dB
	distortion	$V_0 = 46 \text{ dBmV};$			- GB
		measured at 446.5 MHz			
d ₂	second order distortion	V _o = 46 dBmV; note 1	_	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	66.5	- * *	dBmV
F	noise figure	f = 450 MHz	_	6.5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	-	435	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; f_q^{r} = 391.25 MHz; V_q = 46 dBmV; measured at f_p + f_q = 446.5 MHz.
- 2. Measured according to DIN45004B;

$$\begin{split} f_p &= 440.25 \text{ MHz}; \ V_p = V_o = 66.5 \ dBmV; \\ f_q &= 447.25 \ MHz; \ V_q = V_o - 6 \ dB; \end{split}$$

 $f_r = 449.25 \text{ MHz}$; $V_r = V_o - 6 \text{ dB}$.

BGD108

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

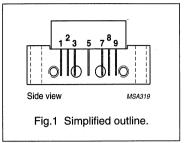
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
.1	input
. 2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	35	37	dB
		f = 450 MHz	36.5	_	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	625	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGD108

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; $T_{case} = 35$ °C; $Z_S = Z_L = 75 \Omega$; $V_B = +24 V$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	35	37	dB
		f = 450 MHz	36.5		dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 450 MHz		±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 450 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	- 1	dB
		f = 160 to 450 MHz	18		dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz		-64	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-	-65	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz		-62	dB
d ₂	second order distortion	note 1	- 1	-73	dB
V _o	output voltage	d _{im} = −60 dB; note 2	67	- 1	dBmV
F	noise figure	f = 450 MHz		7	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	<u> </u>	625	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; V}_p = 46 \text{ dBmV;} \\ & f_q = 391.25 \text{ MHz; V}_q = 46 \text{ dBmV;} \\ & \text{measured at } f_p + f_q = 446.5 \text{ MHz.} \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ & f_q = 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGD502; BGD504

FEATURES

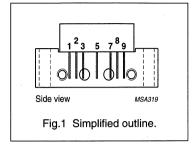
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz			
	BGD502		18	19	dB
	BGD504		19.5	20.5	dB
	power gain	f = 550 MHz			
	BGD502		18.8	20.8	dB
	BGD504		20.2	22.2	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	435	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD502; BGD504

CHARACTERISTICS

Bandwidth 40 to 550 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75 \ \Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz				
	BGD502		18	- 1	19	dB
	BGD504		19.5	-	20.5	dB
	power gain	f = 550 MHz		1		
	BGD502		18.8		20.8	dB
	BGD504		20.2		22.2	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	1-	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-:	-	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 550 MHz	18		1-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19			dB
		f = 160 to 550 MHz	18		_	dB
S ₂₁	phase response	f = 50 MHz	+135	-	+225	deg
СТВ	composite triple beat	77 channels flat;				1 1
	BGD502	$V_o = 44 \text{ dBmV};$			-65	dB
	BGD504	measured at 547.25 MHz		-	-64	dB
X _{mod}	cross modulation	77 channels flat;				
	BGD502	$V_o = 44 \text{ dBmV};$	`- <u> </u> - '.	_	-68	dB
	BGD504	measured at 55.25 MHz		_	-67	dB
CSO	composite second order distortion	77 channels flat;		- 1		
	BGD502	$V_o = 44 \text{ dBmV};$	- 1	_	-62	dB
	BGD504	measured at 548.5 MHz		_	-60	dB
d ₂	second order distortion	note 1				
	BGD502		_	- 1	-72	dB
	BGD504			-	-70	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2				
	BGD502		64	_	_	dBmV
	BGD504		63.5	_ '	_	dBmV
F	noise figure	f = 550 MHz		-	8	dB
I _{tot}	total current consumption (DC)	note 3	-	415	435	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 493.25 \text{ MHz}$; $V_q = 44 \text{ dBmV}$; measured at $f_p + f_q = 548.5 \text{ MHz}$.
- 2. Measured according to DIN45004B: f_p = 540.25 MHz; V_p = V_o ; f_q = 547.25 MHz; V_q = V_o –6 dB; f_r = 549.25 MHz; V_r = V_o –6 dB; measured at f_p + f_q f_r = 538.25 MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

1995 Oct 25 41

BGD502; BGD504

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz				
·	BGD502		18		19	dB
	BGD504		19.5	-	20.5	dB
	power gain	f = 450 MHz				
	BGD502		18.6	-	20.6	dB
	BGD504		20	- '	22	dB
SL	slope cable equivalent	f = 40 to 450 MHz			-	
	BGD502		0.2	-	1.8	dB
	BGD504		0	- "	1.65	dB .
FL	flatness of frequency response	f = 40 to 450 MHz	_	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_		dB
		f = 80 to 160 MHz	19	-	- ,	dB
		f = 160 to 450 MHz	18	-	-	dB
S ₂₁	phase response	f = 50 MHz	+135	_	+225	deg
СТВ	composite triple beat	60 channels flat;				
	BGD502	$V_o = 46 \text{ dBmV};$	-	_	-67	dB
	BGD504	measured at 445.25 MHz	-	_	-66	dB
CSO	composite second order distortion	60 channels flat;		-		
	BGD502	$V_o = 46 \text{ dBmV};$	_	_	t.b.f.	dB
	BGD504	measured at 548.5 MHz	_	_	t.b.f.	dB
X _{mod}	cross modulation	60 channels flat;				
	BGD502	$V_o = 46 \text{ dBmV};$	_	-	-67	dB
	BGD504	measured at 55.25 MHz	-		-66	dB
d ₂	second order distortion	note 1				
	BGD502		_	_	-75	dB
	BGD504		_	-	-73	dB
Vo	output voltage	d _{im} = -60 dB; note 2		-		
	BGD502		67	_	-	dBmV
	BGD504		66.5	_	_	dBmV
F	noise figure	f = 450 MHz	_	_	7	dB
I _{tot}	total current consumption (DC)	note 3	_	415	435	mA

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 391.25 \text{ MHz}$; $V_q = 46 \text{ dBmV}$; measured at $f_p + f_q = 446.5 \text{ MHz}$.
- 2. Measured according to DIN45004B: f_p = 440.25 MHz; V_p = V_o ; f_q = 447.25 MHz; V_q = V_o -6 dB; f_r = 449.25 MHz; V_r = V_o -6 dB; measured at f_p + f_q f_r = 438.25 MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

BGD506

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

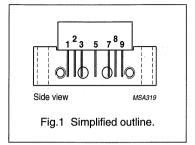
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	22.5	dB
		f = 550 MHz	22.1	_	dB
I _{tot}	total current consumption (DC)	VB = +24V	_	435	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C
V _B	DC supply voltage		+28	V

BGD506

CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 35$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	22.5	dB
		f = 550 MHz	22.1		dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	_	20	dB
		f = 80 to 160 MHz		19	dB
		f = 160 to 550 MHz	-	18	dB
S ₂₂	output return losses	f = 40 to 80 MHz	- 1	20	dB
		f = 80 to 160 MHz	-	19	dB
		f = 160 to 550 MHz		18	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	-	-62	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-63	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-55	dB
d ₂	second order distortion	V _o = 44 dBmV; note 1		-66	dB
Vo	output voltage	d _{im} = -60 dB; note 2	62.5	_	dBmV
F	noise figure	f = 550 MHz		7	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	-	435	mA

Notes

- 1.
 $$\begin{split} f_p = 55.25 \text{ MHz; } V_p = 44 \text{ dBmV;} \\ f_q = 493.25 \text{ MHz; } V_q = 44 \text{ dBmV;} \\ \text{measured at } f_p + f_q = 548.5 \text{ MHz.} \end{split}$$
- 2. Measured according to DIN45004B;

$$\begin{split} f_p &= 540.25 \text{ MHz; } V_o = V_p; \\ f_q &= 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGD508

FEATURES

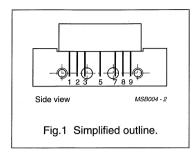
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115C

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	35	37	dB
	· ·	f = 550 MHz	36.5	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	625	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C ,

BGD508

CHARACTERISTICS

Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	35	37	dB
		f = 550 MHz	36.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-,	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	- "	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-62	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-65	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	63	_	dBmV
F	noise figure	f = 550 MHz	-	7.5	dB
I _{tot}	total current consumption (DC)	note 3	-	625	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 393.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$ $f_q = 447.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

1995 Nov 14

BGD508

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	35	37	dB
		f = 450 MHz	36.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
·		f = 160 to 450 MHz	18	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	'	-64	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-65	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV measured at 446.5 MHz	-	-62	dB
d ₂	second order distortion	note 1	_	-73	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 450 MHz	_	7	dB
I _{tot}	total current consumption (DC)	note 3	_	625	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{split}$$

BGD508

HANDLING

As the BGD508 is a high gain amplifier with doubled output power and 15 W dissipation, it is necessary to ground the heatsink when the power supply is switched on or off.

Switching on

- Ensure the 24 V (DC) supply is disconnected from the PCB or test jig.
- Ground the heatsink and the common pins (pins 2, 3, 7 and 8) of the module. Connect input and output pins (pins 1 and 9) to a 75 Ω source and load.
- 3. Connect the 24 V (DC) to the module.

Permanent damage to the amplifier can be caused by switching on the supply voltage when the heatsink is not fully grounded.

Switching off

- 1. Disconnect the 24 V (DC) supply from the PCB or test jig.
- 2. Disconnect the module.

Permanent damage to the amplifier can be caused by disconnecting ground from the heatsink and common pins before the module supply voltage is switched off.

BGD601

FEATURES

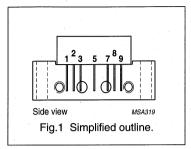
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module designed for applications in CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	13	dB
		f = 600 MHz	12.7		dB
I _{tot}	total current consumption (DC)	V _B = 24 V		435	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD601

CHARACTERISTICS

Table 1 Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	13	dB
		f = 600 MHz	12.7	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz		±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
	-	f = 160 to 600 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	_	dB
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-62	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-66	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	63	_	dBmV
F	noise figure	f = 600 MHz	_	9.5	dB
I _{tot}	total current consumption (DC)	note 3		435	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ & f_q = 541.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \end{array}$ measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 588.25$ MHz.

BGD601

Table 2 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	12	13	dB
		f = 550 MHz	12.5	14.5	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	- 1	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	=	-65	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-68	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz		-64	dB
d ₂	second order distortion	note 1		-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	-	dBmV
F	noise figure	f = 550 MHz	_	9	dB
I _{tot}	total current consumption (DC)	note 3		435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

$$f_p = 540.25 \text{ MHz}; V_p = V_o;$$

$$f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGD601

Table 3 Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	13	dB
		f = 450 MHz	12.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
-		f = 160 to 450 MHz	18	_	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-67	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-67	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	-65	dB
d ₂	second order distortion	note 1		-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 450 MHz	_	8	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

$$f_p = 440.25 \text{ MHz}; V_p = V_o;$$

$$f_q = 447.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$$

$$f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGD602

FEATURES

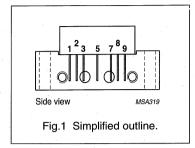
- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module designed for applications in CATV systems with a bandwidth of 40 to 600 MHz operating with a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	19	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V		435	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD602

CHARACTERISTICS

Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
	+	f = 600 MHz	19	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
*		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-62	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	r	66	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	63	_	dBmV
F	noise figure	f = 600 MHz	-	8	dB
I _{tot}	total current consumption (DC)	note 3	-	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

$$f_p = 590.25 \text{ MHz}; V_p = V_o;$$

 $f_q = 597.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$
 $f_r = 599.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$
measured at $f_p + f_q - f_r = 588.25 \text{ MHz}.$

BGD602

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{mb} = 35 °C; Z_S = Z_L = 75 $\Omega.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.8	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-66	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-68	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	-	-62	dB
d ₂	second order distortion	note 1	_	-72	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	64	-	dBmV
F	noise figure	f = 550 MHz	-	7.5	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

```
\begin{split} f_p &= 540.25 \text{ MHz; } V_p = V_o; \\ f_q &= 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 549.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 538.25 \text{ MHz.} \end{split}
```

BGD602

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75$ Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.6	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-67	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz		-66	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV measured at 446.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-75	dB
V _o	output voltage	d _{im} = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 450 MHz		7	dB
I _{tot}	total current consumption (DC)	note 3		435	mA

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:
 - $f_p = 440.25 \text{ MHz}; V_p = V_o;$
 - $f_q = 447.25 \text{ MHz}; V_q = V_o 6 \text{ dB};$
 - $f_r = 449.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
 - measured at $f_p + f_q f_r = 438.25$ MHz.
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD602D

FEATURES

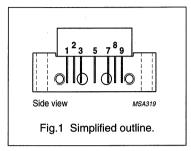
- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range cascode amplifier module with darlington configuration for CATV systems operating over a frequency range of 40 to 600 MHz at a supply voltage of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	17.5	18.5	dB
		f = 600 MHz	18.5	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	440	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD602D

CHARACTERISTICS

Bandwidth 40 to 600 MHz; $V_B = 24$ V; $T_{case} = 35$ °C; $Z_S = Z_L = 75$ Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.5	18.5	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 600 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	 -	dB
		f = 160 to 600 MHz	18	- "	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz		-68	dB
X _{mod}	cross modulation	85 channels flat; $V_o = 44 \text{ dBmV}$; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-64	dB
d ₂	second order distortion	note 1	-	-76	dB
Vo	output voltage	d _{im} = -60 dB; note 2	66	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 600 MHz	1-	7	dB
I _{tot}	total current consumption (DC)	note 3	=,.	440	mA

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV}; \\ f_q = 541.25 \text{ MHz}; V_q = 44 \text{ dBmV}; \\ \text{measured at } f_p + f_q = 596.5 \text{ MHz}.$
- $\begin{array}{ll} 2. & f_p = 590.25 \text{ MHz; V}_p = V_o; \\ f_q = 597.25 \text{ MHz; V}_q = V_o 6 \text{ dB;} \\ f_r = 599.25 \text{ MHz; V}_r = V_o 6 \text{ dB;} \\ \text{measured at f}_p + f_q f_r = 588.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD602D

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{case} = 35 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.5	18.5	dB
		f = 550 MHz	18.3	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-69	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-62	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	-	-66	dB
d ₂	second order distortion	note 1	-	-78	dB
Vo	output voltage	d _{im} = −60 dB; note 2	67	-	dBmV
F	noise figure	f = 50 MHz	ļ -	5.5	dB
		f = 550 MHz	_	7	dB
I _{tot}	total current consumption (DC)	note 3	_	440	mA

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. $f_p = 540.25$ MHz; $V_p = V_o$; $f_q = 547.25$ MHz; $V_q = V_o 6$ dB; $f_r = 549.25$ MHz; $V_r = V_o 6$ dB; measured at $f_p + f_q f_r = 538.25$ MHz.
- 3. The module normally operates at $V_B = 24~V$, but is able to withstand supply transients up to 30 V.

BGD602D

CHARACTERISTICS

Bandwidth 40 to 450 MHz; V_B = 24 V; T_{case} = 35 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.5	18.5	dB
		f = 450 MHz	18.1	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
-		f = 160 to 450 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-	-68	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV measured at 446.5 MHz	-	-66	dB
d ₂	second order distortion	note 1	_	-80	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	67	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 450 MHz	-	6.5	dB
I _{tot}	total current consumption (DC)	note 3	_	440	mA

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 391.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; V}_p = V_o; \\ & f_q = 447.25 \text{ MHz; V}_q = V_o 6 \text{ dB;} \\ & f_r = 449.25 \text{ MHz; V}_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD702

FEATURES

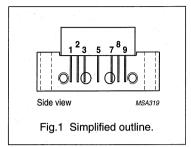
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION			
1	input			
2	common			
3	common			
5	+V _B			
7	common			
8	common			
9	output			



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	- , '	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	435	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD702

CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 640 MHz	17	_	dB
		f = 640 to 750 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 640 MHz	17	_	dB
		f = 640 to 750 MHz	16	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-58	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	62	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-58	dB
d ₂	second order distortion	note 1	-	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
	·	f = 450 MHz	- 1	6.5	dB
		f = 550 MHz	_	6.5	dB
		f = 600 MHz	-	7	dB
		f = 750 MHz	_	8.5	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 749.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 738.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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BGD702

Table 2 Bandwidth 40 to 600 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz		±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 600 MHz	17	1-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 320 MHz	18		dB
		f = 320 to 600 MHz	17		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	-65	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-65	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	-	-60	dB
d ₂	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	-	dBmV
F	noise figure	see Table 1	- 1	_	dB
I _{tot}	total current consumption (DC)	note 3		435	mA .

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

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Table 3 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB .
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 550 MHz	17	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 550 MHz	17	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	-	-67	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	<u>.</u>	-67	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-62	dB
d ₂	second order distortion	note 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64.5	-	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.

2. Measured according to DIN45004B:

 $f_p = 540.25 \text{ MHz}; V_p = V_o;$

 $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGD702

Table 4 Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 450 MHz	17	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	- "	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 450 MHz	17	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-	-68	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz		-65	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV measured at 446.5 MHz		-65	dB
d ₂	second order distortion	note 1	_	-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	-	dBmV
F	noise figure	see Table 1	-	-	dB
I _{tot}	total current consumption (DC)	note 3	-	435	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 46 \ \text{dBmV}; \\ & f_q = 391.25 \ \text{MHz}; \ V_q = 46 \ \text{dBmV}; \\ & \text{measured at} \ f_p + f_q = 446.5 \ \text{MHz}. \end{array}$
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \end{split}$$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGD702D

FEATURES

- · Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

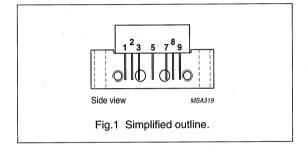
CATV systems in the 40 to 750 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range cascode amplifier module with darlington pre-stage dies operating at a voltage supply of $24\ V\ (DC)$.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	20	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	400	435	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	supply voltage	_	25	٧
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD702D

CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	20		dB
SL	slope cable equivalent	f = 40 to 750 MHz	2	4	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB ·
·		f = 640 to 750 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	1-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	1-	dB
	•	f = 640 to 750 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-62	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-62	dB
d ₂	second order distortion	note 1	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 750 MHz	_	7	dB
I _{tot}	total current consumption (DC)	note 3	400	435	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 691.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 746.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 749.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 738.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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BGD702D

Table 2 Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	19.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	1.5	3.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB .
		f = 320 to 600 MHz	16	- "	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	-68	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-62	dB
d ₂	second order distortion	note 1	_	-74	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	68	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 600 MHz	T-	6	dB
I _{tot}	total current consumption (DC)	note 3	400	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

BGD702D

Table 3 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	19		dB
SL	slope cable equivalent	f = 40 to 550 MHz	1	3	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 550 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
:		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
	·	f = 320 to 550 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-69	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-62	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-66	dB
d_2	second order distortion	note 1	-	-78	dB
Vo	output voltage	d _{im} = -60 dB; note 2	69	_	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 550 MHz	-	5.5	dB
I _{tot}	total current consumption (DC)	note 3	400	435	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV}; \\ f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV}; \\ \text{measured at } f_p + f_q = 548.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $f_p = 540.25 \text{ MHz}; V_p = V_o;$ $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ measured at $f_p + f_q - f_r = 538.25 \text{ MHz}.$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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Hybrid CATV amplifier module

BGD702MI

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability
- Mirrored image pinning of the BGD702.

APPLICATIONS

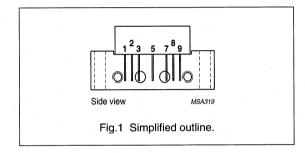
 CATV systems operating in the 40 to 750 MHz frequency range.

DESCRIPTION

Hybrid amplifier module in a SOT115J package operating at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	output
2	common
3	common
5	+V _B
7	common
8	common
9	input



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	435	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD702MI

CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 640 MHz	17	-	dB
		f = 640 to 750 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	_	dB
•		f = 320 to 640 MHz	17	_	dB
		f = 640 to 750 MHz	16	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-58	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-62	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-58	dB
d ₂	second order distortion	note 1	_	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 450 MHz	_	6.5	dB
		f = 550 MHz	_	6.5	dB
		f = 600 MHz	-	7	dB
		f = 750 MHz	_	8.5	dB
I _{tot}	total current consumption (DC)	note 3	-	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 740.25 \text{ MHz}; V_p = V_o;$ $f_q = 747.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 749.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ measured at $f_p + f_q - f_r = 738.25 \text{ MHz}.$

3. The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

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BGD702MI

Table 2 Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 600 MHz	17	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	-	dB
	and the second s	f = 320 to 600 MHz	17		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	-65	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-65	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d ₂	second order distortion	note 1		-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64		dBmV
F	noise figure	see Table 1			dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.

2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

BGD702MI

Table 3 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	. .	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
1 A 1 A 1 A 1 A 1 A 1 A 1 A 1 A 1 A 1 A		f = 80 to 160 MHz	19	<u>-</u>	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 550 MHz	17	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 550 MHz	17	1-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-67	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-67	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz		-62	dB
d ₂	second order distortion	note 1	_	-72	dB
V _o	output voltage	$d_{im} = -60 \text{ dB}$; note 2	64.5		dBmV
F	noise figure	see Table 1	_	-	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 540.25 \text{ MHz; } V_p = V_o; \\ f_q &= 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 549.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 538.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD702MI

Table 4 Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	Ī-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18		dB
		f = 320 to 450 MHz	17	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
·		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 450 MHz	17	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-68	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-	-65	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	-65	dB
d ₂	second order distortion	note 1		-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67		dBmV
F	noise figure	see Table 1	_	. –	dB
I _{tot}	total current consumption (DC)	note 3		435	mA -

Notes

1. $f_p = 55.25 \text{ MHz}; V_p = 46 \text{ dBmV};$ $f_q = 391.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at $f_p + f_q = 446.5 \text{ MHz}.$

2. Measured according to DIN45004B:

 $\begin{array}{l} f_p = 440.25 \; \text{MHz;} \; V_p = V_o; \\ f_q = 447.25 \; \text{MHz;} \; V_q = V_o - 6 \; \text{dB;} \\ f_r = 449.25 \; \text{MHz;} \; V_r = V_o - 6 \; \text{dB;} \\ \text{measured at} \; f_p + f_q - f_r = 438.25 \; \text{MHz.} \end{array}$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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FEATURES

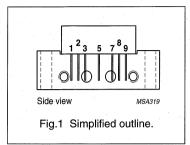
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

APPLICATIONS

• CATV systems in the frequency range of 40 to 750 MHz.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



DESCRIPTION

Hybrid amplifier module operating at a voltage supply of +24 V (DC) encapsulated in a SOT115J package.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 750 MHz	20		dB
I _{tot}	total current consumption (DC)	V _B = +24 V		435	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	PARAMETER MIN. MAX.		UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD704

CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $V_B = +24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 750 MHz	20	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	_ :	dB
		f = 320 to 640 MHz	17	-	dB
		f = 640 to 750 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 640 MHz	17	-	dB
		f = 640 to 750 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-57	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-56	dB
d_2	second order distortion	note 1	_	-66	dB .
Vo	output voltage	d _{im} = -60 dB; note 2	60.5	_	dBmV
F	noise figure	f = 50 MHz	_	5	dB
		f = 450 MHz	_	6.5	dB
		f = 550 MHz	_	7	dB
		f = 600 MHz	_	7	dB
•	·	f = 750 MHz	_	8.5	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:
 - $f_p = 740.25 \text{ MHz}; V_p = V_o;$
 - $f_q = 747.25 \text{ MHz}; V_q = V_o 6 \text{ dB};$
 - $f_r = 749.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
 - measured at $f_p + f_q f_r = 738.25$ MHz.
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

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Table 2 Bandwidth 40 to 600 MHz; $V_B = +24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 600 MHz	20	1 - 1	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	-	dB
		f = 320 to 600 MHz	17		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 600 MHz	17		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-64	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	. — .	-64	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz		-58	dB
d ₂	second order distortion	note 1		-68	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	63	_	dBmV
F	noise figure	see Table 1		-	dB
I _{tot}	total current consumption (DC)	note 3		435	mA

Notes

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 541.25 MHz; V_q = 44 dBmV; measured at $f_p + f_q = 596.5 \text{ MHz}$.
- 2. Measured according to DIN45004B:

$$\begin{split} &f_p = 590.25 \text{ MHz; } V_p = V_o; \\ &f_q = 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 588.25$ MHz.

3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

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Table 3 Bandwidth 40 to 550 MHz; $V_B = +24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 550 MHz	20	_	dB .
SL	slope cable equivalent	f = 40 to 550 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz		±0.3	dB .
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 550 MHz	17	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 550 MHz	17	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	- "	-66	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-66	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	-	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	63.5	_ :	dBmV
F	noise figure	see Table 1	_	-	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV}; f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

$$f_p = 540.25 \text{ MHz}; V_p = V_o;$$

$$f_{r} = 547.25 \text{ MHz} \cdot V_{r} = V_{r} - 6 \text{ dB} \cdot$$

$$f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGD704

Table 4 Bandwidth 40 to 450 MHz; $V_B = +24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 450 MHz	20	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 320 MHz	18	_	dB
		f = 320 to 450 MHz	17	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 320 MHz	18	- , ,	dB
		f = 320 to 450 MHz	17	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; $V_0 = 46 \text{ dBmV}$; measured at 445.25 MHz	_	-67	dB
X _{mod}	cross modulation	60 channels flat; $V_o = 46 \text{ dBmV}$; measured at 55.25 MHz	-	-64	dB
CSO	composite second order distortion	60 channels flat; $V_0 = 46 \text{ dBmV}$ measured at 446.5 MHz	-	-63	dB
d ₂	second order distortion	note 1	- 1	-73	dB
Vo	output voltage	d _{im} = -60 dB; note 2	66	_	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	435	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGD802

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

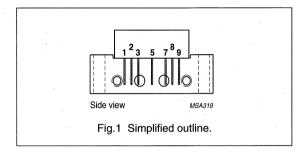
 CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	410	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	supply voltage	-	25	٧
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

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CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	_	dB
+ 21		f = 640 to 860 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	49 channels flat; V _o = 47 dBmV; measured at 859.25 MHz	_	-63	dB
X _{mod}	cross modulation	49 channels flat; V _o = 47 dBmV; measured at 55.25 MHz	-	-62	dB
CSO	composite second order distortion	49 channels flat; V _o = 47 dBmV; measured at 860.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-69	dB
V _o	output voltage	d _{im} = -60 dB; note 2	61.5	_	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 550 MHz		6	dB
		f = 650 MHz		7	dB
		f = 750 MHz	_	7.5	dB
		f = 860 MHz	_	9	dB
I _{tot}	total current consumption (DC)	note 3	_	410	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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Table 2 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5	- :	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	- ,	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	- , ,	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	129 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	-	-54	dB
X _{mod}	cross modulation	129 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-59	dB
CSO	composite second order distortion	129 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	_	-56	dB
d ₂	second order distortion	note 1		-69	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	61.5	- 1	dBmV
F	noise figure	see Table 1		-	dB
I _{tot}	total current consumption (DC)	note 3		410	mA

Notes

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 805.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 860.5 MHz.
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$ $f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

$$\begin{split} f_r &= 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r &= 849.25 \text{ MHz.} \end{split}$$

3. The module normally operates at V_B = 24 V, but is able to withstand supply transients up to 30 V.

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BGD802

Table 3 Bandwidth 40 to 750 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat;	_	-58	dB
		V _o = 44 dBmV; measured at 745.25 MHz			
X _{mod}	cross modulation	110 channels flat;	-	-60	dB .
		V _o = 44 dBmV; measured at 55.25 MHz			
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption (DC)	note 3	_	410	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 749.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 738.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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Table 4 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	- 1	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	_	dB
S ₂₂	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	-	-65	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-63	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-63	dB
d ₂	second order distortion	note 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	65	_	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	410	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

 $\begin{aligned} &f_p = 540.25 \text{ MHz; } V_p = V_o; \\ &f_q = 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ &f_r = 549.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ &\text{measured at } f_p + f_q - f_r = 538.25 \text{ MHz.} \end{aligned}$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD802MI

FEATURES

- Excellent linearity
- · Extremely low noise
- · Excellent return loss properties
- Silicon nitride passivation
- · Rugged construction
- · Gold metallization ensures excellent reliability
- Mirrored image pinning of the BGD802.

APPLICATIONS

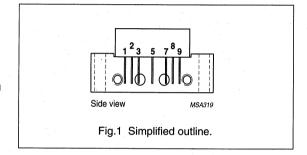
 CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid amplifier module in a SOT115J2 package operating with a voltage supply of 24 V (DC).

PINNING - SOT115J2

PIN	DESCRIPTION
1	output
2	common
3	common
5	+V _B
7	common
8	common
9	input



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5	- "	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	410	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	supply voltage		25	V
V_i	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD802MI

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
r		f = 860 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	49 channels flat; V _o = 47 dBmV; measured at 859.25 MHz	_	-61	dB
X _{mod}	cross modulation	49 channels flat; V _o = 47 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	49 channels flat; V _o = 47 dBmV; measured at 860.5 MHz	-	-60	dB
d ₂	second order distortion	note 1	-	-69	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61.5	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 550 MHz	-	6	dB
		f = 650 MHz	-	7	dB
		f = 750 MHz		7.5	dB
		f = 860 MHz	_	9	dB
I _{tot}	total current consumption (DC)	note 3	_	410	mA

Notes

1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.

2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$

 $f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD802MI

Bandwidth 40 to 860 MHz; V_B = 24 V; T_{case} = 35 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz		±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	- :	dB
		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	- , , ,	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	129 channels flat; V _o = 42 dBmV; measured at 859.25 MHz	-	-58	dB
X _{mod}	cross modulation	129 channels flat; V _o = 42 dBmV; measured at 55.25 MHz	-	-63	dB
CSO	composite second order distortion	129 channels flat; V _o = 42 dBmV; measured at 860.5 MHz		-58	dB
d_2	second order distortion	note 1	_	-69	dB
V _o	output voltage	d _{im} = -60 dB; note 2	61.5	-	dBmV
F	noise figure	see Table 1			dB
I _{tot}	total current consumption (DC)	note 3	-	410	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; f_q^{F} = 805.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 860.5 MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} &f_p = 851.25 \text{ MHz; } V_p = V_o, \\ &f_q = 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

3. The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

BGD804

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

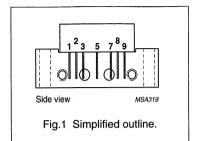
APPLICATIONS

CATV systems in the 40 to 860 MHz frequency range.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



DESCRIPTION

Hybrid amplifier module in a SOT115J package operating at a voltage supply of +24 V (DC).

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 860 MHz	20	_	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	-	410	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C
V _B	supply voltage	_	25	V

BGD804

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = +24$ V; $T_{case} = 35$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 860 MHz	20	- , , , , ,	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	- "	dB
		f = 640 to 860 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	= .	dB
,		f = 640 to 860 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	49 channels flat; V _o = 47 dBmV; measured at 859.25 MHz	-	-61	dB
X _{mod}	cross modulation	49 channels flat; $V_0 = 47 \text{ dBmV}$; measured at 55.25 MHz	_ :	-62	dB
CSO	composite second order distortion	49 channels flat; V _o = 47 dBmV; measured at 860.5 MHz	-,	-58	dB
d ₂	second order distortion	note 1		-67	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60	-	dBmV
F	noise figure	f = 50 MHz	-	5	dB
		f = 550 MHz	_	6	dB
		f = 650 MHz	_	6	dB
		f = 750 MHz	_	6.5	dB
		f = 860 MHz	_	7.5	dB
I _{tot}	total current consumption (DC)	note 3		410	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.
- 2. Measured according to DIN45004B;

 $\begin{array}{l} f_p = 851.25 \text{ MHz}; \ V_p = V_o; \\ f_q = 858.25 \text{ MHz}; \ V_q = V_o - 6 \text{ dB}; \\ f_r = 860.25 \text{ MHz}; \ V_r = V_o - 6 \text{ dB}; \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz}. \end{array}$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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Table 2 Bandwidth 40 to 860 MHz; $V_B = +24$ V; $T_{case} = 35$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 860 MHz	20	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz		±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5		dB ·
		f = 640 to 860 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	129 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	_	-53	dB
X _{mod}	cross modulation	129 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	129 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	_	-54	dB
d ₂	second order distortion	note 1		-67	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60		dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	410	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 805.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 860.5 \text{ MHz}.$
- 2. Measured according to DIN45004B;

$$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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Table 3 Bandwidth 40 to 750 MHz; $V_B = +24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 750 MHz	20	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.45	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5		dB
		f = 640 to 750 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	–57	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-62	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-56	dB
d ₂	second order distortion	note 1		-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	63		dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	410	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 44 \ \text{dBmV}; \\ & f_q = 691.25 \ \text{MHz}; \ V_q = 44 \ \text{dBmV}; \end{array}$ measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B;

 $\begin{aligned} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{aligned}$

 $f_r = 749.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 738.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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BGD804

Table 4 Bandwidth 40 to 650 MHz; $V_B = +24 \text{ V}$; $T_{case} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 650 MHz	20	-	dB
SL	slope cable equivalent	f = 40 to 650 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 650 MHz	-	±0.35	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	- ,	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 650 MHz	15	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	- ,	dB
		f = 320 to 650 MHz	15		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	94 channels flat; V _o = 44 dBmV; measured at 649.25 MHz		-60	dB
X _{mod}	cross modulation	94 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-62	dB
CSO	composite second order distortion	94 channels flat; V _o = 44 dBmV; measured at 650.5 MHz	. —	-58	dB
d ₂	second order distortion	note 1	_	-69	dB
Vo	output voltage	d _{im} = -60 dB; note 2	65	_	dBmV
F	noise figure	see Table 1			dB
I _{tot}	total current consumption (DC)	note 3	-	410	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 595.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 650.5 \text{ MHz}.$
- 2. Measured according to DIN45004B;

 $f_p = 640.25 \text{ MHz}; V_p = V_o;$

 $f_q = 647.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 649.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 638.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

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Table 5 Bandwidth 40 to 550 MHz; $V_B = +24$ V; $T_{case} = 35$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 550 MHz	20	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.35	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-64	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-64	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-62	dB
d ₂	second order distortion	note 1	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	66	-	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption (DC)	note 3	-	410	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B;

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\begin{array}{l} \text{f}_p = 540.25 \text{ MHz; } V_p = V_o; \\ \text{f}_q = 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ \text{f}_r = 549.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 538.25 \text{ MHz.} \end{array}
```

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD885

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

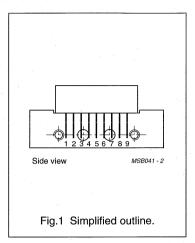
Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115D

PIN	DESCRIPTION	
1	input (note 1)	
2	common	
3	common	
4	10 V, 200 mA supply terminal	
5	common	
6	common	
7	common	
8	+V _B	
9	output (note 1)	

Note

1. Pins 1 and 9 carry DC voltages.



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	450	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER		MAX.	UNIT
V _B	DC supply voltage	_	26	٧
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGD885

CHARACTERISTICS

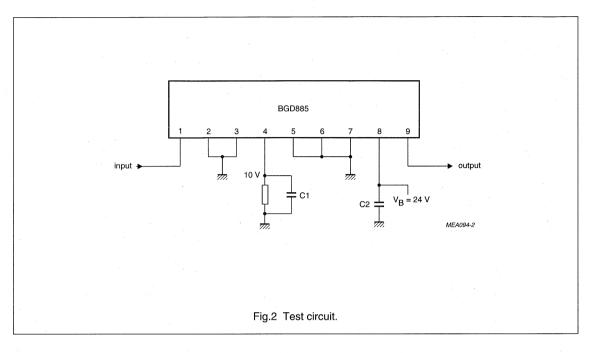
Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.6	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 MHz; note 1	20	_	dB
		f = 800 to 860 MHz	10	_	dB
S ₂₂	output return losses	f = 40 MHz; note 1	20	_	dB
		f = 800 to 860 MHz	10	_	dB
d ₂	second order distortion	note 2	_	-53	dB
Vo	output voltage	d _{im} = -60 dB; note 3	64	_	dBmV
		$d_{im} = -60 \text{ dB}$; note 4	63		dBmV
F	noise figure	f = 50 MHz	_	8	dB
		f = 550 MHz	-	8	dB
-		f = 650 MHz	-	8	dB
		f = 750 MHz	-	8	dB
		f = 860 MHz	_	8	dB
I _{tot}	total current consumption (DC)	note 5	_	450	mA

Notes

- 1. Decrease per octave of 1.5 dB.
- 2. $V_p = 59$ dBmV at $f_p = 349.25$ MHz; $V_q = 59$ dBmV at $f_q = 403.25$ MHz; measured at $f_p + f_q = 752.5$ MHz.
- 3. Measured according to DIN45004B:
 - $$\begin{split} f_p &= 341.25 \text{ MHz; } V_p = V_o; \\ f_q &= 348.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r &= 350.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 339.25 \text{ MHz.} \end{split}$$
- 4. Measured according to DIN45004B:
 - $$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 849.25 \text{ MHz.} \end{split}$$
- 5. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGD885



List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1	ceramic multilayer capacitor	1 nF (max.)
C2	ceramic multilayer capacitor	1 nF
R	resistor	56 Ω, 2 W

BGE884

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

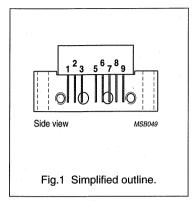
Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115G

PIN	DESCRIPTION
1	input (note 1)
2	common
3	common
5	common
6	common
7	common
8	+V _B
9	output (note 1)

Note

1. Pins 1 and 9 carry DC voltages.



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	150	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	DC supply voltage	-	26	V
V _i	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGE884

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.4	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.3	dB
S ₁₁ .	input return losses	f = 40 MHz; note 1	20	_	dB
		f = 800 to 860 MHz	10	-	dB
S ₂₂	output return losses	f = 40 to 860 MHz	15	-	dB
d ₂	second order distortion	note 2	_	-60	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; notes 3 and 4	55	-	dBmV
F	noise figure	f = 350 MHz	-	7.5	dB
		f = 860 MHz	-	8	dB
I _{tot}	total current consumption (DC)	note 5	-	150	mA

Notes

- 1. Decreases by 1.5 dB per octave.
- $\begin{array}{l} \text{2.} \quad f_p = 349.25 \; \text{MHz; V}_p = 44 \; \text{dBmV;} \\ f_q = 403.25 \; \text{MHz; V}_q = 44 \; \text{dBmV;} \\ \text{measured at f}_p + f_q = 752.5 \; \text{MHz.} \\ \end{array}$
- 3. $f_p = 341.25 \text{ MHz}$; $V_p = V_o$; $f_q = 348.25 \text{ MHz}$; $V_q = V_o 6 \text{ dB}$; $f_r = 350.25 \text{ MHz}$; $V_r = V_o 6 \text{ dB}$; measured at $f_p + f_q f_r = 339.25 \text{ MHz}$.
- $\begin{array}{ll} \text{4.} & \text{f}_p = 851.25 \text{ MHz; } \text{V}_p = \text{V}_o; \\ & \text{f}_q = 858.25 \text{ MHz; } \text{V}_q = \text{V}_o 6 \text{ dB;} \\ & \text{f}_r = 860.25 \text{ MHz; } \text{V}_r = \text{V}_o 6 \text{ dB;} \\ & \text{measured at f}_p + \text{f}_q \text{f}_r = 849.25 \text{ MHz.} \\ \end{array}$
- 5. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGE885

FEATURES

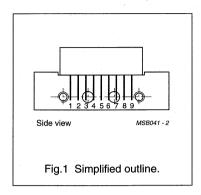
- Excellent linearity
- · Extremely low noise
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier module for use in CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115D

PIN	DESCRIPTION
1	input; note 1
2	common
3	common
4	12 V, 60 mA supply terminal
5	common
6	common
7	common
8	+V _B
9	output; note 1



Note

1. Pins 1 and 9 carry DC voltages.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	16.5	17.5	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	240	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	DC supply voltage		28	V
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

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BGE885

CHARACTERISTICS

Bandwidth 40 to 860 MHz; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 450 MHz	-	14	dB
		f = 450 to 860 MHz	_	10	dB
S ₂₂	output return losses	f = 40 to 450 MHz	_	14	dB
		f = 450 to 860 MHz	_	10	dB
d ₂	second order distortion	note 1	_	-53	dB
Vo	output voltage	d _{im} = -60 dB; note 2	_	59	dBmV
F	noise figure	f = 350 MHz	_	7.5	dB
		f = 860 MHz	-	8	dB
I _{tot}	total current consumption (DC)	note 3		240	mA

Notes

- 1. $f_p = 349.25 \text{ MHz}; V_p = 59 \text{ dBmV}; f_q = 403.25 \text{ MHz}; V_q = 59 \text{ dBmV}; measured at } f_p + f_q = 752.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o = 59 \text{ dBmV};$

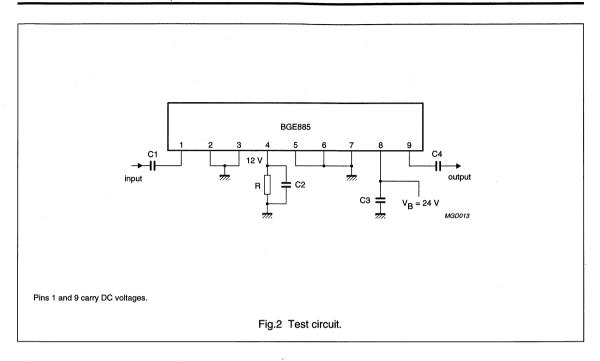
 $f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGE885



List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1, C3, C4	ceramic multilayer capacitor	1 nF
C2	ceramic multilayer capacitor	1 nF (max.)
R	resistor	200 Ω, 1 W

BGE887

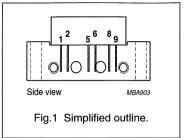
FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

PINNING - SOT115H

PIN	DESCRIPTION
1	input
2	common
5	+V _B
6	common
8	common
9	output

PIN CONFIGURATION



DESCRIPTION

Hybrid amplifier module intended for use in the UHF part of VHF/UHF split-band CATV systems over a frequency range of 470 to 860 MHz with a voltage supply of +24 V (DC).

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 470 MHz	22.5	25	dB
I _{tot}	total current consumption (DC)	V _B = +24 V; note 1	_	280	mA

Note

1. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C
V _B	DC supply voltage	-	+28	V

BGE887

CHARACTERISTICS

Table 1 $T_{case} = 30 \, ^{\circ}C; Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 470 MHz	22.5	25	dB
SL	slope cable equivalent	f = 470 to 860 MHz	-0.2	+1	dB
FL	flatness of frequency response	f = 470 to 860 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 470 to 860 MHz	12	_	dB
S ₂₂	output return losses	f = 470 to 860 MHz	17	-	dB
Vo	output voltage	d _{im} = -60 dB; note 1	60.5	_	dBmV
		d _{im} = -60 dB; note 2	60.5		dBmV
F	noise figure	f = 470 MHz	-	8	dB
		f = 860 MHz	-	8.5	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	280	mA

Notes

- $\begin{array}{l} \text{1.} \quad f_p = 483.25 \text{ MHz; } V_p = V_o; \\ f_q = 490.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 492.25 \text{ MHz; } V_r = V_o 6 \text{dB;} \\ \text{measured at } f_p + f_q f_r = 481.25 \text{ MHz.} \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 851.25 \text{ MHz}; \, V_p = V_o; \\ & f_q = 858.25 \text{ MHz}; \, V_q = V_o 6 \text{ dB}; \\ & f_r = 860.25 \text{ MHz}; \, V_r = V_o 6 \text{ dB}; \\ & \text{measured at } f_p + f_q f_r = 849.25 \text{ MHz}. \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGX881

FEATURES

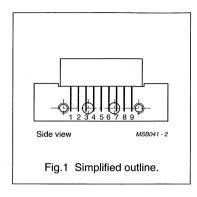
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115D

PIN	DESCRIPTION		
1	input; note1		
2	common		
3	common		
4	12 V, 60 mA supply terminal		
5	common		
6	common		
7	common		
8	+V _B		
9	output; note1		



Note

1. Pins 1 and 9 carry DC voltages.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	12	13	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	240	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	DC supply voltage	_	26	V
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGX881

CHARACTERISTICS

Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	13	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 MHz; note 1	20	_	dB
		f = 800 to 860 MHz	10	-	dB
S ₂₂	output return losses	f = 40 MHz; note 1	20	_	dB
		f = 640 to 860 MHz	15	-	dB
d ₂	second order distortion	note 2		-53	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 3	60.5	_	dBmV
		$d_{im} = -60 \text{ dB}$; note 4	59.5	_	dBmV
F	noise figure	f = 350 MHz	-	8.5	dB
		f = 860 MHz	_	9	dB
I _{tot}	total current consumption (DC)	note 5		240	mA

Notes

1. Decreases 1.5 dB per octave.

```
2. f_p = 349.25 \text{ MHz}; V_p = 59 \text{ dBmV};

f_q = 403.25 \text{ MHz}; V_q = 59 \text{ dBmV};

measured at f_p + f_q = 752.5 \text{ MHz}.
```

3. Measured according to DIN45004B:

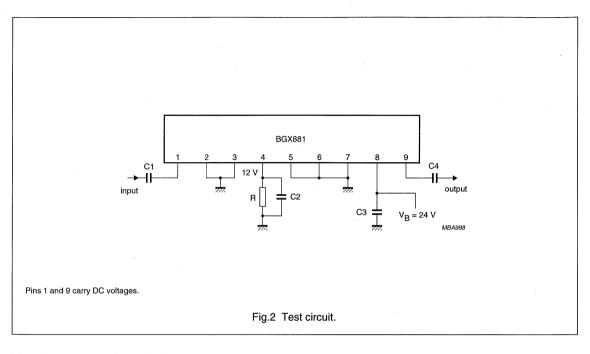
```
\begin{array}{l} f_p = 341.25 \text{ MHz; } V_p = V_o; \\ f_q = 348.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 350.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 339.25 \text{ MHz.} \end{array}
```

4. Measured according to DIN45004B:

```
\begin{array}{lll} f_p = 851.25 \text{ MHz; } V_p = V_o; \\ f_q = 858.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{array}
```

5. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGX881



List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1, C3, C4	ceramic multilayer capacitor	1 nF
C2	ceramic multilayer capacitor	1 nF (max.)
R	resistor	200 Ω, 1 W

BGX885N

FEATURES

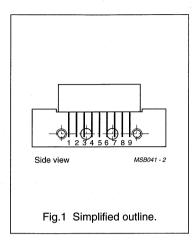
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115D

PIN	DESCRIPTION
1	input (note 1)
2	common
3	common
4	60 mA
	supply terminal
5	common
6	common
7	common
8	+V _B
9	output (note 1)



Note

1. Pins 1 and 9 carry DC voltages.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
		f = 750 MHz	17.3	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	240	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _B	DC supply voltage	_	26	V
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

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BGX885N

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
		f = 750 MHz	17.3	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.4	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 MHz; note 1	20	-	dB
		f = 800 to 860 MHz	10	_	dB
S ₂₂	output return losses	f = 40 MHz; note 1	20	-	dB
		f = 640 to 860 MHz	15	_	dB
d ₂	second order distortion	note 2	_	-53	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 3	61	_	dBmV
		$d_{im} = -60 \text{ dB}$; note 4	60	_	dBmV
F	noise figure	f = 50 MHz	_	7.5	dB
	· ·	f = 350 MHz	· · · · - · ·	7.5	dB
		f = 550 MHz	_	7.5	dB
		f = 650 MHz	-	7.5	dB
		f = 750 MHz	-	8	dB
		f = 860 MHz	-	8	dB
I _{tot}	total current consumption (DC)	note 5	-	240	mA

Notes

- 1. Decrease per octave of 1.5 dB.
- 2. $f_p = 349.25 \text{ MHz}$; $V_p = V_o = 59 \text{ dBmV}$; $f_a = 403.25 \text{ MHz}; V_a = V_o;$ measured at $f_p + f_q = 752.5$ MHz.
- 3. Measured according to DIN45004B:
 - $f_p = 341.25 \text{ MHz}; V_p = V_o;$ $f_q = 348.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 - $f_r = 350.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$

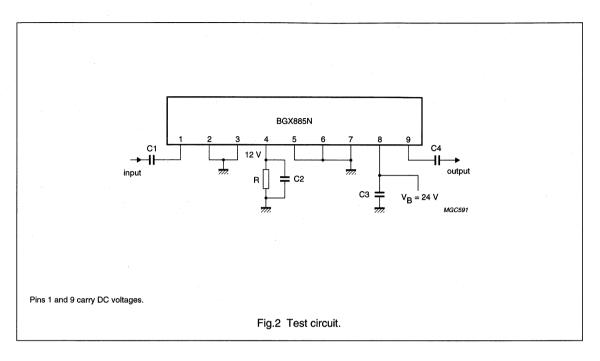
measured at $f_p + f_q - f_r = 339.25$ MHz.

- 4. Measured according to DIN45004B:
 - $f_p = 851.25 \text{ MHz}; V_p = V_o;$
 - $f_q = 858.25 \text{ MHz}; V_q = V_o 6 \text{ dB};$
 - $f_r = 860.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

5. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGX885N



List of components (see Fig.2)

COMPONENT DESCRIPTION		VALUE
C1, C3, C4	ceramic multilayer capacitor	1 nF (max.)
C2	ceramic multilayer capacitor	1 nF
R	resistor	200 Ω, 1 W

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BGY61

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

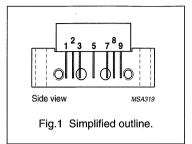
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 10 MHz	12.5	_	13.5	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	215	230	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+90	°C

BGY61

CHARACTERISTICS

Table 1 Bandwidth 5 to 200 MHz; $T_{mb} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 10 MHz	12.5	-	13.5	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2	_	+1	dB
FL	flatness of frequency response	f = 5 to 200 MHz	_	-	±0.2	dB
S ₁₁	input return losses	f = 5 to 200 MHz	20		_	dB
S ₂₂	output return losses	f = 5 to 200 MHz	20	_	_	dB
СТВ	composite triple beat	22 channels flat; V _o = 50 dBmV; measured at 175.25 MHz	-	_	-68	dB
X _{mod}	cross modulation	22 channels flat; V _o = 50 dBmV; measured at 55.25 MHz		<u></u>	–61	dB
d ₂	second order distortion	V _o = 50 dBmV; note 1	_	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	-	_	dBmV
		d _{im} = -60 dB; note 3	64	_	_	dBmV
F	noise figure	f = 200 MHz	_	-	7	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 4	_	215	230	mA

Notes

- 1. $f_p = 83.25 \text{ MHz}; V_p = 50 \text{ dBmV}; \\ f_q = 109.25 \text{ MHz}; V_q = 50 \text{ dBmV}; \\ \text{measured at } f_p + f_q = 192.5 \text{ MHz}.$
- 2. Measured according to DIN45004B;

$$f_p = 35.25 \text{ MHz}; V_o = V_p;$$

 $f_q = 42.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$
 $f_r = 44.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$
measured at $f_p + f_q - f_r = 33.25 \text{ MHz}.$

3. Measured according to DIN45004B;

```
\begin{split} f_p &= 187.25 \text{ MHz; } V_o = V_p; \\ f_q &= 194.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 196.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 185.25 \text{ MHz.} \end{split}
```

4. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY65

FEATURES

- · Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

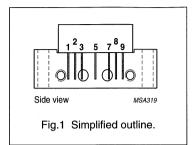
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
-8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 10 MHz	18	_	19	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	215	230	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+90	°C

BGY65

CHARACTERISTICS

Table 1 Bandwidth 5 to 200 MHz; $T_{mb} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 10 MHz	18	-	19	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2	_	+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 5 to 200 MHz	20	_		dB
S ₂₂	output return losses	f = 5 to 200 MHz	20	_	-	dB
СТВ	composite triple beat	22 channels flat; V _o = 50 dBmV; measured at 175.25 MHz	_	_	-68	dB
X _{mod}	cross modulation	22 channels flat; V _o = 50 dBmV; measured at 55.25 MHz		-	–61	dB
d ₂	second order distortion	V _o = 50 dBmV; note 1	_	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	_	-	dBmV
		d _{im} = -60 dB; note 3	64	_	_	dBmV
F	noise figure	f = 200 MHz	_	-	5.5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 4		215	230	mA

Notes

- 1. $f_p = 83.25$ MHz; $V_p = 50$ dBmV; $f_q = 109.25$ MHz; $V_q = 50$ dBmV; measured at $f_p + f_q = 192.5$ MHz.
- 2. Measured according to DIN45004B:
 - $$\begin{split} f_p &= 35.25 \text{ MHz; V}_o = V_p; \\ f_q &= 42.25 \text{ MHz; V}_q = V_o 6 \text{ dB;} \\ f_r &= 44.25 \text{ MHz; V}_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 33.25 \text{ MHz.} \end{split}$$
- 3. Measured according to DIN45004B:
 - $$\begin{split} f_p &= 187.25 \text{ MHz; } V_o = V_p; \\ f_q &= 194.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r &= 196.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 185.25 \text{ MHz.} \end{split}$$
- 4. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY66B

FEATURES

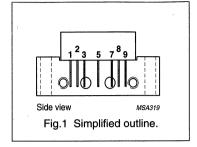
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

APPLICATIONS

 Intended as a reverse amplifier for use in two-way systems.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



DESCRIPTION

Hybrid high dynamic range amplifier module designed for applications in CATV systems with a bandwidth of 5 to 120 MHz operating with a voltage supply of 24 V (DC).

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 10 MHz	24.5	25.5	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	115	135	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY66B

CHARACTERISTICS

Table 1 Bandwidth 5 to 120 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 10 MHz	24.5	25.5	dB
SL	slope cable equivalent		-0.2	+0.5	dB
FL	flatness of frequency response		-	±0.2	dB
S ₁₁	input return losses		20	_	dB
S ₂₂	output return losses		20	_	dB
СТВ	composite triple beat	14 channels flat; V _o = 48 dBmV; measured at 67.25 MHz		-66	dB
X _{mod}	cross modulation	14 channels flat; V _o = 48 dBmV; measured at 67.25 MHz	-	-54	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60		dBmV
F	noise figure	f = 120 MHz	-	5	dB
I _{tot}	total current consumption (DC)	note 3	115	135	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 48$ dBmV; $f_q = 61.25$ MHz; $V_q = 48$ dBmV; measured at $f_p + f_q = 116.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 111.25 \text{ MHz; } V_p = V_o; \\ f_q &= 118.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 120.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 109.25 \text{ MHz.} \end{split}$$

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY67

FEATURES

- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

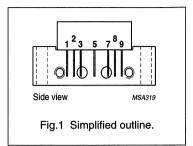
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 10 MHz	21.5	_	22.5	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	215	230	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+90	°C

BGY67

CHARACTERISTICS

Table 1 Bandwidth 5 to 200 MHz; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 10 MHz	21.5	_	22.5	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2	_	+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz	_	-	±0.2	dB
S ₁₁	input return losses	f = 5 to 200 MHz	20	_		dB
S ₂₂	output return losses	f = 5 to 200 MHz	20	_	_	dB
СТВ	composite triple beat	22 channels flat; V _o = 50 dBmV; measured at 175.25 MHz		_	-67	dB
X _{mod}	cross modulation	22 channels flat; V _o = 50 dBmV; measured at 55.25 MHz	_	_	-60	dB
d ₂	second order distortion	V _o = 50 dBmV; note 1	_	-	-67	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	_	-	dBmV
		d _{im} = -60 dB; note 3	64	-	-	dBmV
F	noise figure	f = 200 MHz	_	-	5.5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 4		215	230	mA

Notes

- 1. $f_p = 83.25$ MHz; $V_p = 50$ dBmV; $f_q = 109.25$ MHz; $V_q = 50$ dBmV; measured at $f_p + f_q = 192.5$ MHz.
- 2. Measured according to DIN45004B;

 $f_p = 35.25 \text{ MHz}; V_o = V_p;$ $f_q = 42.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$ $f_r = 44.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$

measured at $f_p + f_q - f_r = 33.25$ MHz.

3. Measured according to DIN45004B; $f_p = 187.25 \text{ MHz; } V_o = V_p; \\ f_q = 194.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 196.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 185.25 \text{ MHz.}$

4. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY67A

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

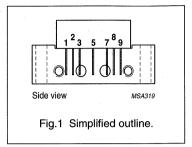
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 10 MHz	23.5	_	24.5	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	215	230	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+90	°C

BGY67A

CHARACTERISTICS

Table 1 Bandwidth 5 to 200 MHz; $T_{mb} = 30$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 10 MHz	23.5	_	24.5	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2	 	+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 5 to 200 MHz	20	- "	_	dB
S ₂₂	output return losses	f = 5 to 200 MHz	20	_	_	dB
СТВ	composite triple beat	22 channels flat; V _o = 50 dBmV; measured at 175.25 MHz	-	_	-67	dB
X _{mod}	cross modulation	22 channels flat; V _o = 50 dBmV; measured at 55.25 MHz	-	-	-59	dB
d ₂	second order distortion	V _o = 50 dBmV; note 1	- 7	-	-67	dB
Vo	output voltage	d _{im} = -60 dB; note 2	67	_	_	dBmV
		d _{im} = -60 dB; note 3	64	_	_	dBmV
F	noise figure	f = 200 MHz	_	_	5.5	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 4	_	215	230	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 83.25 \text{ MHz; } V_p = 50 \text{ dBmV;} \\ & f_q = 109.25 \text{ MHz; } V_q = 50 \text{ dBmV;} \\ & \text{measured at } f_p + f_q = 192.5 \text{ MHz.} \end{array}$
- 2. Measured according to DIN45004B;

 $f_p = 35.25 \text{ MHz}; V_o = V_p;$ $f_q = 42.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 44.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 33.25$ MHz.

3. Measured according to DIN45004B;

 $f_p = 187.25 \text{ MHz}; V_o = V_p;$

 $f_q = 194.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 196.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 185.25$ MHz.

4. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

Optical receiver module

BGY67BO

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Excellent flatness
- · Standard CATV outline
- Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

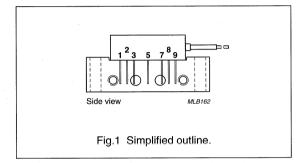
 Reverse receiver amplifier in two-way CATV systems in the 5 to 300 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range optical amplifier module in a SOT115M package operating at a voltage supply of +24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor the pin diode current and an electrical output with an impedance of 75 Ω .

PINNING - SOT115M

PIN	DESCRIPTION
1	monitor current
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		5	300	MHz
S ₂₂	output return losses	f = 5 to 300 MHz	13	-	dB
	optical input return losses		40	_	dB
d ₂	second order distortion			-70	dBc
F	equivalent noise input	f = 10 to 300 MHz	-	7	pA/√Hz
I _{tot}	total current consumption (DC)	V _B = 24 V	150	180	mA

HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

CAUTION

The device is supplied in an antistatic package and must be protected against static discharge during transport or handling.

Optical receiver module

BGY67BO

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		5	300	MHz
T _{stg}	storage temperature		-40	+85	°C
T _{mb}	operating mounting base temperature		-20	+85	°C
P _{in}	optical input power	continuous	-	5	mW
ESD	ESD sensitivity	human body model; R = 1.5 k Ω ; C = 100 pF	500	_	V

CHARACTERISTICS

Table 1 Bandwidth 5 to 300 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
S	responsivity	λ = 1300 nm	800	_	V/W
FL	flatness of frequency response		_	±0.3	dB
S ₂₂	output return losses	f = 5 to 300 MHz	15	_	dB
	optical input return losses		40		dB
d_2	second order distortion	note 1	_	-70	dB
d_3	third order distortion	note 2	_	-80	dB
F	equivalent noise input	f ₁ = 50 to 300 MHz	-	7	pA/√Hz
s_{λ}	spectral sensitivity	λ = 1310 ±20 nm	0.85		A/W
		$\lambda = 1350 \pm 20 \text{ nm}$	0.9		A/W
λ	optical wavelength		1290	1600	nm
L	length of optical fibre	fibre; SM type; 9/125 μm	1	_	m
I _{tot}	total current consumption (DC)	note 3	150	180	mA

Notes

1. Two laser test; each laser with 40% modulation index;

 $f_p = 20.25 \text{ MHz}; P_p = 0.5 \text{ mW}; f_q = 34 \text{ MHz}; P_q = 0.5 \text{ mW};$

measured at $f_p + f_q = 54.25$ MHz.

Three laser test; each laser with 40% modulation index;

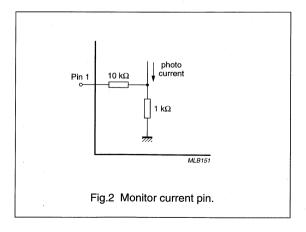
 $f_p = 125.25 \text{ MHz}; P_p = 0.33 \text{ mW};$

 $f_q = 110.25 \text{ MHz}; P_q = 0.33 \text{ mW};$

 $f_r = 135.25 \text{ MHz}; P_r = 0.33 \text{ mW};$

measured at $f_p + f_q + f_r = 100.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.



BGY68

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

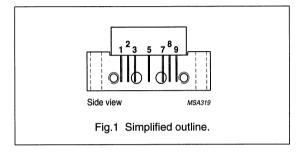
Reverse amplifier in two-way CATV systems in the 5 to 75 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range amplifier module in a SOT115J package operating at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 10 MHz	29.2	30.8	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	135	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY68

CHARACTERISTICS

Table 1 Bandwidth 5 to 75 MHz; $V_B = +24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 10 MHz	29.2	30.8	dB
SL	slope cable equivalent	f = 5 to 75 MHz	-0.2	+0.5	dB
FL	flatness of frequency response	f = 5 to 75 MHz	_	±0.2	dB
S ₁₁	input return losses	f = 5 to 75 MHz	20		dB
S ₂₂	output return losses	f = 5 to 50 MHz	20	-	dB
		f = 50 to 75 MHz	18	-	dB
СТВ	composite triple beat	4 channels flat; V _o = 50 dBmV; measured at 25 MHz		-68	dB
X _{mod}	cross modulation	4 channels flat; V _o = 50 dBmV; measured at 25 MHz	-	-60	dB
d_2	second order distortion	note 1		-70	dB
F	noise figure	f = 75 MHz	_	3.5	dB
I _{tot}	total current consumption (DC)	note 2		135	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 19 \text{ MHz}; \ V_p = 50 \ dBmV; \\ & f_q = 31 \text{ MHz}; \ V_q = 50 \ dBmV; \\ & \text{measured at } f_p + f_q = 50 \text{ MHz}. \end{array}$
- 2. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY80; BGY81

FEATURES

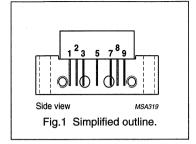
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of (DC). The BGY80 is intended for use as a 12.5 dB pre-amplifier and the BGY81 as a 12.5 dB final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	_	13	dB
	- 1	f = 450 MHz	12.5	_	14	dB
I _{tot}	total current consumption (DC)	V _B = 24 V				
	BGY80		_	180	200	mA ·
	BGY81			220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY80; **BGY81**

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	12		13	dB
		f = 450 MHz	12.5		14	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	_	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-, '	_	dB
		f = 160 to 450 MHz	18		_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	_	dB
e .		f = 80 to 160 MHz	19	_	_	dB
1		f = 160 to 450 MHz	18	_	-	dB
S ₂₁	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat BGY80 BGY81	60 channels flat; V_o = 46 dBmV; measured at 445.25 MHz		_	-54 -58	dB dB
X _{mod}	cross modulation BGY80 BGY81	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	_	-59 -62	dB dB
CSO	composite second order distortion BGY80 BGY81	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz			-58 -61	dB dB
d ₂	second order distortion BGY80 BGY81	note 1		_	-72 -74	dB dB
Vo	output voltage BGY80 BGY81	d _{im} = -60 dB; note 2	61.5 64	_		dBmV dBmV
F	noise figure BGY80 BGY81	f = 450 MHz	; 		7.5 8	dB dB
l _{tot}	total current consumption (DC) BGY80 BGY81	note 3	- -	180 220	200 240	mA mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 391.25 \text{ MHz}$; $V_q = 46 \text{ dBmV}$; measured at $f_p + f_q = 446.5 \text{ MHz}$.
- 2. Measured according to DIN45004B: f_p = 440.25 MHz; V_p = V_o ; f_q = 447.25 MHz; V_q = V_o –6 dB; f_r = 449.25 MHz; V_r = V_o –6 dB; measured at f_p + f_q f_r = 438.25 MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

BGY82; BGY83

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

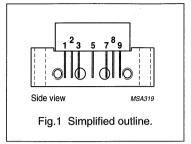
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 450 MHz	14.5	_	-	dB
I _{tot}	total current consumption (DC)	DC value; V _B = +24 V				
	BGY82		-	180	200	mA
	BGY83			220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{case}	mounting base operating temperature	-20	+100	°C

BGY82; BGY83

CATV amplifier modules

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 450 MHz	14.5	-	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB ₁
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	_ ' '	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_ "	_	dB
СТВ	composite triple beat	60 channels flat; $V_0 = 46 \text{ dBmV}$;				
	BGY82	measured at 445.25 MHz	-	-	-55	dB
	BGY83		_	_	-59	dB
X _{mod}	cross modulation	60 channels flat; $V_0 = 46 \text{ dBmV}$;				
	BGY82	measured at 55.25 MHz	-	_	-56	dB .
	BGY83		_	_	-59	dB
cso	composite second order distortion					
	BGY82	measured at 446.25 MHz	<u></u>		-55	dB
	BGY83		_		-59	dB
d ₂	second order distortion	note 1	-	1.		
	BGY82		ļ-	-	-72	dB
	BGY83		_	_	-74	dB
Vo	output voltage	d _{im} = -60 dB; note 2				
	BGY82		61.5	- ,	-	dBmV
	BGY83	:	64	_	_	dBmV
F	noise figure	f = 450 MHz				
	BGY82		_	-"	7	dB
	BGY83			-	8	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3				
	BGY82		_	180	200	mA
	BGY83			220	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B;

 $f_p=440.25$ MHz; $V_p=V_o;$ $f_q=447.25$ MHz; $V_q=V_o$ –6 dB; $f_r=449.25$ MHz; $V_r=V_o$ –6 dB; measured at $f_p+f_q-f_r=438.25$ MHz.

3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY84; BGY85

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

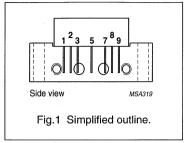
DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC). is intended for use as an input amplifier module and BGY85 as an output amplifier module.

PINNING - SOT115J

PIN	DESCRIPTION
. 1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	_	17.5	dB
		f = 450 MHz	17.3	_	18.8	dB
I _{tot}	total current consumption (DC)	V _B = +24 V				
	BGY82		-	180	200	mA
	BGY83		-	220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY84; BGY85

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	_	17.5	dB
		f = 450 MHz	17.3	_	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	-	dB
•		f = 160 to 450 MHz	18	_	- "	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV;				
	BGY84	measured at 445.25 MHz	_	_	-55	dB
	BGY85		_	_	-58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV;				
	BGY84	measured at 55.25 MHz			-57	dB
	BGY85		_ `		-60	dB
d ₂	second order distortion	note 1	_	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2				
	BGY84		60	<u>-</u>	_	dBmV
	BGY85		62.5	- '		dBmV
F	noise figure	f = 450 MHz				
	BGY84		_	_	6.5	dB
	BGY85		_		7	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3				
	BGY84		_	180	200	mA
	BGY85			220	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 343.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 398.5$ MHz.
- 2. Measured according to DIN45004B;

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$

 $f_q = 447.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY84A; BGY85A

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

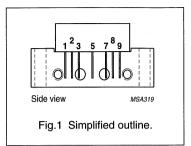
DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC). BGY84A is intended for use as an input amplifier module and BGY85A as an output amplifier module.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	_	18.8	dB
•		f = 450 MHz	18.7	-	20.2	dB
I _{tot}	total current consumption (DC)	V _B = +24 V				
	BGY84A		_	180	200	mA
	BGY85A		-	220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY84A; BGY85A

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18		18.8	dB
		f = 450 MHz	18.7	_	20.2	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.3		1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz		_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 450 MHz	18		- 1000	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20			dB
* * * * * * * * * * * * * * * * * * *		f = 80 to 160 MHz	19	-		dB
		f = 160 to 450 MHz	18	_	_	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV;				
	BGY84A	measured at 445.25 MHz	_	4 .	-55	dB
	BGY85A			- ' '	-59	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV;				
	BGY84A	measured at 55.25 MHz	_	_	-58	dB
	BGY85A	44.			-61	dB
d ₂	second order distortion	note 1	_	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2		-		
	BGY84A		60	-	_	dBmV
	BGY85A		62.5	- 1 1		dBmV
F	noise figure	f = 40 to 450 MHz				
	BGY84A		-	_	6.5	dB
	BGY85A		_		7	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3				
	BGY84A		_	180	200	mA
	BGY85A		<u>-</u>	220	240	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 343.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at $f_p + f_q = 398.5 \text{ MHz}$.
- 2. Measured according to DIN45004B;

 - $$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \end{split}$$
 - $f_r = 449.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
 - measured at $f_p + f_q f_r = 438.25$ MHz.
- 3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY86; **BGY87**

FEATURES

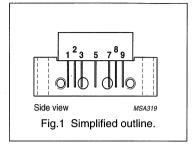
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC). The BGY86 is intended for use as a pre-amplifier and BGY87 as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	-	22.5	dB
:		f = 450 MHz	21.7	_	23.5	dB .
I _{tot}	total current consumption (DC)	V _B = 24 V				
	BGY86			180	200	mA
	BGY87			220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY86; **BGY87**

CHARACTERISTICS

Bandwidth 40 to 450 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	-	22.5	dB
		f = 450 MHz	21.7	-	23.5	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	_	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-		±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
*		f = 160 to 450 MHz	18	_	_	dB
S ₂₁	phase response	f = 50 MHz	+135	_	+225	deg
СТВ	composite triple beat BGY86 BGY87	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	_	-54 -58	dB dB
X _{mod}	cross modulation BGY86 BGY87	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz		_	-51 -55	dB dB
CSO	composite second order distortion BGY86 BGY87	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	- -		-53 -57	dB dB
d ₂	second order distortion BGY86 BGY87	note 1		_	-68 -72	dB dB
Vo	output voltage BGY86 BGY87	d _{im} = -60 dB; note 2	61.5 64	-	_	dBmV dBmV
F	noise figure BGY86 BGY87	f = 450 MHz	-		6 6.5	dB dB
l _{tot}	total current consumption (DC) BGY86 BGY87	note 3		180 220	200 240	mA mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 391.25 \text{ MHz}$; $V_q = 46 \text{ dBmV}$; measured at $f_p + f_q = 446.5 \text{ MHz}$.
- 2. Measured according to DIN45004B: f_p = 440.25 MHz; V_p = V_o ; f_q = 447.25 MHz; V_q = V_o -6 dB; f_r = 449.25 MHz; V_r = V_o -6 dB; measured at f_p + f_q f_r = 438.25 MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

BGY87B

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

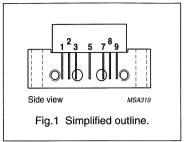
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
I _{tot}	total current consumption (DC)	V _B = +24 V; note 1	_	340	mA

Note

1. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY87B

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; T_{case} = 35 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	26.2	27.8	dB
		f = 450 MHz	27.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	_	20	dB
		f = 80 to 160 MHz	-	19	dB
		f = 160 to 450 MHz	-	18	dB
S ₂₂	output return losses	f = 40 to 80 MHz	_	20	dB
	· ·	f = 80 to 160 MHz	_	19	dB
	·	f = 160 to 450 MHz	_	18	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-58	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	-60	dB
d ₂	second order beat	V _o = 46 dBmV; note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	dBmV
F	noise figure	f = 450 MHz	_	6	dB
I _{tot}	total current consumption	DC value; V _B = +24 V	_	340	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B; $f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.}$

BGY88

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

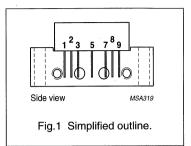
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V and intended for use as a line-extender.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5		35.5	dB
		f = 450 MHz	35	_	37	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	320	340	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY88

CHARACTERISTICS

Table 1 Bandwidth 40 to 450 MHz; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	33.5		35.5	dB
		f = 450 MHz	35	- "	37	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-		±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	- "	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19		-	dB
		f = 160 to 450 MHz	18		_	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-		-58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	- , ,	_	-59	dB
d ₂	second order distortion	note 1	_		-70	dB
Vo	output voltage	d _{im} = -60 dB note 2	62	-		dBmV
F	noise figure	f = 450 MHz	-	_	6	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	320	340	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 343.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 398.5$ MHz.
- 2. Measured according to DIN45004B; $f_p=440.25~\text{MHz};~V_p=V_o=62~\text{dBmV};\\ f_q=447.25~\text{MHz};~V_q=V_o-6~\text{dB};\\ f_r=449.25~\text{MHz};~V_r=V_o-6~\text{dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY89

FEATURES

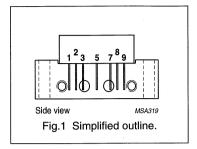
- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC). The module is intended for use as a line-extender.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	37	_	39	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	320	340	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY89

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	37		39	dB
		f = 450 MHz	37	-	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	-	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz		-	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18		-,	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19		- '	dB
		f = 160 to 450 MHz	18	_	_	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	_	-58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-	_	-58	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	-	_	-58	dB
d ₂	second order distortion	note 1	-	-	-70	dB
Vo	output voltage	d _{im} = −60 dB; note 2	63	_ %		dBmV
F	noise figure	f = 450 MHz	_	-	5.5	dB
I _{tot}	total current consumption (DC)	note 3	-	320	340	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 343.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 398.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o = 63 \text{ dBmV};$

 $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY580; BGY581

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

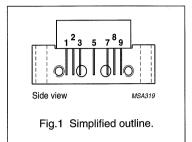
DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC). The BGY580 is intended for use as a pre-amplifier and BGY581 as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
. 8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	_	13	dB
·		f = 550 MHz	12.5	_	14.5	dB
I _{tot}	total current consumption (DC)	V _B = +24 V				
	BGY580		_	180	200	mA
	BGY581		_	220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{case}	case operating temperature	-20	+100	°C

BGY580; BGY581

CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 30^{\circ}C$; $Z_S = Z_L = 75\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	_	13	dB
		f = 550 MHz	12.5	_	14.5	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	_	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_		dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 550 MHz	18	_	_	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV;				
,	BGY580	measured at 547.25 MHz	-	-	-52	dB
	BGY581		-	-	-56	dB
X_{mod}	cross modulation	77 channels flat; V _o = 44 dBmV;			-	
	BGY580	measured at 55.25 MHz	-	-	-59	dB
	BGY581			_	-62	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV;				
	BGY580	measured at 548.5 MHz	-	-	-56	dB
	BGY581		_	_	-59	dB
d_2	second order distortion	note 1				
	BGY580		-	-	-70	dB
	BGY581		_	_	-72	dB
V_o	output voltage	d _{im} = -60 dB; note 2				
	BGY580		59	_	-	dBmV
	BGY581		61.5	_	_	dBmV
F	noise figure	f = 550 MHz				
	BGY580		-	-	8.5	dB
	BGY581		_	-	9	dB
I_{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3				
	BGY580		_	180	200	mA
,	BGY581		_	220	240	mA

Notes

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 493.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 548.5 MHz.
- 2. Measured according to DIN45004B; $f_p = 540.25 \text{ MHz; } V_p = V_o; f_q = 547.25 \text{ MHz; } V_q = V_p 6 \text{ dB; } f_r = 549.25 \text{ MHz; } V_r = V_p 6 \text{ dB; } measured \text{ at } f_p + f_q f_r = 538.25 \text{ MHz.}$
- 3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY582; BGY583

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

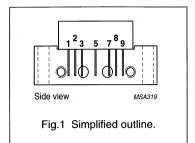
DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 550 MHz	14.5	-	_	dB
I _{tot}	total current consumption (DC)	V _B = +24 V				
	BGY582		-	180	200	mA
	BGY583			220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY582; BGY583

CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 30 \, ^{\circ}C$; $Z_{S} = Z_{L} = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	_	14.5	dB
		f = 550 MHz	14.5	_	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	-	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
'		f = 160 to 550 MHz	18	_	_	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV;				
	BGY582	measured at 547.25 MHz		_	-55	dB
	BGY583		-		-59	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV;				
	BGY582	measured at 55.25 MHz	_	_	-58	dB
	BGY583		_	_	-61	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV;				
	BGY582	measured at 548.5 MHz	-	_	-55	dB
,	BGY583		_		-59	dB
d ₂	second order distortion	note 1				
	BGY582		_	_	-70	dB
	BGY583		- 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2				
	BGY582		59	_	-	dBmV
	BGY583		61.5	_	_	dBmV
F	noise figure	f = 550 MHz				
	BGY582				7.5	dB
	BGY583		_	- ,	8.5	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3				7 .
,	BGY582		_ ,	180	200	mΑ
	BGY583		_	220	240	mA

- 1. $f_p=55.25$ MHz; $V_p=44$ dBmV; $f_q=493.25$ MHz; $V_q=44$ dBmV; measured at $f_p+f_q=548.5$ MHz.
- 2. Measured according to DIN45004B; $f_p=440.25 \text{ MHz; } V_p=V_o; f_q=447.25 \text{ MHz; } V_q=V_p-6 \text{ dB;} \\ f_r=449.25 \text{ MHz; } V_r=V_p-6 \text{ dB;} \\ \text{measured at } f_p+f_q-f_r=438.25 \text{ MHz.} \\ \end{cases}$
- 3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY584; BGY585

FEATURES

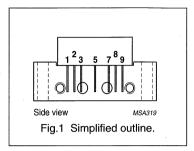
- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC). The BGY584 is intended for use as a pre-amplifier and BGY585 as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V _B		
7	common		
8	common		
9	output		



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5		17.5	dB
·		f = 550 MHz	17.6	-	19	dB
I _{tot}	total current consumption (DC)	V _B = 24 V				
	BGY584		-	180	200	mA
	BGY585		_	220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY584; BGY585

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	- "	17.5	dB
		f = 550 MHz	17.6	_	19	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	r	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		- ,	dB
.*		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	1.8	-	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	_		dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat BGY584 BGY585	77 channels flat; V_o = 44 dBmV; measured at 547.25 MHz	- -	_	-56 -59	dB dB
X _{mod}	cross modulation BGY584 BGY585	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_		-59 -62	dB dB
CSO	composite second order distortion BGY584 BGY585	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_ _	_ , , ,	-56 -59	dB dB
d ₂	second order distortion BGY584 BGY585	note 1	_	_	-68 -70	dB dB
Vo	output voltage BGY584 BGY585	d _{im} = -60 dB; note 2	58.5 61	_	-	dBmV dBmV
F	noise figure BGY584 BGY585	f = 550 MHz	-	_	7 8	dB dB
I _{tot}	total current consumption (DC) BGY584 BGY585	note 3	_	180 220	200 240	mA mA

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 493.25 \text{ MHz}$; $V_q = 44 \text{ dBmV}$; measured at $f_p + f_q = 548.5 \text{ MHz}$.
- 2. Measured according to DIN45004B: f_p = 540.25 MHz; V_p = V_o ; f_q = 547.25 MHz; V_q = V_o -6 dB; f_r = 549.25 MHz; V_r = V_o -6 dB; measured at f_p + f_q f_r = 538.25 MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

BGY584; BGY585

CHARACTERISTICS

Bandwidth 40 to 450 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	-	17.5	dB
•		f = 450 MHz	17.4	_	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
	\$	f = 160 to 450 MHz	18	-	-	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat BGY584 BGY585	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	- · .	_	-58 -61	dB dB
X _{mod}	cross modulation BGY584 BGY585	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	 - -		-57 -60	dB dB
CSO	composite second order distortion BGY584 BGY585	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	-	_	-58 -61	dB dB
d ₂	second order distortion BGY584 BGY585	note 1	-	_	-73 -75	dB dB
Vo	output voltage BGY584 BGY585	d _{im} = -60 dB; note 2	61.5 64	_	_	dBmV dBmV
F	noise figure BGY584 BGY585	f = 450 MHz	_	-	6	dB dB
l _{tot}	total current consumption (DC) BGY584 BGY585	note 3		180 220	200 240	mA mA

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 391.25 \text{ MHz}$; $V_q = 46 \text{ dBmV}$; measured at $f_p + f_q = 446.5 \text{ MHz}$.
- 2. Measured according to DIN45004B: f_p = 440.25 MHz; V_p = V_o ; f_q = 447.25 MHz; V_q = V_o –6 dB; f_r = 449.25 MHz; V_r = V_o –6 dB; measured at f_p + f_q f_r = 438.25 MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

BGY584A; BGY585A

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

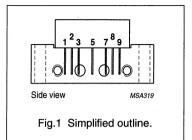
DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC). The BGY584A is intended for use as a pre-amplifier and BGY585A as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.7	-	18.7	dB
		f = 550 MHz	18.8	_	20	dB
I _{tot}	total current consumption (DC)	V _B = +24 V				
	BGY584A			180	200	mA
	BGY585A			220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT	
Vi	RF input voltage	-	65	dBmV	
T _{stg}	storage temperature	-40	+100	°C	
T _{case}	case operating temperature	-20	+100	°C	

BGY584A; BGY585A

CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.7	_	18.7	dB
		f = 550 MHz	18.8	_	20	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	_	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	-	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		- "	dB
•		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	_	_	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV;				
	BGY584A	measured at 547.25 MHz	_	-	-56	dB
	BGY585A		_	_	-59	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV;				
	BGY584A	measured at 55.25 MHz		-	-59	dB
·	BGY585A		_	_	-62	dB
CSO	composite second order distortion	77 channels flat; $V_0 = 44 \text{ dBmV}$;				
	BGY584A	measured at 548.5 MHz	-	-	-55	dB
	BGY585A		_		-59	dB
d_2	second order distortion	note 1			ļ	
	BGY584A		-	-	-70 ·	dB
	BGY585A		_	_	-72	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2				
	BGY584A		59	-	-	dBmV
	BGY585A		61.5	_	_	dBmV
F	noise figure	f = 550 MHz				
	BGY584A		_	_	7	dB
	BGY585A				8	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3				
	BGY584A		-	180	200	mA
	BGY585A		-	220	240	mA

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 493.25 \text{ MHz}$; $V_q = 44 \text{ dBmV}$; measured at $f_p + f_q = 548.5 \text{ MHz}$.
- 2. Measured according to DIN45004B; f_p = 540.25 MHz; V_p = V_o ; f_q = 547.25 MHz; V_q = V_p -6 dB; f_r = 549.25 MHz; V_r = V_p -6 dB; measured at f_p + f_q f_r = 538.25 MHz.
- 3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY584A; BGY585A

Table 2 Bandwidth 40 to 450 MHz; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.7	_	18.7	dB
		f = 450 MHz	18.6	_ 1	19.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_		±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 450 MHz	18	- 1		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 450 MHz	18	_		dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV;				
	BGY584A	measured at 445.25 MHz	-	-	-57	dB
	BGY585A		-	-	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV;				-
	BGY584A	measured at 55.25 MHz		-	-58	dB
	BGY585A		-	-	-61	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV;				
	BGY584A	measured at 446.5 MHz	_	_	-58	dB
	BGY585A		_	-	-61	dB
d_2	second order distortion	note 1				
	BGY584A		_	-	-73	dB
	BGY585A		_		-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2				
	BGY584A		61.5			dBmV
,	BGY585A		64	_	-	dBmV
F	noise figure	f = 450 MHz				
	BGY584A			_	6	dB
	BGY585A		- "	- '	7	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3				
	BGY584A		_	180	200	mA
	BGY585A			220	240	mA

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B;
 - $f_p = 440.25 \text{ MHz}; V_p = V_o;$
 - $f_q = 447.25 \text{ MHz}; V_q = V_p 6 \text{ dB};$
 - $f_r = 449.25 \text{ MHz}$; $V_r = V_p 6 \text{ dB}$; measured at $f_p + f_q f_r = 438.25 \text{ MHz}$.
- 3. The modules normally operate at $V_B = +24 \text{ V}$, but are able to withstand supply transients up to +30 V.

BGY586; BGY587

FEATURES

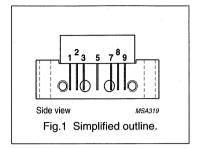
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC). The BGY586 is intended for use as a pre-amplifier and BGY587 as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V _B		
7	common		
8	common		
9	output		



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	_	22.5	dB
		f = 550 MHz	22	-	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V				
	BGY586		_	180	200	mA
	BGY587		_	220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY586; BGY587

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	-	22.5	dB
		f = 550 MHz	22	-	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	-	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_		dB
		f = 80 to 160 MHz	19		-	dB
		f = 160 to 550 MHz	18	_		dB
S ₂₁	phase response	f = 50 MHz	+135	-	+225	deg
СТВ	composite triple beat BGY586 BGY587	77 channels flat; V_o = 44 dBmV; measured at 547.25 MHz		-	-53 -57	dB dB
X _{mod}	cross modulation BGY586	77 channels flat; V ₀ = 44 dBmV;				
	BGY587	measured at 55.25 MHz		_	-55 -58	dB dB
cso	composite second order distortion BGY586 BGY587	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_		-50 -54	dB dB
d ₂	second order distortion BGY586 BGY587	note 1	_	_	-62 -66	dB dB
Vo	output voltage BGY586 BGY587	d _{im} = -60 dB; note 2	58.5 61	_	_	dBmV dBmV
F	noise figure BGY586 BGY587	f = 550 MHz	_		6.5 7	dB dB
I _{tot}	total current consumption (DC) BGY586 BGY587	note 3	-	180 220	200 240	mA mA

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B: $f_p = 540.25$ MHz; $V_p = V_o$; $f_q = 547.25$ MHz; $V_q = V_o 6$ dB; $f_r = 549.25$ MHz; $V_r = V_o 6$ dB; measured at $f_p + f_q f_r = 538.25$ MHz.
- 3. The modules normally operate at $V_B = 24 \text{ V}$, but are able to withstand supply transients up to 30 V.

BGY587B

FEATURES

- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

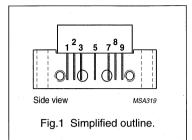
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5	_	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	_	340	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C
V _B	DC supply voltage	-	+28	V

BGY587B

CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5		dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	_	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-57	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-60	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz		–57	dB
d_2	second order distortion	note 1		-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 550 MHz	_	6.5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	_	340	mA

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B; $f_p = 540.25 \text{ MHz}$; $V_p = V_o = 66.5 \text{ dBmV}$; $f_q = 547.25 \text{ MHz}$; $V_q = V_o 6 \text{ dB}$; $f_r = 549.25 \text{ MHz}$; $V_r = V_o 6 \text{ dB}$; measured at $f_p + f_q f_r = 538.25 \text{ MHz}$.
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY588

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

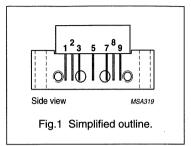
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC) and intended for use as a line-extender.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	_	35.5	dB
		f = 550 MHz	35	-	37	dB
I _{tot}	total current consumption (DC)	V _B = +24 V	-	320	340	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY588

CHARACTERISTICS

Table 1 Bandwidth 40 to 550 MHz; $T_{case} = 30$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5		35.5	dB
1		f = 550 MHz	35	_	37	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0		2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz		-	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18	_	-	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	_	-57	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-	-59	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-	−57	dB
d ₂	second order distortion	note 1	_	_	-68	dB
Vo	output voltage	d _{im} = −60 dB; note 2	61	-	_	dBmV
F	noise figure	f = 550 MHz	_	-	6.5	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	320	340	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B;

 $f_p = 540.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV};$

 $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGY588

Table 2 Bandwidth 40 to 450 MHz; $T_{case} = 35$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	-	35.5	dB
		f = 450 MHz	35	-	37	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	-	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	_	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-	-59	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	-	-59	dB
d_2	second order distortion	note 1	-	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	_	dBmV
F	noise figure	f = 450 MHz	_	-	6	В
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	320	340	mA

- 1. f_p = 55.25 MHz; V_p = 46 dBmV; f_q = 391.25 MHz; V_q = 46 dBmV; measured at f_p + f_q = 446.5 MHz.
- 2. Measured according to DIN45004B; $f_p = 440.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV}; f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB}; f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB}; measured at <math>f_p + f_q f_r = 438.25 \text{ MHz}.$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY681

FEATURES

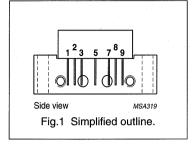
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 600 MHz operating with a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	13	dB
		f = 600 MHz	12.7	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	240	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY681

CHARACTERISTICS

Bandwidth 40 to 600 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	-	13	dB
		f = 600 MHz	12.7	-	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.7		2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 600 MHz	18	-	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 600 MHz	18	-	-	dB
S ₂₁	phase response	f = 50 MHz	-45		+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	_	-52	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-	-58	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-	-57	dB
d ₂	second order distortion	note 1	_		-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59.5	-	-	dBmV
F	noise figure	f = 600 MHz	-	-	9.5	dB
I _{tot}	total current consumption (DC)	note 3	_	220	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 590.25 \text{ MHz}; V_p = V_o;$

 $f_q = 597.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 588.25$ MHz.

BGY681

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	-	13	dB
		f = 550 MHz	12.5	_	14.5	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	_	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	- 1	dB
		f = 80 to 160 MHz	19	_	_	dB
-		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	-	_	dB
S ₂₁	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	_	-56	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	_	-62	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-	-59	dB
d ₂	second order distortion	note 1	_		-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61.5	_	-	dBmV
F	noise figure	f = 550 MHz	_	_	9	dB
I _{tot}	total current consumption (DC)	note 3	-	220	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

 $\begin{aligned} &f_p = 540.25 \text{ MHz; } V_p = V_o; \\ &f_q = 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ &f_r = 549.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ &\text{measured at } f_p + f_q - f_r = 538.25 \text{ MHz.} \end{aligned}$

BGY681

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	ļ-	13	dB
	e de la companya de	f = 450 MHz	12.5	-	14	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-,	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_		dB
· ·		f = 80 to 160 MHz	19	-	_	dB
٠.		f = 160 to 450 MHz	18	_	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	_	dB
S ₂₁	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-	-58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-	-62	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_		-61	dB
d ₂	second order distortion	note 1	-	-	-74	dB
Vo	output voltage	d _{im} = −60 dB; note 2	64	-	-	dBmV
F	noise figure	f = 450 MHz	_	-	8	dB
I _{tot}	total current consumption (DC)	note 3	_	220	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

$$f_p = 440.25 \text{ MHz}; V_p = V_o;$$

$$f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$$

$$f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGY683

FEATURES

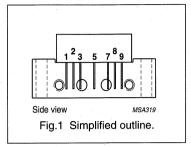
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	14.5	dB
		f = 600 MHz	14.5		dB
I _{tot}	total current consumption (DC)	V _B = 24 V		240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY683

CHARACTERISTICS

Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	14.5	dB
-		f = 600 MHz	14.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	1.7	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	-55	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-59	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-57	dB
d ₂	second order distortion	note 1	_	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	58		dBmV
F	noise figure	f = 600 MHz	_	9	dB
I _{tot}	total current consumption (DC)	note 3	_	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

BGY683

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{case} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 550 MHz	14.5	_	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	_	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	- : .		±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 550 MHz	18		_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-		dB
		f = 160 to 550 MHz	18	-	-	dB
S ₂₁	phase response	f = 50 MHz	-45		+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	_	-59	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	<u>.</u>	-61	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	-	_	-59	dB
d ₂	second order distortion	note 1	-	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61.5	_	-	dBmV
F	noise figure	f = 550 MHz	_	_	8.5	dB
I _{tot}	total current consumption (DC)	note 3		200	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{split}$$

BGY683

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	-	17.5	dB
		f = 450 MHz	17.4	_	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_		dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
,		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	_	-	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz		_	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz		_	-60	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	_	-61	dB
d ₂	second order distortion	note 1	_	-	-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	_	dBmV
F	noise figure	f = 450 MHz		_	7	dB
I _{tot}	total current consumption (DC)	note 3	_	200	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGY685

FEATURES

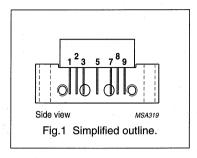
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module designed for applications in CATV systems operating over a frequency range of 40 to 600 MHz operating with a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	16.5	17.5	dB
		f = 600 MHz	17.8	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY685

CHARACTERISTICS

Table 1 Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
		f = 600 MHz	17.8	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.5	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 600 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-55	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-60	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	-	-56	dB
d ₂	second order distortion	note 1	-	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60	-	dBmV
F	noise figure	f = 600 MHz	_	8.5	dB
I _{tot}	total current consumption (DC)	note 3	_	240	mA

- $\begin{array}{ll} \text{1.} & \text{f}_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ & \text{f}_q = 541.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ & \text{measured at f}_p + \text{f}_q = 596.5 \text{ MHz.} \end{array}$
- 2. Measured according to DIN45004B:
 - $f_p = 590.25 \text{ MHz}; V_p = V_o;$
 - $f_q = 597.25 \text{ MHz}; V_q = V_o 6 \text{ dB};$
 - $f_r = 599.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
 - measured at $f_p + f_q f_r = 588.25$ MHz.
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY685

Table 2 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	16.5	-	17.5	dB
	·	f = 550 MHz	17.6	_	19	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz		-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_		dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	_		dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	_	-59	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	_	-62	dB
CSO	composite second order distortion	77 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 548.5 MHz	_	_	-59	dB
d_2	second order distortion	note 1	-	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	- 1	- 1	dBmV
F	noise figure	f = 550 MHz	-		8	dB
I _{tot}	total current consumption (DC)	note 3	-	220	240	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:

$$t_p = 540.25 \text{ MHz}; V_p = V_o;$$

$$\begin{split} f_p &= 540.25 \text{ MHz; } V_p = V_o; \\ f_q &= 547.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

$$f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGY685

Table 3 Bandwidth 40 to 450 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	- 4, 1	17.5	dB
		f = 450 MHz	17.4	- 1	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	- 1	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	- :	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	-".	dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 450 MHz	18	_	- , -	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 450 MHz	18			dB
S ₂₁	phase response	f = 50 MHz	-45	**	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-	-	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	= 1		-60	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	-	-61	dB
d_2	second order distortion	note 1	-	-	-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	-		dBmV
F	noise figure	f = 450 MHz	-	-	7	dB
I _{tot}	total current consumption (DC)	note 3		220	240	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 46 \text{ dBmV};$ $f_q = 391.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at $f_p + f_q = 446.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $\begin{aligned} &f_p = 440.25 \text{ MHz; } V_p = V_o; \\ &f_q = 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ &f_r = 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \end{aligned}$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGY685A

FEATURES

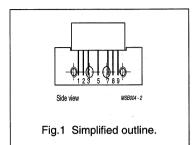
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Special super-high dynamic range amplifier module for applications in CATV systems with a bandwidth of 40 to 600 MHz at a supply voltage of +24 V (DC).

PINNING - SOT115C

PIN	DESCRIPTION
1	input
2	common
3 -	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.7	_	18.7	dB
		f = 600 MHz	19	_	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	220	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY685A

CHARACTERISTICS

Bandwidth 40 to 600 MHz; T_{case} = 30 °C; Z_{S} = Z_{L} = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.7	18.7	dB
		f = 600 MHz	19	- 1	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.5	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-55	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-60	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-56	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60	-	dBmV
F	noise figure	f = 600 MHz	-	8.5	dB
I _{tot}	total current consumption (DC)	note 3		240	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ & f_q = 541.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ & \text{measured at } f_p + f_q = 596.5 \text{ MHz.} \\ \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 590.25 \text{ MHz; V}_p = V_o; \\ & f_q = 597.25 \text{ MHz; V}_q = V_o 6 \text{ dB;} \\ & f_r = 599.25 \text{ MHz; V}_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY685A

CHARACTERISTICS

Bandwidth 40 to 550 MHz; T_{case} = 30 °C; Z_{S} = Z_{L} = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.7	_	18.7	dB
		f = 550 MHz	18.8	_	20	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	_	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	_	dB
·		f = 160 to 550 MHz	18	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-		dB
-		f = 160 to 550 MHz	18		_	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	_	-59	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	_	-62	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	-	_	-59	dB
d ₂	second order distortion	note 1	-	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61.5	_	_	dBmV
F	noise figure	f = 550 MHz	Ī-	-	8	dB
I _{tot}	total current consumption (DC)	note 3	_	220	240	mA

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- $\begin{array}{ll} 2. & f_p = 540.25 \text{ MHz; } V_p = V_o; \\ f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 549.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

BGY685A

CHARACTERISTICS

Bandwidth 40 to 450 MHz; T_{case} = 30 °C; Z_{S} = Z_{L} = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	17.7	- 1	18.7	dB
		f = 450 MHz	18.6		19.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	- 1	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz		_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	- '	- ,	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	-		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		- "	dB
		f = 80 to 160 MHz	19	_		dB
		f = 160 to 450 MHz	18	- 1	- "."	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz		-	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-		-61	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV measured at 446.5 MHz	-	_	-61	dB
d ₂	second order distortion	note 1	_		-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64		_	dBmV
·F··	noise figure	f = 450 MHz		-:	7	dB
I _{tot}	total current consumption (DC)	note 3	- 4	220	240	mA

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ & f_q = 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY685AD

FEATURES

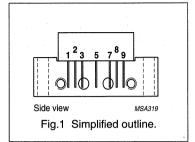
- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metalization ensures excellent reliability.

APPLICATIONS

 CATV systems operating over a frequency range of 40 to 600 MHz.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



DESCRIPTION

The BGY685AD is a hybrid high dynamic range cascode amplifier module with Darlington pre-stage dies operating at a voltage supply of +24 V in a SOT115J2 package.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.75	<u>-</u> ;	dB
I _{tot}	total current consumption (DC)	V _B = 24 V		250	mA

LIMITING VALUES

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY685AD

CHARACTERISTICS

Bandwidth 40 to 600 MHz; V_B = 24 V; T_{case} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.75	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	-62	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-58	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	62	_	dBmV
F	noise figure	f = 50 MHz	_	6	dB
		f = 600 MHz	_	8	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	250	mA

Notes

- 1. $V_p = V_q = 44 \text{ dBmV};$ $f_p = 55.25$ MHz; $f_q = 541.25$ MHz; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 590.25 \text{ MHz}; V_p = V_o;$

 $f_q = 597.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 588.25$ MHz.

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BGY685AD

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{case} = 30 °C; Z_S = Z_L = 75 $\Omega.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.8		dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	-	-65	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz		-62	dB
d ₂	second order distortion	note 1	_	-72	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	63	-	dBmV
F	noise figure	f = 50 MHz		6	dB
		f = 550 MHz	_	7.5	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	250	mA

Notes

- 1. $V_p = V_q = 44 \text{ dBmV};$ $f_p = 55.25 \text{ MHz};$ $f_q = 493.25 \text{ MHz};$ measured at $f_p + f_q = 548.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $f_p = 540.25 \text{ MHz}; V_p = V_o;$

 $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGY685AD

CHARACTERISTICS

Bandwidth 40 to 450 MHz; V_B = 24 V; T_{case} = 30 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
•		f = 550 MHz	18.6	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 450 MHz	18	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	T-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-	-66	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-58	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	-	-67	dB
d ₂	second order distortion	note 1	_	-75	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	65		dBmV
F	noise figure	f = 50 MHz	_	6	dB
		f = 450 MHz	_	7	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	250	mA

Notes

- 1. $V_p = V_q = 46 \text{ dBmV};$ $f_p = 55.25 \text{ MHz}; f_q = 391.25 \text{ MHz};$ measured at $f_p + f_q = 446.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{split}$$

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BGY685AL

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

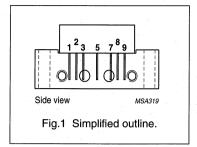
DESCRIPTION

Hybrid high dynamic range amplifier module designed for applications in CATV systems operating over a frequency range of 40 MHz to 600 MHz operating with a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7 7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5		dB
I _{tot}	total current consumption (DC)	V _B = +24 V	-	250	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY685AL

CHARACTERISTICS

Table 1 Bandwidth 40 to 600 MHz; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.5	2.0	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
-		f = 160 to 600 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18	_	dB
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-56	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-55	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-56	dB
d ₂	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60	_	dBmV
F	noise figure	f = 600 MHz	_	5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	_	250	mA

- 1.
 $$\begin{split} &f_p=55.25\text{ MHz; V}_p=44\text{ dBmV;}\\ &f_q=541.25\text{ MHz; V}_q=44\text{ dBmV;}\\ &\text{measured at }f_p+f_q=596.5\text{ MHz.} \end{split}$$
- $\begin{array}{ll} \text{2.} & f_p = 590.25 \text{ MHz; } V_p = V_o; \\ & f_q = 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY685AL

Table 2 Bandwidth 40 to 550 MHz; T_{case} = 30 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 550 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	-	dB
СТВ	composite triple beat	77 channels flat; $V_o = 44 \text{ dBmV}$; measured at 547.25 MHz	_	-58	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-56	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz		-58	dB
d ₂	second order distortion	note 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61.5		dBmV
F	noise figure	f = 550 MHz	_	4.5	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	250	mA

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 548.5 \text{ MHz}.$
- $\begin{array}{ll} \text{2.} & f_p = 540.25 \text{ MHz; } V_p = V_o; \\ & f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 549.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY685AL

Table 3 Bandwidth 40 to 450 MHz; $T_{case} = 30$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
• •		f = 450 MHz	18.3	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.3	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 450 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	- 4	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 450 MHz	18		dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz		<i>–</i> 58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz		-54	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_ ** * .	-58	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	62.5	_	dBmV
F	noise figure	f = 450 MHz	_	4.5	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	= "	250	mA

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ & f_q = 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY687

FEATURES

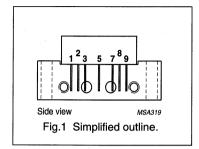
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 600 MHz	22	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY687

CHARACTERISTICS

Bandwidth 40 to 600 MHz; $T_{case} = 30$ °C; $Z_S = Z_L = 75 \Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f =50 MHz	21	22	dB
		f = 600 MHz	22	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.8	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
		f = 550 to 600 MHz	16	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-54	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-54	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-52	dB
d ₂	second order distortion	note 1	_	-66	dB
Vo	output voltage	d _{im} = -60 dB; note 2	58	_	dBmV
F	noise figure	f = 600 MHz	-	6.5	dB
I _{tot}	total current consumption (DC)	note 3	-	240	mA

Notes

1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.

 $\begin{array}{ll} \text{2.} & f_p = 590.25 \text{ MHz; } V_p = V_o; \\ & f_q = 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ & f_r = 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ & \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \\ \end{array}$

BGY687B

FEATURES

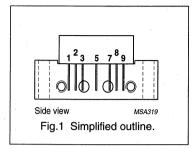
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	26.2	27.8	dB
		f = 600 MHz	27.8	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	340	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY687B

CHARACTERISTICS

Bandwidth 40 to 600 MHz; V_B = 24 V; T_{mb} = 35 °C; Z_S = Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 600 MHz	27.8	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.8	2.8	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 600 MHz	18	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-53	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-58	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	-	-54	dB
d ₂	second order distortion	note 1	- 7	-66	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60	-	dBmV
F	noise figure	f = 600 MHz	_	7	dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.

2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o, \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

BGY687B

CHARACTERISTICS

Bandwidth 40 to 550 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75 \Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 550 MHz	27.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz		±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	- 1.1	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 550 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 550 MHz	18	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	- 1	-57	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	- 4	-57	dB
d ₂	second order distortion	note 1	-	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	-	dBmV
F. S.	noise figure	f = 550 MHz		6.5	dB
I _{tot}	total current consumption (DC)	note 3		340	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 548.5 \text{ MHz}$.
- 2. Measured according to DIN45004B:
 - $$\begin{split} &f_p = 540.25 \text{ MHz; } V_p = V_o; \\ &f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \end{split}$$

 - $f_r = 549.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGY687B

CHARACTERISTICS

Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 35 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 450 MHz	27.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-	-58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-58	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	dBmV
F	noise figure	f = 450 MHz	_	6	dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

 $\begin{aligned} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{aligned}$

BGY785A

FEATURES

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

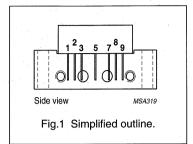
DESCRIPTION

Hybrid high dynamic range cascode amplifier module designed for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

	SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
1	G _p	power gain	f = 50 MHz	18	19	dB
-			f = 750 MHz	18.5	-	dB
	l _{tot}	total current consumption (DC)	V _B = 24 V	= "	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

BGY785A

CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	2.0	dB
FL	flatness of frequency response	f = 40 to 750 MHz	- "	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	Ī-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	Ī-	dB
		f = 640 to 750 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	-	dB
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-53	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-56	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	-	-53	dB
d ₂	second order distortion	note 1	_	-65	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 450 MHz	_	5.5	dB
		f = 550 MHz	_	5.5	dB
		f = 600 MHz	_	6	dB
		f = 750 MHz		7	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	240	mA

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 691.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 746.5 MHz.
- $\begin{array}{ll} \text{2.} & f_p = 740.25 \text{ MHz; } V_p = V_o; \\ & f_q = 747.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 749.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 738.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY785A

Table 2 Bandwidth 40 to 600 MHz; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_{S} = Z_{L} = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 600 MHz	16		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 600 MHz	16		dB
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	-	-57	dB
X _{mod}	cross modulation	85 channels flat; $V_o = 44 \text{ dBmV}$; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-58	dB
d ₂	second order distortion	note 1		-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	-	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3		240	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 44 \ \text{dBmV}; \\ & f_q = 541.25 \ \text{MHz}; \ V_q = 44 \ \text{dBmV}; \\ & \text{measured at} \ f_p + f_q = 596.5 \ \text{MHz}. \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 590.25 \text{ MHz; } V_p = V_o; \\ & f_q = 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY785A

Table 3 Bandwidth 40 to 550 MHz; $T_{case} = 30$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
_		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	_	dB
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	_	-60	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz		-60	dB
d ₂	second order distortion	note 1	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	62	_	dBmV
F	noise figure	see Table 1	_		dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	_	240	mA

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- $\begin{array}{ll} \text{2.} & f_p = 540.25 \text{ MHz}; \ V_p = V_o; \\ & f_q = 547.25 \text{ MHz}; \ V_q = V_o 6 \text{ dB}; \\ & f_r = 549.25 \text{ MHz}; \ V_r = V_o 6 \text{ dB}; \\ & \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz}. \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

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Table 4 Bandwidth 40 to 450 MHz; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	<u> </u>	dB
	Table 1	f = 160 to 320 MHz	17	-	dB
·		f = 320 to 450 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 450 MHz	16	_	dB
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-	-60	dB
CSO	composite second order distortion	60 channels flat; V _o = 44 dBmV; measured at446.5 MHz	_	61	dB
d ₂	second order distortion	note 1	_	-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	dBmV
F	noise figure	see Table 1	_	-	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	240	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 46 \text{ dBmV}; \\ & f_q = 391.25 \text{ MHz}; \ V_q = 46 \text{ dBmV}; \\ & \text{measured at } f_p + f_q = 446.5 \text{ MHz}. \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY785AD

FEATURES

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

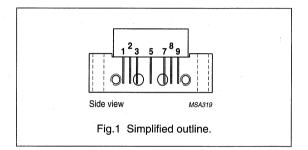
CATV systems operating in the 40 to 750 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range cascode amplifier module with darlington pre-stage dies in a SOT115J package operating at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	265	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage		60	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY785AD

CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $V_B = 24$ V; $T_{case} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
'		f = 750 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-58	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-56	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-58	dB
d ₂	second order distortion	note 1	_	-68	dB
V _o	output voltage	d _{im} = -60 dB; note 2	61	- '	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 450 MHz	_	5	dB
		f = 550 MHz		5.5	dB
		f = 600 MHz	_	5.5	dB
		f = 750 MHz	-	6	dB
I _{tot}	total current consumption (DC)	note 3	-	265	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 740.25 \text{ MHz}; V_p = V_o;$

 $f_q = 747.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 749.25 \text{ MHz} = ; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 738.25$ MHz.

BGY785AD

Table 2 Bandwidth 40 to 600 MHz; V_B = 24 V; T_{case} = 30 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	=1, ,	dB
*.		f = 160 to 320 MHz	17		dB
		f = 320 to 600 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	- 1	dB
a		f = 320 to 600 MHz	16	_	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz		-64	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-59	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz		-60	dB
d ₂	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	-	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	-	265	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 541.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 596.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

$$f_p = 590.25$$
; $V_p = V_o$; $f_q = 597.25$; $V_q = V_o - 6$ dB; $f_r = 599.25$; $V_r = V_o - 6$ dB; measured at $f_p + f_q - f_r = 588.25$ MHz.

BGY785AD

Table 3 Bandwidth 40 to 550 MHz; $V_B = 24$ V; $T_{case} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16		dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	-	-66	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	-	-62	dB
d ₂	second order distortion	note 1		-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64.5	_	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	265	mA

Notes

- 1.
 $$\begin{split} f_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ f_q = 493.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ \text{measured at } f_p + f_q = 548.5 \text{ MHz.} \end{split}$$
- 2. Measured according to DIN45004B:

 $f_p = 540.25 \text{ MHz}; V_p = V_o;$ $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 538.25$ MHz.

BGY785AD

Table 4 Bandwidth 40 to 450 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 450 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 450 MHz	16	_	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	-	-66	dB
X_{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz		-65	dB
d_2	second order distortion	note 1	_	-75	dB
Vo	output voltage	d _{im} = -60 dB; note 2	66	-	dBmV
F	noise figure	see Table 1			dB
I _{tot}	total current consumption (DC)	note 3		265	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 46 \text{ dBmV}$; $f_q = 391.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at $f_p + f_q = 446.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o \text{-}6 \text{ dB;} \end{split}$$

 $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGY785AD/8M

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

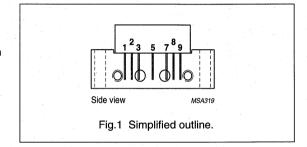
CATV systems operating in the 40 to 870 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range cascode amplifier module with Darlington pre-stage dies in a SOT115J package, operating at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION			
1	input			
2	common			
3	common			
5	+V _B			
7	common			
8	common			
9	output			



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 870 MHz	18.5		dB
I _{tot}	total current consumption (DC)	V _B = 24 V		265	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY785AD/8M

CHARACTERISTICS

Table 1 Bandwidth 40 to 870 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
-		f = 870 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 870 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 870 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 870 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 870 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	110 channels flat, note 1; V _o = 44 dBmV; measured at 745.25 MHz	 ,	-58	dB
X _{mod}	cross modulation	110 channels flat, note 1; V _o = 44 dBmV; measured at 55.25 MHz	_	-56	dB
CSO	composite second order distortion	110 channels flat, note 1 V _o = 44 dBmV; measured at 746.5 MHz	_	-58	dB
d ₂	second order distortion	notes 1 and 2	_	-68	dB
Vo	output voltage	d _{im} = -60 dB; notes 1 and 3	61	_	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 550 MHz	_	5.5	dB
		f = 650 MHz	_	5.5	dB
		f = 750 MHz	_	6	dB
		f = 870 MHz	_	6.5	dB
I _{tot}	total current consumption (DC)	note 4	_	265	mA

- 1. Linearity guaranteed up to 750 MHz.
- 2. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 3. Measured according to DIN45004B:
 - $f_p = 740.25 \text{ MHz}; V_p = V_o;$
 - $f_q = 747.25 \text{ MHz}; V_q = V_o 6 \text{ dB};$
 - $f_r = 749.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$
 - measured at $f_p + f_q f_r = 738.25$ MHz.
- 4. The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

BGY785AD/8M

Table 2 Bandwidth 40 to 650 MHz; $V_B = 24$ V; $T_{case} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 650 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 650 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 650 MHz		±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 650 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	- ,	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 650 MHz	16	1-	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	94 channels flat, note 1; V _o = 44 dBmV; measured at 649.25 MHz	_	-62	dB
X _{mod}	cross modulation	94 channels flat, note 1; V _o = 44 dBmV; measured at 55.25 MHz		-57	dB
CSO	composite second order distortion	94 channels flat, note 1; V _o = 44 dBmV; measured at 650.5 MHz		-60	dB
d ₂	second order distortion	notes 1 and 2	-	-70	dB
V _o	output voltage	$d_{im} = -60 \text{ dB}$; notes 1 and 3	63	-	dBmV
F	noise figure	see Table 1	-	- 11 1 1	dB
I _{tot}	total current consumption (DC)	note 4	_	265	mA

- 1. Linearity guaranteed up to 750 MHz.
- 2. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 595.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 650.5 MHz.
- 3. Measured according to DIN45004B: $f_p=640.25~\text{MHz};~V_p=V_o;~f_q=647.25~\text{MHz};~V_q=V_o-6~\text{dB};~f_r=649.25~\text{MHz};~V_r=V_o-6~\text{dB};~measured~\text{at}~f_p+f_q-f_r=638.25~\text{MHz}.$
- 4. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY785AD/8M

Table 3 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	T-	dB
,		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	<u> </u>	dB
+ + ·		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	Ī-	dB
		f = 320 to 550 MHz	16	_	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	77 channels flat, note 1; V _o = 44 dBmV; measured at 547.25 MHz	_	-65	dB
X _{mod}	cross modulation	77 channels flat, note 1; V _o = 44 dBmV; measured at 55.25 MHz	_	-59	dB
CSO	composite second order distortion	77 channels flat, note 1; V _o = 44 dBmV; measured at 548.5 MHz	_	-62	dB
d ₂	second order distortion	notes 1 and 2		-72	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; notes 1 and 3	64.5	_	dBmV
F	noise figure	see Table 1	_		dB
I _{tot}	total current consumption (DC)	note 4	_	265	mA

- 1. Linearity guaranteed up to 750 MHz.
- 2. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.
- 3. Measured according to DIN45004B: $f_p = 540.25 \text{ MHz}; \ V_p = V_o; \ f_q = 547.25 \text{ MHz}; \ V_q = V_o 6 \text{ dB}; \ f_r = 549.25 \text{ MHz}; \ V_r = V_o 6 \text{ dB}; \ measured at \ f_p + f_q f_r = 538.25 \text{ MHz}.$
- 4. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY787

FEATURES

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

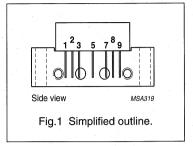
DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 750 MHz	21.5	- " "	dB
I _{tot}	total current consumption (DC)	V _B = +24 V		240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	mounting base operating temperature	-20	+100	°C

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CHARACTERISTICS

Table 1 Bandwidth 40 to 750 MHz; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 750 MHz	21.5	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-51	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	51	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz		-50	dB
d ₂	second order distortion	note 1	_	-63	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59	- 1	dBmV
F	noise figure	f = 50 MHz	_	5	dB
		f = 450 MHz	_	5.5	dB
		f = 550 MHz	1-	5.5	dB
		f = 600 MHz		6	dB
		f = 750 MHz	_	6.5	dB
I _{tot}	total current consumption	DC value; $V_B = +24 \text{ V}$; note 3	-	240	mA

Notes

- 1.
 $$\begin{split} f_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ f_q = 691.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ \text{measured at } f_p + f_q = 746.5 \text{ MHz.} \end{split}$$
- $\begin{array}{ll} \text{2.} & f_p = 740.25 \text{ MHz; } V_p = V_o; \\ & f_q = 747.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 749.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 738.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = +24$ V, but is able to withstand supply transients up to +30 V.

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Table 2 Bandwidth 40 to 600 MHz; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 600 MHz	21.5		dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz;	20	_	dB
	•	f = 80 to 160 MHz	18.5	_	dB
	·	f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_ '	-56	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-53	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-53	dB
d ₂	second order distortion	note 1	_	-66	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59.5	_	dBmV
F	noise figure	see Table 1	_	-	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	-	240	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ & f_q = 541.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ & \text{measured at } f_p + f_q = 596.5 \text{ MHz.} \\ \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 590.25 \text{ MHz; } V_p = V_o; \\ & f_q = 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

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Table 3 Bandwidth 40 to 550 MHz; T_{case} = 30 °C; Z_{S} = Z_{L} = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 550 MHz	21.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	- '	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz	-	-59	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-54	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-55	dB
d ₂	second order distortion	note 1	_	-66	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61.5	-	dBmV
F	noise figure	see Table 1		-	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	240	mA

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 493.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 548.5 MHz.
- $\begin{array}{ll} \text{2.} & f_p = 540.25 \text{ MHz; } V_p = V_o; \\ & f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 549.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

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Table 4 Bandwidth 40 to 450 MHz; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 450 MHz	21.5		dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
	·	f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	_ *	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz		-59	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	_	-53	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	_	60	dB
d ₂	second order distortion	note 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	64	_	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption	DC value; V _B = +24 V; note 3	_	240	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 46 \ dBmV; \\ & f_q = 391.25 \ MHz; \ V_q = 46 \ dBmV; \\ & \text{measured at } f_p + f_q = 446.5 \ MHz. \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ & f_q = 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at $V_B = +24 \text{ V}$, but is able to withstand supply transients up to +30 V.

BGY883

FEATURES

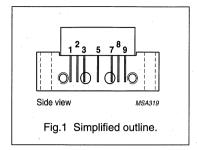
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN DESCRIPTION		
1	input	
2	common	
3	common	
5	+V _B	
7	common	
8	common	
9	output	



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	14.5	15.5	dB
		f = 860 MHz	15	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	235	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY883

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	14.5	_	15.5	dB
		f = 860 MHz	15		_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	_	2	dB
FL ·	flatness of frequency response	f = 40 to 860 MHz	_	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	18.5	_	-	dB
-		f = 160 to 320 MHz	17	_	_	dB
		f = 320 to 640 MHz	15.5	-	_	dB
		f = 640 to 860 MHz	14	_	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	18.5	_	-	dB
		f = 160 to 320 MHz	17	_	-	dB
		f = 320 to 640 MHz	15.5	-	-	dB
		f = 640 to 860 MHz	14	- "	_	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	49 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 859.25 MHz	_	_	-61	dB
X _{mod}	cross modulation	49 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_		-61	dB
CSO	composite second order distortion	49 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	-	_	-61	dB
d ₂	second order distortion	note 1	_	_	-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	58.5	60	-	dBmV
F	noise figure	f = 50 MHz	-		6	dB
		f = 550 MHz	_		7	dB
		f = 650 MHz	_	_	7.5	dB
		f = 750 MHz	_		8	dB
		f = 860 MHz	_	_	8.5	dB
I _{tot}	total current consumption (DC)	note 3	-		235	mA

Notes

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 805.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 860.5 MHz.
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$

 $f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

BGY885A

FEATURES

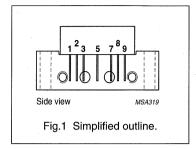
- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	240	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY885A

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18		19	dB
		f = 860 MHz	18.5	_	-	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	_	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	- "	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	18.5	_	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5	-	-	dB
		f = 640 to 860 MHz	14	_		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		_	dB
		f = 80 to 160 MHz	18.5		-	dB
		f = 160 to 320 MHz	17	-	_	dB
		f = 320 to 640 MHz	15.5	_	-	dB
		f = 640 to 860 MHz	14	-	_	dB
S ₂₁	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	49 channels flat; V _o = 44 dBmV; measured at 859.25 MHz			-61	dB
X _{mod}	cross modulation	49 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	, .	_	-61	dB
CSO	composite second order distortion	49 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	-		-61	dB
d ₂	second order distortion	note 1	_	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	58	60	-	dBmV
F	noise figure	f = 50 MHz	_	-	5	dB
		f = 450 MHz	-	_	5.5	dB
		f = 550 MHz	_	-:	5.5	dB
		f = 600 MHz	- '	_	6	dB
		f = 650 MHz	_		6	dB
		f = 750 MHz	-"		7	dB
		f = 860 MHz	- 1	_ * *.	8	dB
I _{tot}	total current consumption (DC)	note 3	-	-	240	mA

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 805.25 \text{ MHz}$; $V_q = 44 \text{ dBmV}$; measured at $f_p + f_q = 860.5 \text{ MHz}$.
- 2. Measured according to DIN45004B:

 - $$\begin{split} f_p = 851.25 \text{ MHz; } V_p = V_o; f_q = 858.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; } V_r = V_o 6 \text{ dB; measured at } f_p + f_q f_r = 849.25 \text{ MHz.} \end{split}$$
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY885A

Table 2 Bandwidth 40 to 750 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
*	. *	f = 750 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_ '	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	-	-53	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-57	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	-	-53	dB
d ₂	second order distortion	note 1	_	-65	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59	-	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption (DC)	note 3	_	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 740.25 \text{ MHz}; V_p = V_o;$

 $f_q = 747.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 749.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 738.25$ MHz.

BGY885A

Table 3 Bandwidth 40 to 600 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-57	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-59	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz		-58	dB
d ₂	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	ļ-	dBmV
F	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption (DC)	note 3	_	240	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV}; \\ f_q = 541.25 \text{ MHz}; V_q = 44 \text{ dBmV}; \\ \text{measured at } f_p + f_q = 596.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $f_p = 590.25 \text{ MHz}; V_p = V_o;$

 $f_q = 597.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 588.25$ MHz.

BGY885A

Table 4 Bandwidth 40 to 550 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V _o = 44 dBmV; measured at 547.25 MHz		-60	dB
X _{mod}	cross modulation	77 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V _o = 44 dBmV; measured at 548.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	62	_	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	240	mA

- 1. $f_p = 55.25 \text{ MHz}$; $V_p = 44 \text{ dBmV}$; $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 548.5$ MHz.
- 2. Measured according to DIN45004B:
 - $$\begin{split} f_p &= 540.25 \text{ MHz; } V_p = V_o; \\ f_q &= 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \end{split}$$

 - $f_r = 549.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
 - measured at $f_p + f_q f_r = 538.25$ MHz.
- 3. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

BGY885A

Table 5 Bandwidth 40 to 450 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
•		f = 450 MHz	18.5		dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 450 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	- 1, 1	dB
		f = 80 to 160 MHz	18.5	- "	dB
		f = 160 to 320 MHz	17		dB
27.5		f = 320 to 450 MHz	16		dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	_	-61	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz		-60	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz		-61	dB
d ₂	second order distortion	note 1	_	-75	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$; note 2	64	_	dBmV
F	noise figure	see Table 1	1-		dB
I _{tot}	total current consumption (DC)	note 3		240	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; V}_p = 46 \text{ dBmV;} \\ & f_q = 391.25 \text{ MHz; V}_q = 46 \text{ dBmV;} \end{array}$ measured at $f_p + f_q = 446.5 \text{ MHz}$.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$

 $f_q = 447.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 438.25$ MHz.

BGY885B

FEATURES

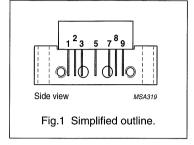
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

The BGY885B is a hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN DESCRIPTION			
1	input		
2	common		
3	common		
5	+V _B		
7	common		
8.	common		
9	output		



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	19.5	20.5	dB
-		f = 860 MHz	20		dB
I _{tot}	total current consumption (DC)	V _B = 24 V		235	mA

LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY885B

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	_	20.5	dB
•		f = 860 MHz	20			dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	-	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-		±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	18.5	_	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5	_	- :	dB
		f = 640 to 860 MHz	14	_	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	-	dB .
		f = 80 to 160 MHz	18.5	_	- :	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5	_	_	dB
		f = 640 to 860 MHz	14	-	_	dB
S ₂₁	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	49 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	_	_	-60	dB
CSO	composite second order distortion	49 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	=1	_	-60	dB
d_2	second order distortion	note 1		-	-68	dB
V _o	output voltage	d _{im} = −60 dB; note 2	57.5	59	_	dBmV
F	noise figure	f = 50 MHz	_	_	5	dB
		f = 550 MHz	_	_	5.5	dB
		f = 650 MHz	_	_	6.5	dB
		f = 750 MHz	_	_	6.5	dB
		f = 860 MHz	_ '		7.5	dB
I _{tot}	total current consumption (DC)	note 3		_	235	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{split}$$

BGY887

FEATURES

- Excellent linearity
- Extremely low noise
- · Excellent return loss properties
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

APPLICATIONS

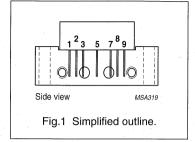
• CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid dynamic range amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 860 MHz	21.5	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V		235	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY887

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 860 MHz	21.5	- :	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5		dB
		f = 640 to 860 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	49 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	_	-62	dB
X _{mod}	cross modulation	49 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	49 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	=	-61	dB
d ₂	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59	-	dBmV
F	noise figure	f = 50 MHz	-	4.5	dB
		f = 550 MHz		5	dB
		f = 600 MHz	_	5	dB
		f = 650 MHz	_	5	dB
		f = 750 MHz	_	5.5	dB
		f = 860 MHz	_	6.5	dB
I _{tot}	total current consumption (DC)	note 3	_	235	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{split}$$

BGY887

Table 2 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 860 MHz	21.5		dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz		±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	- ,	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	- 1 1	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	1-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	- " " " " " " " " " " " " " " " " " " "	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	129 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	-	-51	dB
X _{mod}	cross modulation	129 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-57	dB
CSO	composite second order distortion	129 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	-	-55	dB
d_2	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59	-	dBmV
F	noise figure	see Table 1	-	-	dB
I _{tot}	total current consumption (DC)	note 3		235	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$

 $f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

BGY887

Table 3 Bandwidth 40 to 750 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \, ^{\circ}\text{C}$; $Z_S = Z_L = 75 \, \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
• -		f = 750 MHz	21.5		dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	. –	dB
		f = 640 to 750 MHz	14		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	1-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	T-	dB
		f = 640 to 750 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	_	-51	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-54	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	-	-56	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	60	_ '	dBmV
F	noise figure	see Table 1	_	-	dB
I _{tot}	total current consumption (DC)	note 3	_	235	mA

Notes

- 1. $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$ $f_q = 691.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at $f_p + f_q = 746.5$ MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \end{split}$$

 $f_r = 749.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 738.25$ MHz.

BGY887

Table 4 Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21	22	dB
		f = 600 MHz	21.5	<u> </u>	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.2	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16		dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16]_	dB
S ₂₁	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	·	-56	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-57	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz		-58	dB
d ₂	second order distortion	note 1	-	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61		dBmV
F	noise figure	see Table 1	-	-	dB
I _{tot}	total current consumption (DC)	note 3		235	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. Measured according to DIN45004B:

 $f_p = 590.25 \text{ MHz}; V_p = V_o;$ $f_q = 597.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ $f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 588.25$ MHz.

BGY887B

FEATURES

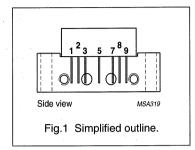
- · Excellent linearity
- · Extremely low noise
- · High gain
- Excellent return loss properties.

APPLICATIONS

 Single-module line extender in CATV systems operating in the 40 to 860 MHz frequency range.

PINNING - SOT115J

PIN DESCRIPTION		
1	input	
2	common	
3	common	
5	+V _B	
7	common	
8	common	
9	output	



DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC). This high gain module consists of two cascaded stages, both in cascode configuration.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 860 MHz	29	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	340	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	- :	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY887B

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 860 MHz	29	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB .
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
-		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	- "	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	_	dB
СТВ	composite triple beat	49 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	_	-60	dB
X _{mod}	cross modulation	49 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	49 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	_	-60	dB
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	58.5	_	dBmV
F	noise figure	f = 50 MHz	_	5	dB
		f = 550 MHz	_	5.5	dB
		f = 600 MHz	_	5.5	dB
		f = 650 MHz	_	5.5	dB
		f = 750 MHz	-	6	dB
		f = 860 MHz	_	6.5	dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

- 1. f_p = 55.25 MHz; V_p = 44 dBmV; f_q = 805.25 MHz; V_q = 44 dBmV; measured at f_p + f_q = 860.5 MHz.
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$

 $f_q = 858.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

BGY887B

Table 2 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 860 MHz	29	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	- ,	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
,		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	-	dB
СТВ	composite triple beat	129 channels flat;	_	-46	dB
		V _o = 44 dBmV;	-		
		measured at 859.25 MHz		50	dB
X _{mod}	cross modulation	129 channels flat; $V_0 = 44 \text{ dBmV}$;		-52	ub
		measured at 55.25 MHz			
CSO	composite second order distortion	129 channels flat;	_	-53	dB
		$V_0 = 44 \text{ dBmV};$			
		measured at 860.5 MHz			
d ₂	second order distortion	note 1		-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	58.5		dBmV
F	noise figure	see Table 1			dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 805.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 860.5$ MHz.
- 2. Measured according to DIN45004B:
 - $f_p = 851.25 \text{ MHz}; V_p = V_o;$ $f_q = 858.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 849.25$ MHz.

BGY887B

Table 3 Bandwidth 40 to 750 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 750 MHz	29	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 750 MHz		±0.45	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
_		f = 160 to 320 MHz	17	_	dB
	*	f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	_	dB
СТВ	composite triple beat	110 channels flat;	_	-50	dB
		V _o = 44 dBmV; measured at 745.25 MHz			
X _{mod}	cross modulation	110 channels flat;	-	-54	dB
		V _o = 44 dBmV; measured at 55.25 MHz			
CSO	composite second order distortion	110 channels flat:		-56	dB
000	composite second order distortion	$V_0 = 44 \text{ dBmV};$	_	-50	ub
		measured at 746.5 MHz			
d ₂	second order distortion	note 1	_	-70	dB
Vo	output voltage	d _{im} = -60 dB; note 2	59	-	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \, V_p = 44 \text{ dBmV}; \\ f_q = 691.25 \text{ MHz}; \, V_q = 44 \text{ dBmV}; \\ & \text{measured at } f_p + f_q = 746.5 \text{ MHz}. \end{array}$
- 2. Measured according to DIN45004B:

$$\begin{split} &f_p = 740.25 \text{ MHz; } V_p = V_o; \\ &f_q = 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ &f_r = 749.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ &\text{measured at } f_p + f_q - f_r = 738.25 \text{ MHz.} \end{split}$$

BGY887B

Table 4 Bandwidth 40 to 600 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 600 MHz	29	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	_	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.35	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 600 MHz	16	- ;	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-55	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-56	dB
CSO	composite second order distortion	85 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 596.5 MHz	- '.	-60	dB
d ₂	second order distortion	note 1	-	-72	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	-	dBmV
F · · · · ·	noise figure	see Table 1	-	_	dB
I _{tot}	total current consumption (DC)	note 3		340	mA

Notes

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz}; \ V_p = 44 \ dBmV; \\ & f_q = 541.25 \ MHz; \ V_q = 44 \ dBmV; \\ & \text{measured at } f_p + f_q = 596.5 \ MHz. \end{array}$
- 2. Measured according to DIN45004B:

 $\begin{aligned} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{aligned}$

BGY887BO

FEATURES

- Excellent linearity
- · Extremely low noise
- Excellent flatness
- · Standard CATV outline
- · Rugged construction
- · Gold metallization ensures excellent reliability.

APPLICATIONS

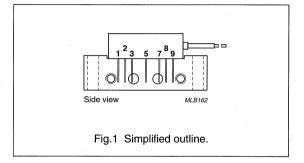
 CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range optical receiver module in a SOT115M package operating at a voltage supply of +24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor the pin diode current and an electrical output with an impedance of 75 $\Omega.$

PINNING - SOT115M

PIN	DESCRIPTION
1	monitor current
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
S ₂₂	output return losses	f = 40 to 860 MHz	11	_	dB
	optical input return losses		40	_	dB
d ₂	second order distortion	f = 324.25 MHz	_	-70	dBc
F	equivalent noise input	f = 40 MHz		7	pA/√Hz
I _{tot}	total current consumption (DC)	V _B = 24 V	_	250	mA

HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

CAUTION

The device is supplied in an antistatic package and must be protected against static discharge during transport or handling.

BGY887BO

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
T _{stg}	storage temperature		-40	+85	°C
T _{mb}	operating mounting base temperature		-20	+85	°C
Pin	optical input power	continuous		2	mW
ESD	ESD sensitivity	human body model; R = 1.5 k Ω ; C = 100 pF	500	_	V

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
S	responsivity	$\lambda = 1300 \text{ nm}$	800	_	V/W
FL	flatness of frequency response		_	±0.5	dB
S ₂₂	output return losses	f = 40 to 860 MHz	11	-	dB
	optical input return losses		40	-	dB
d ₂	second order distortion	note 1	. –	-70	dB
d ₃	third order distortion	note 2	_	-80	dB
F	equivalent noise input	f = 40 MHz	_	7	pA/√Hz
Sλ	spectral sensitivity	$\lambda = 1310 \pm 20 \text{ nm}$	0.85	_	A/W
		$\lambda = 1550 \pm 20 \text{ nm}$	0.9	-	A/W
λ	optical wavelength		1290	1600	nm
L	length of optical fibre	fibre; SM type; 9/125 μm	1		m
I _{tot}	total current consumption (DC)	V _B = 24 V		250	mA

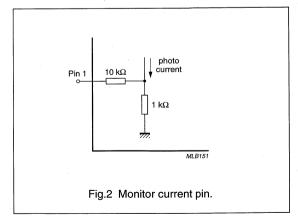
Notes

1. Two laser test; each laser with 40% modulation index; $f_p = 135 \text{ MHz}; P_p = 0.5 \text{ mW}; \\ f_q = 189.25 \text{ MHz}; P_q = 0.5 \text{ mW};$

Three laser test; each laser with 40% modulation index;

 $\begin{array}{l} f_p = 326.25 \text{ MHz; } P_p = 0.33 \text{ mW;} \\ f_q = 333.25 \text{ MHz; } P_q = 0.33 \text{ mW;} \\ f_r = 335.25 \text{ MHz; } P_q = 0.33 \text{ mW;} \\ \text{measured at } f_p + f_q = 324.25 \text{ MHz.} \end{array}$

measured at $f_p + f_q = 324.25$ MHz.



BGY887BO/FC

FEATURES

- · Excellent linearity
- · Extremely low noise
- Excellent flatness
- Standard CATV outline
- · Rugged construction
- · Gold metallization ensures excellent reliability
- FC/APC connector (JDS version).

APPLICATIONS

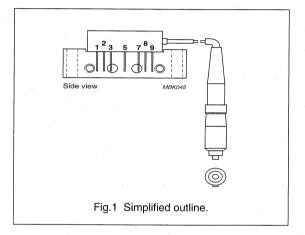
 CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range optical receiver module in a SOT115N package operating at a voltage supply of +24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor the pin diode current and an electrical output with an impedance of 75 Ω . The optical fibre is terminated by an FC/APC connector (JDS version) and partly reinforced by a 3 mm diameter Kevlar buffer.

PINNING - SOT115N

PIN	DESCRIPTION
1	monitor current
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
S ₂₂	output return losses	f = 40 to 860 MHz	11	_	dB
	optical input return losses		40		dB
d ₂	second order distortion	f = 324.25 MHz	-	-70	dBc
F	equivalent noise input	f = 40 MHz	-	7	pA/√Hz
I _{tot}	total current consumption (DC)	V _B = 24 V		250	mA

HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

CAUTION

The device is supplied in an antistatic package and must be protected against static discharge during transport or handling.

BGY887BO/FC

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
T _{stg}	storage temperature		-40	+85	°C
T _{mb}	operating mounting base temperature		-20	+85	°C
Pin	optical input power	continuous	_	2	mW
ESD	ESD sensitivity	human body model; R = 1.5 kΩ; C = 100 pF	500	_	V

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24$ V; $T_{mb} = 30$ °C; $Z_L = 75~\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
S	responsivity	λ = 1300 nm	750	_	V/W
FL	flatness of frequency response		_	±0.5	dB
S ₂₂	output return losses	f ₁ = 40 to 860 MHz	11	-	dB
	optical input return losses		40	_	dB
OBR _C	connector optical return losses		70	_	dB
IL _C	connector optical insertion losses		_	0.5	dB
d ₂	second order distortion	note 1	-	-70	dB
d_3	third order distortion	note 2	_	-80	dB
F	equivalent noise input	f ₁ = 40 MHz	_	7	pA/√Hz
S _λ	spectral sensitivity	$\lambda = 1310 \pm 20 \text{ nm}$	0.85	_	A/W
		λ = 1350 ±20 nm	0.9	_	A/W
λ	optical wavelength		1290	1600	nm
L	length of optical fibre	buffered fibre; SM type; 9/125 μm; Kevlar buffer: 3 mm	577	627	mm
I _{tot}	total current consumption (DC)	note 3	_	250	mA

Notes

1. Two laser test; each laser with 40 % modulation index: $\begin{aligned} f_p &= 135 \text{ MHz}; \ P_p = 0.5 \text{ mW}; \\ f_q &= 189.25 \text{ MHz}; \ P_q = 0.5 \text{ mW}; \end{aligned}$

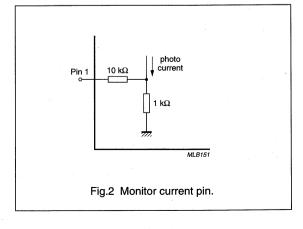
measured at $f_p + f_q = 324.25$ MHz.

2. Three laser test; each laser with 40 % modulation index:

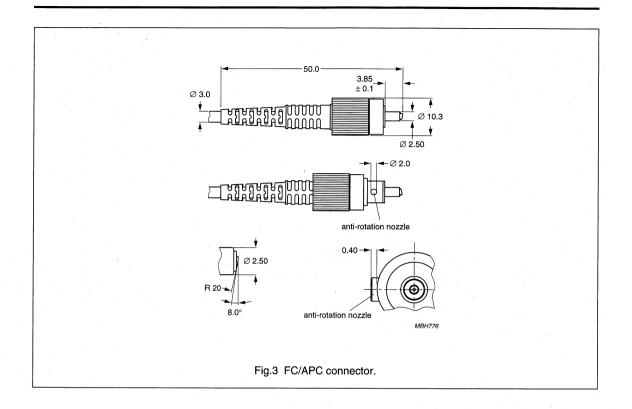
 $f_p = 326.25 \text{ MHz}; P_p = 0.33 \text{ mW};$

 $f_q = 333.25 \text{ MHz}; P_q = 0.33 \text{ mW};$ $f_r = 335.25 \text{ MHz}; P_q = 0.33 \text{ mW};$

measured at $f_p + f_q = 324.25$ MHz.



BGY887BO/FC



BGY887BO/SC

FEATURES

- Excellent linearity
- · Extremely low noise
- Excellent flatness
- · Standard CATV outline
- · Rugged construction
- · Gold metallization ensures excellent reliability
- SC/APC connector.

APPLICATIONS

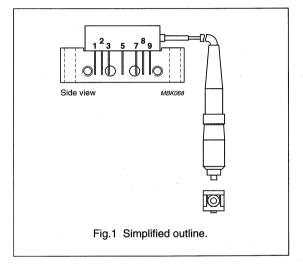
 CATV systems operating in the 40 to 860 MHz frequency range.

DESCRIPTION

Hybrid high dynamic range optical receiver module in a SOT115P package operating at a voltage supply of +24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor the pin diode current and an electrical output with an impedance of 75 $\Omega.$ The optical fibre is terminated by an SC/APC connector and partly reinforced by a 3 mm diameter Kevlar buffer.

PINNING - SOT115P

PIN	DESCRIPTION
1	monitor current
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
S ₂₂	output return losses	f = 40 to 860 MHz	11	_	dB
	optical input return losses		40	_	dB
d_2	second order distortion	f = 324.25 MHz	_	-70	dBc
F	equivalent noise input	f = 40 MHz	_	7	pA/√Hz
I _{tot}	total current consumption (DC)	V _B = 24 V	-	250	mA .

HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

C	Δ	l	ľ	ГΙ	a	N	۱

The device is supplied in an antistatic package and must be protected against static discharge during transport or handling.

BGY887BO/SC

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
T _{stg}	storage temperature		-40	+85	°C
T _{mb}	operating mounting base temperature		-20	+85	°C
Pin	optical input power	continuous	-	2	mW
ESD	ESD sensitivity	human body model; R = 1.5 k Ω ; C = 100 pF	500	_	V

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{mb} = 30 \,^{\circ}\text{C}$; $Z_L = 75 \,\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
S	responsivity	λ = 1300 nm	750		V/W
FL	flatness of frequency response			±0.5	dB
S ₂₂	output return losses	f ₁ = 40 to 860 MHz	11	_	dB
	optical input return losses		40	_	dB
OBR _C	connector optical return losses		70	_	dB
IL _C	connector optical insertion losses		_	0.5	dB
d ₂	second order distortion	note 1	- 7	-70	dB
d ₃	third order distortion	note 2	_	-80	dB
F	equivalent input noise	f = 40 MHz	-	7	pA/√Hz
S _λ	spectral sensitivity	$\lambda = 1310 \pm 20 \text{ nm}$	0.85		A/W
		$\lambda = 1350 \pm 20 \text{ nm}$	0.9		A/W
λ	optical wavelength		1290	1600	nm
L	length of optical fibre	buffered fibre; SM type; 9/125 μm; Kevlar buffer: 3 mm	817	917	mm
I _{tot}	total current consumption (DC)	note 3	- 5.5	250	mA

Notes

1. Two laser test; each laser with 40 % modulation index:

 $\begin{aligned} f_p &= 135 \text{ MHz; } P_p = 0.5 \text{ mW;} \\ f_q &= 189.25 \text{ MHz; } P_q = 0.5 \text{ mW;} \end{aligned}$

 $f_q = 189.25 \text{ MHz}; P_q = 0.5 \text{ mW};$ measured at $f_p + f_q = 324.25 \text{ MHz}.$

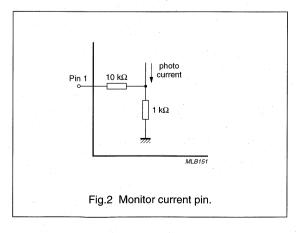
Three laser test; each laser with 40 % modulation index:

 $f_p = 326.25 \text{ MHz}; P_p = 0.33 \text{ mW};$

 $f_q = 333.25 \text{ MHz}; P_q = 0.33 \text{ mW};$

 $f_r = 335.25 \text{ MHz}; P_r = 0.33 \text{ mW};$

measured at $f_p + f_q + f_r = 324.25$ MHz.



BGY888

FEATURES

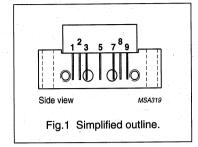
- Excellent linearity
- · Extremely low noise
- High gain
- · Excellent return loss properties.

APPLICATIONS

 Single module line extender in CATV systems operating over a frequency range of 40 to 860 MHz.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



DESCRIPTION

The BGY888 is a hybrid high dynamic range amplifier module operating at a voltage supply of +24 V in a SOT115J package. The high gain module consists of two cascaded stages both in cascode configuration.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	33.5	34.5	dB
		f = 860 MHz	34	-	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	_	340	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY888

CHARACTERISTICS

Table 1 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G _p	power gain	f = 50 MHz	33.5	34.5	dB
		f = 860 MHz	34	_	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
,		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5		dB
		f = 640 to 860 MHz	14	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	49 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	-	-60	dB
X_{mod}	cross modulation	49 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-59	dB
CSO	composite second order distortion	49 channels flat; V _o = 44 dBmV; measured at 860.5 MHz	_	-55	dB
d ₂	second order distortion	note 1	_	-65	dB
V_o	output voltage	d _{im} = -60 dB; note 2	58	_	dBmV
F	noise figure	f = 50 MHz	-	4.5	dB
		f = 550 MHz	_	5	dB
		f = 600 MHz	_	5	dB
		f = 650 MHz	_	5.5	dB
		f = 750 MHz	_	6	dB
		f = 860 MHz	_	7	dB
I _{tot}	total current consumption (DC)	note 3	-	340	mA

Notes

1. $V_p = V_q = 44 \text{ dBmV};$ $f_p = 55.25 \text{ MHz}; f_q = 805.25 \text{ MHz};$ measured at $f_p + f_q = 860.5 \text{ MHz}.$

2. Measured according to DIN45004B:

$$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{split}$$

BGY888

Table 2 Bandwidth 40 to 860 MHz; $V_B = 24 \text{ V}$; $T_{case} = 30 \,^{\circ}\text{C}$; $Z_S = Z_L = 75 \,^{\circ}\Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	34.5	dB
.		f = 860 MHz	34	-	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	- 1 - 1 - 1 - 1	±0.5	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	- 1000	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14		dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	129 channels flat; V _o = 44 dBmV; measured at 859.25 MHz	_	-46	dB
X _{mod}	cross modulation	129 channels flat; V _o = 44 dBmV; measured at 55.25 MHz		-50	dB
CSO	composite second order distortion	129 channels flat; V _o = 44 dBmV; measured at 860.5 MHz		-48	dB
d ₂	second order distortion	note 1		-65	dB
V _o	output voltage	d _{im} = -60 dB; note 2	58		dBmV
F	noise figure	see Table 1			dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

 $\begin{array}{ll} \text{1.} & V_p = V_q = 44 \text{ dBmV}; \\ f_p = 55.25 \text{ MHz}; f_q = 805.25 \text{ MHz}; \\ \text{measured at } f_p + f_q = 860.5 \text{ MHz}. \end{array}$

2. Measured according to DIN45004B:

 $\begin{array}{l} f_p = 851.25 \text{ MHz; } V_p = V_o; \\ f_q = 858.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{array}$

BGY888

Table 3 Bandwidth 40 to 750 MHz; V_B = 24 V; T_{case} = 30 °C; Z_S = Z_L = 75 Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	34.5	dB
		f = 750 MHz	34	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.45	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	-	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
1.		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	-	dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	-	-50	dB
X _{mod}	cross modulation	110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-51	dB
CSO	composite second order distortion	110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_	-53	dB
d ₂	second order distortion	note 1	-	-65	dB
V _o	output voltage	d _{im} = -60 dB; note 2	59	_ `.	dBmV
F	noise figure	see Table 1	_	-	dB
I _{tot}	total current consumption (DC)	note 3	_	340	mA

Notes

- 1. $V_p = V_q = 44 \text{ dBmV};$ $f_p = 55.25 \text{ MHz}; f_q = 691.25 \text{ MHz};$ measured at $f_p + f_q = 746.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $f_p = 740.25 \text{ MHz}; V_p = V_o;$

 $f_q = 747.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$

 $f_r = 749.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$

measured at $f_p + f_q - f_r = 738.25$ MHz.

BGY888

Table 4 Bandwidth 40 to 600 MHz; $V_B = 24$ V; $T_{case} = 30$ °C; $Z_S = Z_L = 75$ Ω

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	34.5	dB
		f = 600 MHz	34	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.35	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	- 1	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 600 MHz	16	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16		dB
S ₂₁	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	-55	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-	-54	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz		-56	dB
d ₂	second order distortion	note 1		-68	dB
Vo	output voltage	d _{im} = -60 dB; note 2	61	_	dBmV
F	noise figure	see Table 1	_	_	dB
I _{tot}	total current consumption (DC)	note 3	T-	340	mA

Notes

 $\begin{array}{ll} \text{1.} & V_p = V_q = 44 \text{ dBmV}; \\ f_p = 55.25 \text{ MHz}; \, f_q = 541.25 \text{ MHz}; \\ \text{measured at } f_p + f_q = 596.5 \text{ MHz}. \end{array}$

Measured according to DIN45004B:

 $\begin{aligned} &\text{f}_p = 590.25 \text{ MHz; } V_p = V_o; \\ &\text{f}_q = 597.25 \text{ MHz; } V_q = V_o; \\ &\text{f}_r = 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ &\text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{aligned}$

BGY1085A

FEATURES

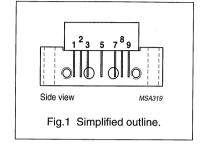
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

DESCRIPTION

Hybrid high amplifier module for CATV systems operating over a frequency range of 40 to 1000 MHz at a supply voltage of +24 V (DC).

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 1000 MHz	18.5	_	dB
I _{tot}	total current consumption (DC)	V _B = 24 V		240	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage	_	65	dBmV
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-20	+100	°C

BGY1085A

CHARACTERISTICS

Table 1 Bandwidth 40 to 1000 MHz; $T_{case} = 30$ °C; $Z_S = Z_L = 75 \Omega$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	-	19	dB
r		f = 1000 MHz	18.5	_	-	dB
SL	slope cable equivalent	f = 40 to 1000 MHz	0	-	2	dB
FL	flatness of frequency response	f = 40 to 1000 MHz		-	±0.3	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	-		dB
		f = 80 to 160 MHz	18.5	-	_	dB
		f = 160 to 320 MHz	17	-	_	dB
		f = 320 to 640 MHz	15.5	-	-	dB
		f = 640 to 1000 MHz	14	_	_	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	18.5	_	_	dB
		f = 160 to 320 MHz	17	_	Ī-	dB
		f = 320 to 640 MHz	15.5	_	-	dB
		f = 640 to 1000 MHz	14	_	_	dB
СТВ	composite triple beat	85 channels flat; V _o = 44 dBmV; measured at 595.25 MHz	_	_	-58	dB
		110 channels flat; V _o = 44 dBmV; measured at 745.25 MHz	-	_	-53	dB
		150 channels flat; V _o = 40 dBmV; measured at 985.25 MHz	-	-53	-	dB
X _{mod}	cross modulation	85 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	_	-	-58	dB
* *		110 channels flat; V _o = 44 dBmV; measured at 55.25 MHz	-		-54	dB
		150 channels flat; V _o = 40 dBmV; measured at 55.25 MHz	_	-54	_	dB
CSO	composite second order distortion	85 channels flat; V _o = 44 dBmV; measured at 596.5 MHz	_	-	-60	dB
		110 channels flat; V _o = 44 dBmV; measured at 746.5 MHz	_ ,	-	-56	dB
		150 channels flat; V _o = 40 dBmV; measured at 986.5 MHz	_	-56	-	dB

BGY1085A

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
d ₂	second order distortion	note 1	_	_	-72	dB
		note 2			-65	dB
		note 3	_	-68	-	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$				
		note 4	61	_	_	dBmV
		note 5	60	_	-	dBmV
11		note 6	57	-	-	dBmV
F	noise figure	f = 50 MHz	_	_	5.5	dB
		f = 550 MHz	-	-	6	dB
		f = 600 MHz	_	-	6	dB
	*	f = 650 MHz	_	_	6.5	dB
		f = 750 MHz	_	-, ,	7	dB
		f = 860 MHz	_	-	7.5	dB
		f = 1000 MHz	-	-	7.5	dB
I _{tot}	total current consumption (DC)	note 7	_	-	240	mA

Notes

- 1. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.
- 2. $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.
- 3. $f_p = 55.25$ MHz; $V_p = 40$ dBmV; $f_q = 931.25$ MHz; $V_q = 40$ dBmV; measured at $f_p + f_q = 986.5$ MHz.
- 4. $f_p = 590.25 \text{ MHz}$; $V_p = V_o$; $f_q = 597.25 \text{ MHz}$; $V_q = V_o 6 \text{ dB}$; $f_r = 599.25 \text{ MHz}$; $V_r = V_o 6 \text{ dB}$; measured at $f_p + f_q f_r = 588.25 \text{ MHz}$.
- 5. $f_p = 740.25 \text{ MHz}$; $V_p = V_o$; $f_q = 747.25 \text{ MHz}$; $V_q = V_o 6 \text{ dB}$; $f_r = 749.25 \text{ MHz}$; $V_r = V_o 6 \text{ dB}$; measured at $f_p + f_q f_r = 738.25 \text{ MHz}$.
- $\begin{array}{ll} \text{6.} & \text{f}_p = 980.25 \text{ MHz; } \text{V}_p = \text{V}_o; \\ & \text{f}_q = 987.25 \text{ MHz; } \text{V}_q = \text{V}_o 6 \text{ dB;} \\ & \text{f}_r = 989.25 \text{ MHz; } \text{V}_r = \text{V}_o 6 \text{ dB;} \\ & \text{measured at f}_p + \text{f}_q \text{f}_r = 978.25 \text{ MHz.} \\ \end{array}$
- 7. The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

PACKAGE OUTLINES

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Wideband hybrid IC modules

Package information

MOUNTING AND SOLDERING RECOMMENDATIONS

Mounting

The heatsink surface must be flat, free of burrs and oxidation and be parallel to the mounting surface.

The heatsink, mounting base and ground leads should be properly RF-grounded.

Heatsink compound should be applied sparingly and evenly on the mounting base. Suitable heatsink compounds are Dow Corning 340, Eccotherm TC-5 (E&C) and Wakefield 120.

When mounting CATV hybrid modules, the UNC screws must first be turned finger-tight. The screws should then be tightened to within the tolerance 0.5 Nm minimum and 0.7 Nm maximum.

Soldering

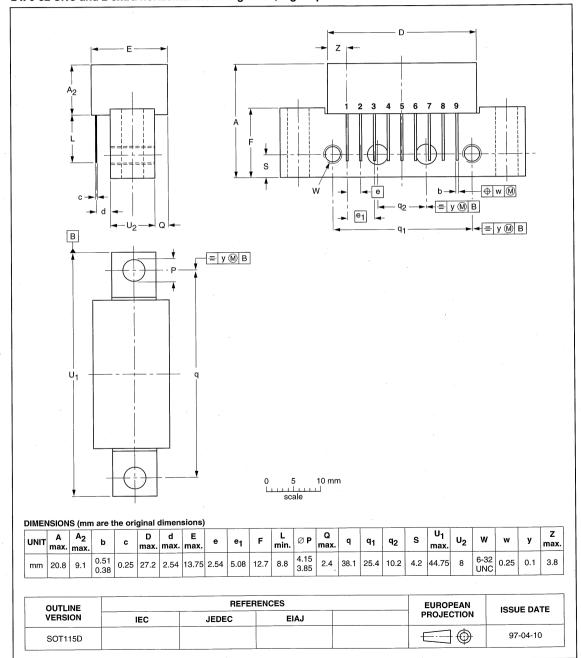
Modules may be soldered directly into a circuit using a soldering iron with a maximum temperature of 260 °C for not more than 3 seconds when the soldered joints are a minimum of 3 mm from the module.

Wideband hybrid IC modules

PACKAGE OUTLINES

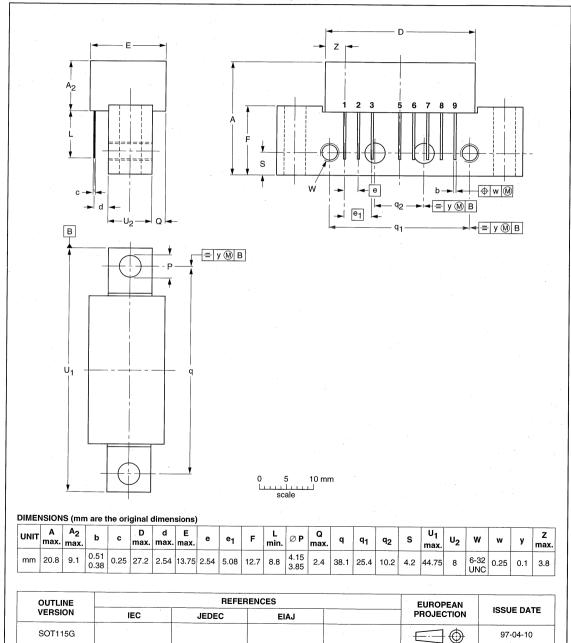
Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 9 gold-plated in-line leads

SOT115D



Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 8 gold-plated in-line leads

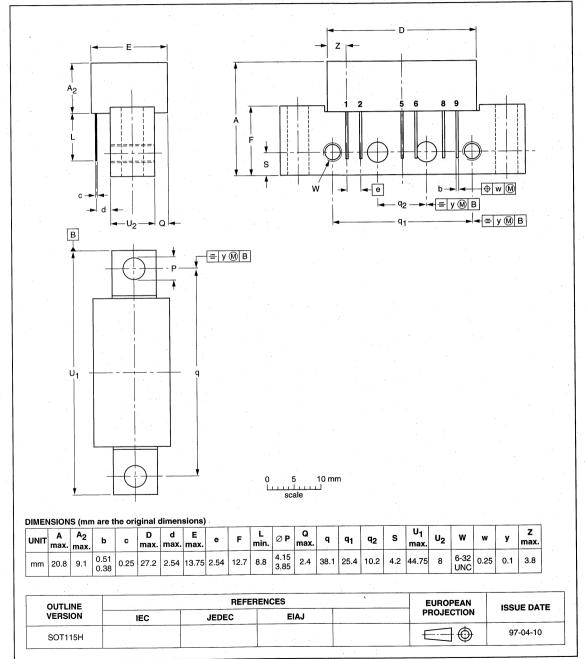
SOT115G



Wideband hybrid IC modules

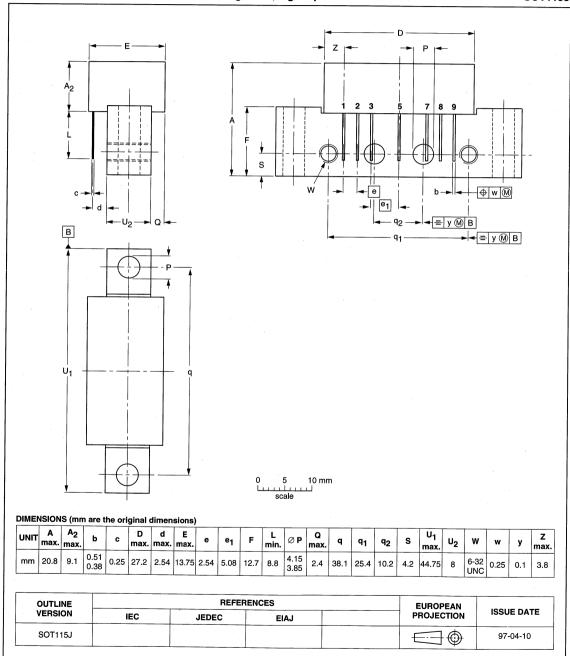
Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2×10^{-2} extra horizontal mounting holes; 6×10^{-2} gold-plated in-line leads

SOT115H



Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

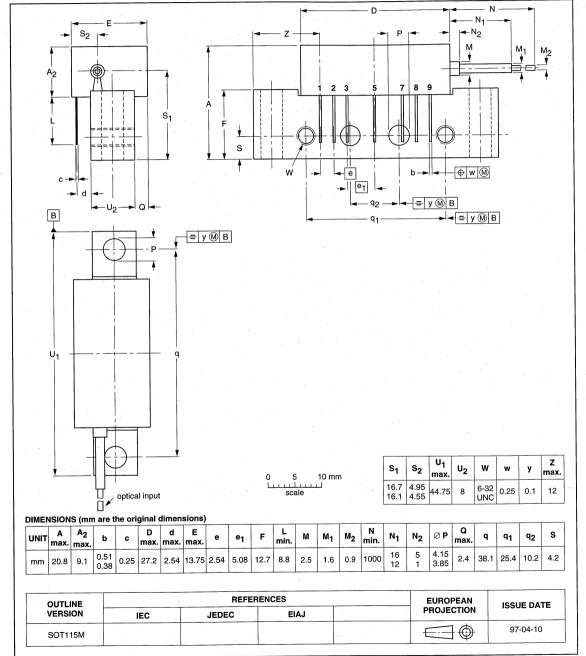
SOT115J



Wideband hybrid IC modules

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; optical input; 7 gold-plated in-line leads

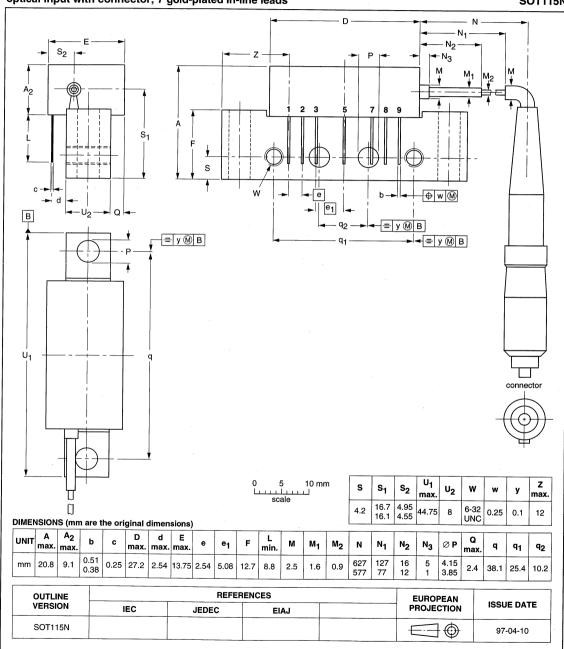
SOT115M



Rectangular single-ended flat package; aluminium flange;

2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; optical input with connector; 7 gold-plated in-line leads

SOT115N



Wideband hybrid IC modules

Rectangular single-ended flat package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; SOT115P optical input with connector; 7 gold-plated in-line leads Ν = y₁ M B **-** N₃ S1 s ⊕ w M е e₁ q_2 **→** = y M B - = y M B = y M B U₁ connector U₁ z 10 mm s_2 W U₂ s S₁ w у У1 q_2 max. max scale 16.7 4.95 6-32 12 4.2 8 0.25 0.1 0.2 10.2 44.75 4.55 16.1 UNC DIMENSIONS (mm are the original dimensions) A₂ D d M₁ M₂ N₁ N₂ M N₃ ØΡ q **q**1 F Мз UNIT е e₁ max max min. max max max. max. 4.15 18.5 16 5 917 0.51 2.4 38.1 25.4 2.5 1.6 0.9 13.75 2.54 5.08 12.7 8.8 27.2 2.54 20.8 9.1 0.25 3.85 mm 16.0 12

EIAJ

EUROPEAN

PROJECTION

 \bigcirc

ISSUE DATE

97-04-18

REFERENCES

JEDEC

OUTLINE

VERSION

SOT115P

IEC



CATV TEST JIGS

CATV test jigs

STANDARD CATV TEST JIG

PARAMETER	CONDITIONS	VALUE	
Frequency		5 to 1000 MHz	
Suitability	suitable for devices with switchabl	e positive and negative power supplies	
Impedance		75 Ω	
Return loss	measured with thru-line system; other port terminated with 75 Ω		
<600 MHz		<-40 dB	
<860 MHz		<-32 dB	
<1000 MHz		<-28 dB	
Cross talk		<-80 dB	
Insertion loss	measured with thru-line system	<0.1 dB	
DC current		<1 A	
DC voltage	automatically switched to the device by means of a microswitch after closing the pressing system	<50 V	
Operating temperature		−25 to +75 °C	
RF connectors		N-type female; 75 Ω	
DC connectors		banana type	
Dimensions	length × breadth × height; note 1	110 × 60 × 55 mm	
Cooling		water cooling connections available on test jig	
Ordering	order the STANDARD CATV TEST Internal Philips: Jos van Gennip, B E-mail: Jos.vanGennip@nym.sc.ph	T JIG via your regional sales office. Building BY-3.073, Philips Semiconductors, Niimegen.	

Note

1. Dimensions without pressing system, RF connectors and cooling connections. Distance between the centre contact of the RF connectors is 35.2 mm.

CATV test jigs

SPECIAL CATV TEST JIG for BGX885N, BGD885, BGE885 and BGX881

PARAMETER	CONDITIONS	VALUE
Frequency		40 to 860 MHz
Impedance		75 Ω
Return loss	measured with thru-line system; other port terminated with 75 Ω .	
40 MHz		<-40 dB decreasing 1.5 dB per octave up to 860 MHz
860 MHz		<-32 dB
Cross talk		<-80 dB
Insertion loss	measured with thru-line system	<0.1 dB
DC current		<1 A
DC voltage	automatically switched to the device by means of a microswitch after closing the pressing system	<50 V
Operating temperature		−25 to +75 °C
RF connectors		N-type female; 75 Ω
DC connectors		banana type
Dimensions	length \times breadth \times height; note 1	110 × 60 × 55 mm
Cooling	·	water cooling connections available on test jig
Ordering	order the STANDARD CATV TES Internal Philips: Jos van Gennip, E E-mail: Jos.vanGennip@nym.sc.p	T JIG via your regional sales office. Building BY-3.073, Philips Semiconductors, Nijmegen. hilips.com

Note

1. Dimensions without pressing system, RF connectors and cooling connections. Distance between the centre contact of the RF connectors is 35.2 mm.

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Data handbook system

DATA HANDBOOK SYSTEM

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SC05	Video Transistors and Modules for Monitors
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	NPN Power Transistors
SC07	Small-signal Field-effect Transistors
SC08a	RF Power Transistors for HF and VHF
SC08b	RF Power Transistors for UHF
SC09	RF Power Modules and Transistors for Mobile
	Phones
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	including TOPFETs and IGBTs
SC13b	Small-signal and Medium-power MOS
	Transistors
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